







**BQ25798** ZHCSNY0B - MAY 2020 - REVISED JANUARY 2023

# 带双输入选择器的 BQ25798 I<sup>2</sup>C 控制、1 节至 4 节、5A 降压/升压电池充电器, 用于太阳能电池板的 MPPT 和快速备份模式

## 1 特性

- 高功率密度、高集成降压/升压充电器,用于 1-4 节 电池,支持任何 USB PD 3.0 概要文件
  - 集成四个开关 MOSFET、BATFET
  - 集成输入和充电电流检测
- 高效
  - 750kHz 或 1.5MHz 开关频率
  - 5A 充电电流,精度 10mA
    - 效率高达 96.5%: 在 3A 电流下从 20V 输入 为 16V 电池充电
- 支持宽输入源
  - 自主采样开路电压(Voc)最大功率点跟踪 (MPPT),用于从光伏面板充电
  - 3.6V 至 24V 宽输入工作电压范围,绝对最大额 定电压为 30V
  - 检测 USB BC1.2、HVDCP 以及非标准适配器
- 的双输入电源多路复用器控制器(可选)
- 窄电压直流 (NVDC) 电源路径
- 支持超快速切换到可调节电压的备用模式
- 通过电池给 USB 端口加电 (USB OTG)
  - 2.8V 至 22V OTG 输出电压,分辨率为 10mV, 支持 USB-PD PPS
  - OTG 输出电流调节高达 3.32A,分辨率为
- 灵活的自主和 I<sup>2</sup>C 模式,可实现出色系统性能
- 用于电压、电流和温度监控的集成 16 位 ADC
- 低电池静态电流
  - 仅使用电池工作时为 17 μ A
  - 充电器关断模式下为 500nA
- 高精度
  - 2S-4S 电池充电电压调节范围为 -0.25% 至 +0.65%
  - 充电电流调节范围为 ±5%
  - 输入电流调节范围为 ±5%
- 安全
  - 热调节和热关断
  - 输入/电池 OVP 和 OCP
  - 转换器 MOSFET OCP
  - 充电安全计时器
- 封装
  - 29 引脚, 4mm × 4mm QFN

## 2 应用

- 可视门铃、智能家居控制
- 数据集中器、机器人割草机
- 资产跟踪、移动 POS
- 多参数患者监护仪、心电图 (ECG)、超声波智能探

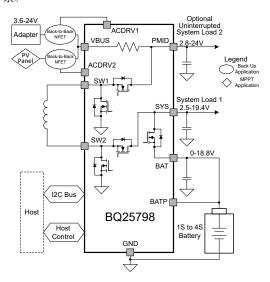
# 3 说明

BQ25798 是一款完全集成的开关模式降压/升压充电 器,适用于 1-4 节锂离子电池和锂聚合物电池。该集成 包括 4 个开关 MOSFET、输入和充电电流检测电路、 电池 FET 以及降压/升压转换器的所有环路补偿。它使 用 NVDC 电源路径管理,并调节系统电压,而不会下 降至低于可配置的最小系统电压。当系统功率超过输入 源额定值时,电池补充模式支持系统,不会使输入源过 载。BQ25798 还使用其内置的 V<sub>OC</sub> 调节 MPPT 算 法,更大限度地提高光伏面板的功率。 BQ25798 支持 在备用模式下从适配器到转换电池电压的超快速切换。

#### 器件信息

PR 11 1P				
器件型号	封装 <sup>(1)</sup>	封装尺寸(标称值)		
BQ25798	QFN (29)	4.0mm x 4.0mm		

如需了解所有可用封装,请参阅数据表末尾的可订购产品附 (1)



简化版原理图



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4 Revision History 注:以前版本的页码可能与当前版本的页码不同

Changes from Revision A (M	ay 2021) to Revision B (January 2023)	Page
• 在整个数据表中删除了对 /P	PG 引脚和 IBAT 引脚的引用	3
	son table	
· Corrected common drain to	common source in ACDRVx pin function in †† 7	5
· Clarified /QON pull up volta	ge in 节 7	5
Updated V <sub>OTG ACC</sub>		9
<ul> <li>Corrected default ICHG in</li> </ul>	节 9.3.2	25
<ul> <li>Clarified PFM peak inductor</li> </ul>	r current in 节 9.3.6.4	34
• Clarified SYSMIN charge co	urrent clamp and settings in 节 9.3.9.2	42
· Clarified trickle to precharge	e regulation in 节 9.3.9.2	42
· Updated I2C terminology in	text and figures in 节 9.3.14	53
	t charge current to 1A in 节 9.5.1	
<ul> <li>Clarified REG0x14 and REG</li> </ul>	G0x33 regarding reporting IBAT discharge current in 节 9.5.1	57
• Changed REG0x2E to no lo	onger recommend 12-bit ADC setting in 🕆 9.5.1	57
<ul> <li>Changed REG0x2E to no lo 57</li> </ul>	onger recommend running average for ADC IBAT when discharging	in 节 9.5.1
<ul> <li>Corrected PN and DEV_RE</li> </ul>	EV naming in REG0x48 in 节 9.5.1	57
• Added STOP_WD_EN in R	EG0x09 bit5 in 节 9.5.1	57
Added optional input snubb	er/TVS to apps diagram in 节 10.2	130
Changes from Revision * (De	ecember 2020) to Revision A (May 2021)	Page
• 将"预告信息"更改为"量	产数据"	1

# 5 说明(续)

充电器支持窄范围 VDC 电源路径管理,将系统电压调节至稍高于电池电压的水平,但是不会下降至低于最小系统电压。即使电池完全放电或移除,最低系统电压也允许系统运行。当系统功率超过输入源额定值时,电池补充模式支持系统电源需求,不会使输入源过载。

该器件从传统 USB 适配器到高电压 USB PD 适配器和传统桶形适配器等各种输入源为电池充电。在没有主机控制时,充电器基于输入电压和电池电压自动将转换器设置为降压、升压或降压-升压配置。双输入源选择器管理来自两个不同输入源的电源流入。输入选择由主机通过 I<sup>2</sup>C 来控制,默认源 1 (VAC1) 作为主输入,源 2 (VAC2) 作为辅助输入。

为支持通过可调节高电压适配器进行快速充电,该器件提供了 D+/D- 握手机制。该器件符合 USB 2.0 和 USB 3.0 功率传输规范,具有输入电流和电压调节功能。此外,输入电流优化器 (ICO) 还能够检测未知输入源的最大功率点。BQ25798 还提供最大功率点跟踪 (MPPT) 算法,以便优化当连接到太阳能电池时消耗的电能。

除了 I<sup>2</sup>C 主机控制的充电模式,此充电器还支持自动充电模式。上电之后,使用默认寄存器设置启用充电。此器件可以在无需软件参与的情况下完成充电周期。它检测电池电压并在不同阶段为电池充电:涓流充电、预充电、恒定电流 (CC) 充电和恒定电压 (CV) 充电。在充电周期的末尾,当充电电流低于在恒定电压阶段中预设定的限值(终止电流)时,充电器自动终止。当整个电池下降到低于再充电阈值时,充电器将自动启动另一个充电周期。

在没有输入源的情况下,此器件支持 USB On-the-Go (OTG) 功能,对电池进行放电以在 VBUS 上以 10mV 步长产生可调的 2.8V 至 22V 电压,符合 USB PD 3.0 规范定义的可编程电源 (PPS) 特性。BQ25798 还提供备用模式,在移除适配器后使用可调 OTG 电压为 PMID 上的系统负载供电。

该充电器提供针对电池充电和系统运行的多种安全特性,其中包括电池负温度系数热敏电阻监视、涓流充电、预充电和快速充电计时器以及电池和输入上的过压/过流保护。当结温超过可编程的阈值时,热调节会减小充电电流。器件的 STAT 输出报告充电状态和任何故障状况。当发生故障时,INT 引脚会立即通知主机。

该器件采用 29 引脚 4mm × 4mm QFN 封装。



# **6 Device Comparison**

PART NUMBER	BQ25790	BQ25792	BQ25798
ACOVP Default Value	7V	26V	26V
ACOVP Options	7V, 12V, 18V or 26V	7V, 12V, 22V or 26V	7V, 12V, 22V or 26V
/PG, IBAT, BATN pins	Yes	No	No
MPPT	No	No	Yes
Backup Mode	No	No	Yes
Package	DSBGA 56, 2.9mm x 3.3mm	QFN 29, 4mm x 4mm	QFN 29, 4mm x 4mm

# 7 Pin Configuration and Functions

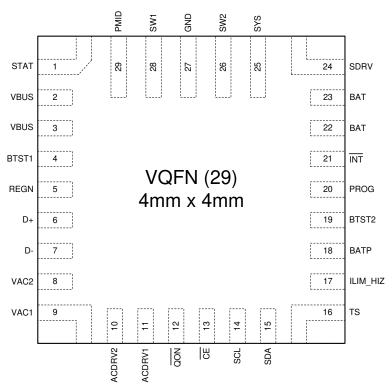


图 7-1. RQM Package 29-Pin VQFN Top View

表 7-1. Pin Functions

F	PIN I/O		DESCRIPTION
NAME	NO.	"0	DESCRIPTION
STAT	1	DO	Open Drain Charge Status Output – It indicates various charger operations. Connect to the pull up rail via a $10 \mathrm{k}\Omega$ resistor. LOW indicates charging in progress. HIGH indicates charging completed or charging disabled. When any fault condition occurs, STAT pin blinks at 1Hz. The STAT pin function can be disabled when DIS_STAT bit is set to 1.
VBUS	2-3	Р	Charger Input Voltage – The power input terminal of the charger. An input current sensing circuit is connected between VBUS and PMID. The recommended capacitors at VBUS are 2 pieces of 10 $\mu$ F and one piece of 0.1 $\mu$ F ceramic capacitors. Place the 0.1 $\mu$ F ceramic capacitor as close as possible to the charger IC.
		Р	Input High Side Power MOSFET Gate Driver Power Supply - Connect a 10V or higher rating, 47nF ceramic capacitor between SW1 and BTST1 as the bootstrap capacitor for driving high side switching MOSFET (Q1).
REGN	5	Р	The Charger Internal Linear Regulator Output $-$ It is supplied from either VBUS or BAT dependent on which voltage is higher. Connect a 10V, 4.7 $\mu$ F ceramic capacitor from REGN to power ground. The REGN LDO output is used for the internal MOSFETs gate driving voltage and the voltage bias for TS pin resistor divider.
D+	6	AIO	<b>Positive Line of the USB Data Line Pair</b> – D+/D- based USB host/charging port detection for VIN1 input. The detection includes data contact detection (DCD), primary and secondary detection in BC1.2, and the adjustable high voltage adapter.
D-	7	AIO	Negative Line of the USB Data Line Pair - D+/D- based USB host/charging port detection for VIN1 input. The detection includes data contact detection (DCD), primary and secondary detection in BC1.2, and the adjustable high voltage adapter.
VAC2	8	Р	VAC2 Input Detection - When a voltage between 3.6V and 24V is applied on VAC2, it represents a valid input being plugged into port #2. Connect to VBUS if the ACFET2 and RBFET2 are not installed.
		Р	<b>VAC1 Input Detection</b> - When a voltage between 3.6V and 24V is applied on VAC1, it represents a valid input being plugged into port #1. Connect to VBUS if the ACFET1 and RBFET1 are not installed.



# 表 7-1. Pin Functions (continued)

PIN		I/O	DESCRIPTION
NAME	NO.		2-20111111011
ACDRV2	10	Р	Input FETs Driver Pin 2 - The charge pump output to drive the port #2 input N-channel MOSFET (ACFET2) and the reverse blocking N-channel MOSFET (RBFET2). The charger turns on the back-to-back MOSFETs by increasing the ACDRV2 voltage 5V above the common source connection of the ACFET2 and RBFET2 when the turn-on condition is met. Tie ACDRV2 to GND if no ACFET2 and RBFET2 installed.
ACDRV1 11		Р	Input FETs Driver Pin 1 - The charge pump output to drive the port #1 input N-channel MOSFET (ACFET1) and the reverse blocking N-channel MOSFET (RBFET1). The charger turns on the back-to-back MOSFETs by increasing the ACDRV1 voltage 5V above the common source connection of the ACFET1 and RBFET1 when the turn-on condition is met. Tie ACDRV1 to GND if no ACFET1 and RBFET1 installed.
QON	12	DI	Ship FET Enable or System Power Reset Control Input — When the device is in ship mode or in the shutdown mode, the SDRV turns off the external ship FET to minimize the battery leakage current. A logic low on this pin with $t_{\rm SM\_EXIT}$ duration turns on ship FET to force the device to exit the ship mode. A logic low on this pin with $t_{\rm RST}$ duration resets system power by turning off the ship FET for $t_{\rm RST\_SFET}$ (also setting the charger in HIZ mode when VBUS is high) and then turning on ship FET (also disabling the charger HIZ mode) to provide full system power reset. During $t_{\rm RST\_SFET}$ when the ship FET is off, the charger applies a 30mA discharging current on SYS to discharge system voltage. The pin contains an internal pull-up through a $t_{\rm RQON}$ resistor. The typical output voltage is 3.6 V-3.8 V with VBUS and VBAT > 5V.
CE	13	DI	Active Low Charge Enable Pin - Battery charging is enabled when EN_CHG bit is 1 and $\overline{CE}$ pin is LOW. $\overline{CE}$ pin must be pulled HIGH or LOW, do not leave floating.
SCL	14	DI	$I^2$ C Interface Clock - Connect SCL to the logic rail through a 10 k $Ω$ resistor.
SDA	15	DIO	I²C Interface Data - Connect SDA to the logic rail through a 10 k Ω resistor.
TS	Temperature Qualification Voltage Input - Connect a negative S 16 AI Program temperature window with a resistor divider from REGN to		<b>Temperature Qualification Voltage Input</b> – Connect a negative temperature coefficient thermistor. Program temperature window with a resistor divider from REGN to TS to GND. Charge suspends when TS pin voltage is out of range. Recommend a 103AT-2 $10k\Omega$ thermistor.
ILIM_HIZ	17	Al	Input Current Limit Setting and HIZ Mode Control Pin — Program ILIM_HIZ voltage by connecting a resistor divider from pull up rail to ILIM_HIZ pin to ground. The pin voltage is calculated as: $V_{\text{ILIM}\_HIZ} = 1V + 800 \text{m} \Omega \times \text{IINDPM}$ , in which IINDPM is the target input current. The input current limit used by the charger is the lower setting of ILIM_HIZ pin and the IINDPM register. When the pin voltage is below 0.75V, the buck-boost converter enters non-switching mode, similar to HiZ mode using EN_HIZ bit, but with REGN on. When the pin voltage is above 1V, the converter resumes switching. Connect ILIM_HIZ to REGN to set the maximum input current limit.
BATP	18	Р	<b>Positive Input for Battery Voltage Sensing</b> – Connect to the positive terminal of battery pack. Place $100 \Omega$ series resistance between this pin and the battery positive terminal.
BTST2	19	Р	Output High Side Power MOSFET Gate Driver Power Supply - Connect a 10V or higher rating, 47nF ceramic capacitor between SW2 and BTST2 as the bootstrap capacitor for driving high side switching MOSFET (Q4).
PROG	20	Al	<b>Charger POR Default Settings Program</b> – At power up, the charger detects the resistance tied to PROG pin to determine the default switching frequency and the default battery charging profile. The surface mount resistor with ±1% or ±2% tolerance is recommended. Please refer to more details in the section of PROG Pin Configuration.
INT	21	DO	<b>Open Drain Interrupt Output.</b> – Connect the $\overline{\text{INT}}$ pin to a logic rail via a 10k $\Omega$ resistor. The $\overline{\text{INT}}$ pin sends an active low, 256 $\mu$ s pulse to the host to report the charger device status and faults.
BAT	22-23	Р	The Battery Charging Power Connection - Connect to the positive terminal of the battery pack. The internal charging current sensing circuit is connected between SYS and BAT. The recommended capacitors at BAT are 2 pieces of 10 µ F ceramic capacitors.
SDRV	24	Р	<b>External N-channel Ship FET (SFET) Gate Driver Output</b> – The driver pin of the external ship FET. The ship FET is always turned on when the ship mode is disabled, and it keeps off when the charger is in ship mode or shutdown mode. Connect a 1nF, 50V rated, 0402 package, ceramic capacitor from SDRV to GND or SDRV to BAT when the ship FET is not used.
sys	25	Р	The Charger Output Voltage to System – The internal N-channel high side MOSFET (Q4) is connected between SYS and SW2 with drain on SYS and source on SW2. The recommended capacitors at SYS are 5 pieces of 10 $\mu$ F and one piece of 0.1 $\mu$ F ceramic capacitors. Place the 0.1 $\mu$ F ceramic capacitor as close as possible to the charger IC.
SW2	26	Р	Boost Side Half Bridge Switching Node Inductor connection to mid point of Q3 and Q4 switches.

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# 表 7-1. Pin Functions (continued)

P	PIN		DESCRIPTION	
NAME	NO.	I/O	DESCRIPTION	
GND	27	Р	Ground Return	
SW1 28 P		Р	Buck Side Half Bridge Switching Node Inductor connection to mid point of Q1 and Q2 switches.	
PMID	29	Р	Q1 MOSFET Drain Connection – An internal N-channel high side MOSFET (Q1) is connected between PMID and SW1 with drain on PMID and source on SW1. The recommended capacitors at PMID are 3 pieces of 10 $\mu$ F and one piece of 0.1 $\mu$ F ceramic capacitors. Place the 0.1 $\mu$ F ceramic capacitor as close as possible to the charger IC. If backup mode will be used, an additional 2 pieces of 33 uF POSCAP are recommended to hold up PMID during the switchover from adapter to battery backup.	



# 8 Specifications

## 8.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
	VAC1, VAC2	-2	30	V
	VBUS (converter not switching)	-2	30	V
	PMID (converter not switching)	-0.3	30	V
	ACDRV1, ACDRV2, BTST1	-0.3	32	V
	SYS (converter not switching)	-0.3	23	V
Voltage range (with	BATP, BAT	-0.3	20	V
respect to GND)	BTST2	-0.3	29	V
	SDRV	-0.3	26	V
	SW1	-2 (50ns)	30	V
	SW2	-2 (50ns)	23	V
	QON, D+, D-, CE, STAT, SCL, SDA, INT, ILIM_HIZ, PROG, TS, REGN	-0.3	6	V
Output Sink Current	INT, STAT		6	mA
	BTST1-SW1, BTST2-SW2	-0.3	6	V
Differential Maltana	PMID-VBUS	-0.3	6	V
Differential Voltage	SYS-BAT	-0.3	16	V
	SDRV-BAT	-0.3	6	V
T <sub>J</sub>	Junction temperature	-40	150	°C
T <sub>stg</sub>	Storage temperature	-55	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# 8.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	±2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±250	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

## 8.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V <sub>VBUS</sub>	Input voltage	3.6	24	V
V <sub>BAT</sub>	Battery voltage		18.8	V
I <sub>VBUS</sub>	Input current		3.3	Α
I <sub>SW</sub>	Output current (SW)		5	Α
	Fast charging current		5	Α
I <sub>BAT</sub>	RMS discharge current (continuously)		6	Α
	Peak discharge current (upto 1 sec)		10	Α
T <sub>A</sub>	Ambient temperature	-40	85	°C

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<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

# 8.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
T <sub>J</sub>	Junction temperature	-40		125	°C
C <sub>VBUS</sub>	Effective VBUS capacitance		2		μF
C <sub>PMID</sub>	Effective PMID capacitance		4		μF
C	Effective PMID capacitance without backup mode support		4		μF
C <sub>PMID</sub>	Effective PMID capacitance with backup mode support		70		μF
C <sub>SYS</sub>	Effective SYS capacitance		6		μF
C <sub>BAT</sub>	Effective BAT capacitance		3		μF

# 8.4 Thermal Information

		BQ25798	
	THERMAL METRIC <sup>(1)</sup>	RQM (QFN)	UNIT
		29-PIN	
R <sub>θ JA</sub>	Junction-to-ambient thermal resistance	44.2	°C/W
R <sub>θ JC(top)</sub>	Junction-to-case (top) thermal resistance	20.9	°C/W
R <sub>0</sub> JB	Junction-to-board thermal resistance	9.7	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	0.5	°C/W
Ψ ЈВ	Junction-to-board characterization parameter	9.7	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

## 8.5 Electrical Characteristics

 $V_{VBUS\_UVLOZ} < V_{VBUS\_OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
QUIESCENT C	URRENTS					
I <sub>Q_BAT_ON</sub>	Quiescent battery current (BATP, BAT, SYS) when the charger is in the battery only mode, battery FET is enabled, ADC is disabled	VBAT = 8V, No VBUS, BATFET is enabled, I2C enabled, ADC disabled, not in ship mode or shut down mode, system is powered by battery. T <sub>J</sub> < 85 °C		17	24	μА
I <sub>Q_BAT_OFF</sub>	Quiescent battery current (BATP) for when the charger is in ship mode.	VBAT = 8V, No VBUS, I2C enabled, ADC disabled, in ship mode, T <sub>J</sub> < 85 °C		11	16	μA
I <sub>SD_BAT</sub>	Shutdown battery current (BATP) when charger is in shut down mode.	VBAT = 8V, No VBUS, I2C disabled, ADC disabled, in shut down mode, T <sub>J</sub> < 85 °C		0.5	0.7	μA
I <sub>Q_BAT_ON</sub>	Quiescent battery current (BATP, BAT, SYS) when the charger is in the battery only mode, battery FET is enabled, ADC is enabled	VBAT = 8V, No VBUS, I2C enabled, ADC enabled, not in ship mode or shut down mode, T <sub>J</sub> < 85 °C		540		μА
	Quiescent input current (VBUS)	VBUS = 15V, VBAT = 8V, charge disabled, converter switching, ISYS = 0A, OOA disabled		3		mA
IQ_VBUS	Quiescent input current (VBOS)	VBUS = 15V, VBAT = 8V, charge disabled, converter switching, ISYS = 0A, OOA enabled		5		mA
1	Shutdown input current (VBUS) in	VBUS = 15V, HIZ mode, no battery, ADC disabled, ACDRV disabled		386		μA
I <sub>SD_VBUS</sub>	HIZ	VBUS = 15V, HIZ mode, no battery, ADC disabled, ACDRV enabled		590		μA



 $V_{VBUS\_UVLOZ} < V_{VBUS\_OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
la a=a	Quiescent battery current (BATP,	VBAT = 8V, VBUS = 5V, OTG mode enabled, converter switching, I <sub>VBUS</sub> = 0A, OOA disabled		3		mA
I <sub>Q_</sub> отG	BAT, SYS) in OTG	VBAT = 8V, VBUS = 5V, OTG mode enabled, converter switching, I <sub>VBUS</sub> = 0A, OOA enabled		5		mA
VBUS / VBAT SU	PPLY					
V <sub>VAC_PRESENT</sub>	VAC present rising threshold to turn on the ACFET-RBFET	For both VAC1 and VAC2		3.4	3.5	V
VAC_PRESENT	VAC present falling threshold to turn off the ACFET-RBFET	For both VAC1 and VAC2		3.2		V
	VAC overvoltage rising threshold, when VAC_OVP[1:0]=00	For both VAC1 and VAC2	25.2	26	26.8	V
	VAC overvoltage falling threshold, when VAC_OVP[1:0]=00	For both VAC1 and VAC2	24.4	25.2	26.0	V
	VAC overvoltage rising threshold, when VAC_OVP[1:0]=01	For both VAC1 and VAC2	17.4	18.0	18.6	V
V <sub>VAC_OVP</sub>	VAC overvoltage falling threshold, when VAC_OVP[1:0]=01	For both VAC1 and VAC2	16.9	17.5	18.1	V
	VAC overvoltage rising threshold, when VAC_OVP[1:0]=10	For both VAC1 and VAC2	11.6	12	12.4	V
	VAC overvoltage falling threshold, when VAC_OVP[1:0]=10	For both VAC1 and VAC2	11.2	11.6	12.0	V
	VAC overvoltage rising threshold, when VAC_OVP[1:0]=11	For both VAC1 and VAC2	6.7	7	7.3	V
	VAC overvoltage falling threshold, when VAC_OVP[1:0]=11	For both VAC1 and VAC2	6.5	6.8	7.1	V
V <sub>VBUS_OP</sub>	VBUS operating range		3.6		24	V
$V_{VBUS\_UVLOZ}$	VBUS rising for active I2C, no battery	VBUS rising	3.25	3.4	3.55	V
$V_{VBUS\_UVLO}$	VBUS falling to turn off I2C, no battery	VBUS falling	3.05	3.2	3.35	V
$V_{VBUS\_PRESENT}$	VBUS to start switching	VBUS rising	3.3	3.4	3.5	V
$V_{VBUS\_PRESENTZ}$	VBUS to stop switching	VBUS falling	3.1	3.2	3.3	V
V <sub>VBUS_OVP</sub>	VBUS overvoltage rising threshold	VBUS rising	25.2	25.7	26.2	V
$V_{VBUS\_OVPZ}$	VBUS overvoltage falling threshold	VBUS falling	24.0	24.4	24.8	V
I <sub>BUS_OCP</sub>	IBUS over-current rising threshold		7.0	8.0	9.0	Α
I <sub>BUS_OCPZ</sub>	IBUS over-current falling threshold		6.5	7.5	8.5	Α
Vp	BAT voltage for active I2C, no	VBAT rising, with the ship FET (SFET) installed	3.25	3.40	3.55	V
V <sub>BAT_UVLOZ</sub>	VBUS, no VAC	VBAT rising, without the ship FET (SFET) installed	2.50	2.60	2.71	V

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 $V_{VBUS\ UVLOZ} < V_{VBUS\ OVP}, T_J = -40^{\circ}\text{C}$  to +125°C, and  $T_J = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

	PARAMETER	125°C, and T <sub>J</sub> = 25°C for typical values  TEST CONDITIONS	MIN	TYP	MAX	UNIT
	BAT voltage to turn off I2C, no	VBAT rising, with the ship FET (SFET) installed	3.05	3.20	3.31	V
V <sub>BAT_UVLO</sub>	VBUS, no VAC	VBAT falling, without the ship FET (SFET) installed	2.30	2.40	2.50	V
V <sub>BAT_OTG</sub>	BAT voltage rising threshold to enable OTG mode	VBAT rising	2.7	2.8	2.9	V
V <sub>BAT_OTGZ</sub>	BAT voltage falling threshold to disable OTG mode	VBAT falling	2.4	2.5	2.6	V
V <sub>POORSRC</sub>	Bad adapter detection threshold	VBUS falling	3.3	3.4	3.5	V
V <sub>POORSRC</sub>	Bad adapter detection threshold hysteresis	VBUS rising above V <sub>POORSRC</sub>	150	200	250	mV
I <sub>POORSRC</sub>	Bad adapter detection current source		7	12	20	mA
R <sub>VBUS_PD</sub>	VBUS pull down resistance			6		kΩ
R <sub>VAC_PD</sub>	VAC pull down resistance	For both VAC1 and VAC2		60		Ω
		VOC_PCT = 000 (0.5625), VOC = 18.0V		10.125		V
		VOC_PCT = 001 (0.625), VOC = 18.0V		11.25		V
		VOC_PCT = 010 (0.6875), VOC = 18.0V		12.375		V
VVINDPM_MPPT	VINDPM as set by the MPPT	VOC_PCT = 011 (0.75), VOC = 18.0V		13.5		V
	algorithm	VOC_PCT = 100 (0.8125), VOC = 18.0V		14.625		V
		VOC_PCT = 101 (0.875), VOC = 18.0V		15.75		V
		VOC PCT = 110 (0.9375), VOC = 18.0V		16.875		V
		VOC_PCT = 111 (1.0), VOC = 18.0V		18.0		V
POWER-PATH MAN	NAGEMENT					
V <sub>SYSMAX_REG_RNG</sub>	System voltage regulation range, measured on SYS		3.2		19	V
		V <sub>BAT</sub> = 16.8V (4s default)	16.82	17.00	17.25	V
.,	System voltage regulation	V <sub>BAT</sub> = 12.6V (3s default)	12.62	12.80	13.04	V
V <sub>SYSMAX_REG_ACC</sub>	accuracy (when V <sub>BAT</sub> >V <sub>SYSMIN</sub> , charging disabled, PFM disabled)	V <sub>BAT</sub> = 8.4V (2s default)	8.44	8.60	8.77	V
	enanging aleasies, i in aleasies,	V <sub>BAT</sub> = 4.2V (1s default)	4.268	4.40	4.550	V
V <sub>SYSMIN_REG_RNG</sub>	V <sub>SYSMIN</sub> regulation range, measured on SYS		2.5		16	V
V <sub>SYSMIN_REG_STEP</sub>	V <sub>SYSMIN</sub> regulation step size			250		mV
		4s battery	11.9	12.2	12.75	V
.,	System voltage regulation	3s battery	9.0	9.2	9.55	V
V <sub>SYSMIN_REG_ACC</sub>	accuracy (when V <sub>BAT</sub> <v<sub>SYSMIN)</v<sub>	2s battery	7.12	7.2	7.52	V
		1s battery	3.5	3.7	4.1	V
.,	VSYS overvoltage rising threshold	As a percentage of the system regulation voltage, to turnoff the converter.	105.5	110.0	112.3	%
V <sub>SYS_OVP</sub>	VSYS overvoltage falling threshold	As a percentage of the system regulation voltage, to re-enable the converter.	95.5	100	102	%
V <sub>SYS_SHORT</sub>	VSYS short voltage falling threshold		2.1	2.2	2.3	V
BATTERY CHARGI	ER					1
V <sub>REG_RANGE</sub>	Typical charge voltage regulation range		3		18.8	V
V <sub>REG_STEP</sub>	Typical charge voltage step			10		mV
	·	, ·				



 $V_{VBUS\_UVLOZ} < V_{VBUS\_OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		V <sub>REG</sub> = 16.8V	-0.65		0.55	%
	Charge voltage accuracy, T <sub>.I</sub> = -	V <sub>REG</sub> = 12.6V	-0.85		0.65	%
$V_{REG\_ACC}$	40°C - 85°C	V <sub>REG</sub> = 8.4V	-0.25		0.65	%
		V <sub>REG</sub> = 4.2V	-0.45		0.95	%
I <sub>CHG_RANGE</sub>	Typical charge current regulation range		0.05		5	Α
I <sub>CHG_STEP</sub>	Typical charge current regulation step			10		mA
		ICHG = 2.5A; VBAT=8V	-3		7	%
	Typical boost mode PWM charge	ICHG = 2A; VBAT=8V	-2		8	%
I <sub>CHG_ACC</sub>	current accuracy, VBUS < VBAT,	ICHG = 1.5A; VBAT=8V	0		10	%
	$T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$	ICHG = 1A; VBAT=8V	-2		8	%
		ICHG = 0.5A; VBAT=8V	-7.5		7.5	%
1		ICHG = 4A; VBAT=8V	-5.5		2.5	%
1.	Typical buck mode PWM charge	ICHG = 2A; VBAT=8V	-6.5		3.5	%
ICHG_ACC	current accuracy, VBUS > VBAT, T <sub>J</sub> = -40°C - 85°C	ICHG = 1A; VBAT=8V	-5		5	%
		ICHG = 0.5A; VBAT=8V	-7.5		7.5	%
I <sub>PRECHG</sub> RANGE	Typical pre-charge current range		40		2000	mA
I <sub>PRECHG</sub> STEP	Typical pre-charge current step			40		mA
	Typical LDO mode charge current	IPRECHG = 480mA, VBAT = 6.5V	-8		8	%
I <sub>PRECHG_ACC</sub>	accuracy when V <sub>BATP</sub> below	IPRECHG = 200mA, VBAT = 6.5V	-20		20	%
	$V_{BAT\_LOWV}$ , VBUS < VBAT, $T_J = -40$ °C - 85°C	IPRECHG = 120mA, VBAT = 6.5V	-35		35	%
		IPRECHG = 1000mA, VBAT = 6.5V	-4.5		3.5	%
"	Typical LDO mode charge current accuracy when V <sub>BATP</sub> below	IPRECHG = 480mA, VBAT = 6.5V	-8		8	
I <sub>PRECHG_ACC</sub>	V <sub>BAT LOWV</sub> , VBUS > VBAT, T <sub>J</sub> = -	IPRECHG = 200mA, VBAT = 6.5V	-20		20	%
	40°C¯- 85°C	IPRECHG = 120mA, VBAT = 6.5V	-30		30	%
I <sub>TERM</sub> RANGE	Typical termination current range	,	40		1000	mA
I <sub>TERM STEP</sub>	Typical termination current step			40		mA
TERM_OTE	Termination current accuracy, T <sub>.1</sub> =	ITERM = 120mA, ICHG < 1000mA	-20		20	%
I <sub>TERM_ACC</sub>	- 40°C - 85°C	ITERM = 480mA, ICHG > 1000mA	-14		14	%
V <sub>BAT_SHORTZ</sub>	Battery short voltage rising threshold to start pre-charge	VBAT rising		2.25		V
V <sub>BAT_SHORT</sub>	Battery short voltage falling threshold to stop pre-charge	VBAT falling		2.06		V
I <sub>BAT_SHORT</sub>	Battery short trickle charging current	VBAT < V <sub>BAT_SHORTZ</sub>		100		mA
		VBAT_LOWV_1:0=00	13	15	17	%
	Battery voltage rising threshold to	VBAT_LOWV_1:0=01	61.5	63.0	64.5	%
V <sub>BAT_LOWV_RISE</sub>	start fast-charge, as percentage of V <sub>REG</sub>	VBAT_LOWV_1:0=10	67.0	68.0	69.0	%
	- 1.20	VBAT_LOWV_1:0=11	71.0	72.5	74.0	%
V <sub>BAT_LOWV_HYS</sub>	Battery voltage threshold hysteresis to stop fast-charge on falling edge	VBAT falling, as percentage of VREG, VBAT_LOWV_1:0=11		1.4		%
		VBAT falling, VRECHG=0011, VREG=8.4V		200		mV
$V_{RECHG}$	Battery recharge threshold	VBAT falling, VRECHG=0111,		400		mV

 $V_{VBUS\ UVLOZ} < V_{VBUS\ OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I <sub>BAT_LOAD</sub>	Battery discharge load current			30		mA
I <sub>SYS_LOAD</sub>	System discharge load current			30		mA
R <sub>BATP</sub>	BATP Input Resistance			2.5		ΜΩ
BATFET						
R <sub>BATFET</sub>	MOSFET on resistance from SYS to BAT			11		mΩ
BATTERY PROT	ECTIONS					
· · · · · · · · · · · · · · · · · · ·	Dettem, avenueltene througheld	VBAT rising, as percentage of VREG	103	104	105	%
V <sub>BAT_OVP</sub>	Battery overvoltage threshold	VBAT falling, as percentage of VREG	101	102	103	%
W	Pottory abort valtage	VBAT falling, to clamp the charging current as trickle charging current.		2.06		V
V <sub>BAT_</sub> SHORT	Battery short voltage	VBAT rising, to release the trickle charging current clamp		2.25		V
I <sub>BAT_OCP</sub>	Battery discharging over-current rising threshold		9.3			Α
INPUT VOLTAGE	/ CURRENT REGULATION					
V <sub>INDPM_RANGE</sub>	Typical input voltage regulation range		3.6		22	V
V <sub>INDPM_STEP</sub>	Typical input voltage regulation step			100		mV
		VINDPM=18.6V	-2		2	%
V <sub>INDPM_ACC</sub>	Input voltage regulation accuracy	VINDPM=10.6V	-3		3	%
		VINDPM=4.3V	-5		5	%
I <sub>INDPM_RANGE</sub>	Typical input current regulation range		0.1		3.3	Α
I <sub>INDPM_STEP</sub>	Typical input current regulation step			10		mA
		IINDPM = 500mA, VBUS=9V, T <sub>J</sub> > -20°C	415	460	500	mA
		IINDPM = 1000mA, VBUS=9V, T <sub>J</sub> > -20°C	880	940	1000	mA
I <sub>INDPM_ACC</sub>	Input current regulation accuracy	IINDPM = 2000mA, VBUS=9V, T <sub>J</sub> > -20°C	1800	1880	1960	mA
		IINDPM = 3000mA, VBUS=9V, T <sub>J</sub> > -20°C	2720	2820	2920	mA
V <sub>ILIM_REG_RNG</sub>	Voltage range for input current regultion at ILIM_HIZ pin		1		4	V
I <sub>LEAK_ILIM</sub>	ILIM_HIZ pin leakage current	V <sub>ILIM_HIZ</sub> = 4V	-1.5		1.5	μΑ
D+ / D- DETECTI	ON					
V <sub>D+_600MVSRC</sub>	D+ voltage source (600 mV)		500	600	700	mV
I <sub>D+_10UASRC</sub>	D+ current source (10 μA)	V <sub>D+</sub> = 200 mV,	7	10	14	μA
I <sub>D+_100UASNK</sub>	D+ current sink (100 μA)	V <sub>D+</sub> = 500 mV,	50	90	150	μA
V <sub>D+_0P325</sub>	D+ comparator threshold for Secondary Detection	D+ pin rising	250		400	mV
V <sub>D+_0P8</sub>	D+ comparator threshold for Data Contact Detection	D+ pin rising	775	850	925	mV
I <sub>D+_LKG</sub>	Leakage current into D+	HIZ mode	-1		1	μΑ
V <sub>D600MVSRC</sub>	D- voltage source (600 mV)		500	600	700	mV
I <sub>D100UASNK</sub>	D- current sink (100 μA)	V <sub>D-</sub> = 500 mV,	50	90	150	μA



 $V_{VBUS\_UVLOZ} < V_{VBUS\_OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>D0P325</sub>	D- comparator threshold for Primary Detection	D- pin Rising	250		400	mV
I <sub>DLKG</sub>	Leakage current into D-	HIZ mode	-1		1	μΑ
R <sub>D19K</sub>	D- resistor to ground (19 k $\Omega$ )	V <sub>D-</sub> = 500mV	14.25 24		24.8	kΩ
V <sub>D+ _2p8</sub>	D+ comparator threshold for non- standard adapter	(combined V <sub>D+_2p8_hi</sub> and V <sub>D+_2p8_lo</sub> )	2.55		2.85	V
V <sub>D2p8</sub>	D- comparator threshold for non- standard adapter	(combined VD2p8_hi and VD2p8_lo)	2.55 2.89		2.85	V
V <sub>D+_2p0</sub>	D+ comparator threshold for non- standard adapter	(combined V <sub>D+_2p0_hi</sub> and V <sub>D+_2p0_lo</sub> )	1.85 2.1		2.15	V
V <sub>D2p0</sub>	D- comparator threshold for non- standard adapter	(combined V <sub>D2p0_hi</sub> and V <sub>D2p0_lo</sub> )	1.85		2.15	V
V <sub>D+_1p2</sub>	D+ comparator threshold for non- standard adapter	(combined V <sub>D+_1p2_hi</sub> and V <sub>D+_1p2_lo</sub> )	1.05		1.35	V
V <sub>D1p2</sub>	D- comparator threshold for non- standard adapter	(combined V <sub>D1p2_hi</sub> and V <sub>D1p2_lo</sub> )	1.05		1.35	V
THERMAL REG	GULATION AND THERMAL SHUTDOWN	· ·				
		TREG = 120°C		120		°C
<b>-</b>	Junction temperature regulation	TREG = 100°C		100		°C
T <sub>REG</sub>	accuracy	TREG = 80°C		80		°C
		TREG = 60°C		60		°C
		Temperature increasing (TSHUT[1:0]=00)		150		°C
T <sub>SHUT</sub>		Temperature increasing (TSHUT[1:0]=01)		130		°C
	Thermal shutdown rising threshold	Temperature increasing (TSHUT[1:0]=10)		120		°C
		Temperature increasing (TSHUT[1:0]=11)		85		°C
T <sub>SHUT_HYS</sub>	Thermal shutdown falling hysteresis	Temperature decreasing by T <sub>SHUT_HYS</sub>		30		°C
JEITA THERMIS	STOR COMPARATOR (CHARGE MODE	()				
V <sub>T1_RISE</sub>	T1 comparator rising threshold. Charge is suspended above this voltage.	As Percentage to REGN (0°C w/ 103AT)	72.4	73.3	74.2	%
V <sub>T1_FALL</sub>	T1 comparator falling threshold. Charge is re-enabled below this voltage.	As Percentage to REGN (3°C w/ 103AT)	71.5	72	72.5	%
		As Percentage of REGN, JEITA_T2=5°C w/ 103AT	70.6	71.1	71.6	%
V	To compare the ricing throughold	As Percentage of REGN, JEITA_T2=10°C w/ 103AT	67.9	68.4	68.9	%
V <sub>T2_RISE</sub>	T2 comparator rising threshold.	As Percentage of REGN, JEITA_T2=15°C w/ 103AT	65.0	65.5	66.0	%
		As Percentage of REGN, JEITA_T2=20°C w/ 103AT	61.9	62.4	62.9	%
		As Percentage of REGN, JEITA_T2=5°C w/ 103AT	69.3	69.8	70.3	%
V	TO company to the control of	As Percentage of REGN, JEITA_T2=10°C w/ 103AT	66.6	67.1	67.6	%
V <sub>T2_FALL</sub>	T2 comparator falling threshold.	As Percentage of REGN, JEITA_T2=15°C w/ 103AT	63.7	64.2	64.7	%
		As Percentage of REGN, JEITA_T2=20°C w/ 103AT	60.6	61.1	61.6	%

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 $V_{VBUS\ UVLOZ} < V_{VBUS\ OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		As Percentage of REGN, JEITA_T3=40°C w/ 103AT	49.2	49.7	50.2	%
V	T3 comparator rising threshold.	As Percentage of REGN, JEITA_T3=45°C w/ 103AT	45.6	46.1	46.6	%
V <sub>T3_RISE</sub>	13 comparator fishing tilleshold.	As Percentage of REGN, JEITA_T3=50°C w/ 103AT	42.0	42.5	43.0	%
		As Percentage of REGN, JEITA_T3=55°C w/ 103AT	38.5	39	39.5	%
		As Percentage of REGN, JEITA_T3=40°C w/ 103AT	47.9	48.4	48.9	%
V	T3 comparator falling threshold	As Percentage of REGN, JEITA_T3=45°C w/ 103AT	44.3	44.8	45.3	%
V <sub>T3_FALL</sub>	T3 comparator falling threshold.	As Percentage of REGN, JEITA_T3=50°C w/ 103AT	40.7	41.2	41.7	%
		As Percentage of REGN, JEITA_T3=55°C w/ 103AT	37.2	37.7	38.2	%
V <sub>T5_FALL</sub>	T5 comparator falling threshold. Charge is suspended below this voltage.	As Percentage of REGN (60°C w/ 103AT)	33.7	34.2	34.7	%
V <sub>T5_RISE</sub>	T5 comparator rising threshold. Charge is re-enabled above this voltage.	As Percentage of REGN (58°C w/ 103AT)	35	35.5	36	%
COLD / HOT TH	ERMISTOR COMPARATOR (OTG MOD	DE)		-		
V <sub>BCOLD_RISE</sub>	TCOLD comparator rising	As Percentage of REGN ( - 20°C w/ 103AT)	79.5	80.0	80.5	%
	threshold.	As Percentage of REGN ( - 10°C w/ 103AT)	76.6	77.1	77.6	%
V	TCOLD comparator falling	As Percentage of REGN ( - 20°C w/ 103AT)	78.2	78.7	79.2	%
V <sub>BCOLD_FALL</sub>	threshold.	As Percentage of REGN ( - 10°C w/ 103AT)	75.3	75.8	76.3	%
		As Percentage of REGN, (55°C w/ 103AT)	37.2	37.7	38.2	%
$V_{BHOT\_FALL}$	THOT comparator falling threshold.	As Percentage of REGN, (60°C w/ 103AT)	33.9	34.4	34.9	%
		As Percentage of REGN, (65°C w/ 103AT)	30.8	31.3	31.8	%
		As Percentage of REGN, (55°C w/ 103AT)	38.8	39.3	39.8	%
V <sub>BHOT_RISE</sub>	THOT comparator rising threshold.	As Percentage of REGN, (60°C w/ 103AT)	35.2	35.7	36.2	%
		As Percentage of REGN, (65°C w/ 103AT)	32.0	32.5	33.0	%
SWITCHING CO	NVERTER					
F <sub>SW</sub>	PWM switching frequency	Oscillator frequency		1.5 750		MHz kHz
SENSE RESISTA	ANCE AND MOSFET RDSON					
R <sub>SNS</sub>	VBUS to PMID input sensing resistance	T <sub>j</sub> = -40°C-85°C (typical value is under 25°C)		8		mΩ
R <sub>Q1_ON</sub>	Buck high-side switching MOSFET turnon resistance between PMID and SW1	T <sub>j</sub> = -40°C-85°C (typical value is under 25°C)		24		mΩ



 $V_{VBUS\_UVLOZ} < V_{VBUS\_OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
R <sub>Q2_ON</sub>	Buck low-side switching MOSFET turnon resistance between SW1 and PGND	T <sub>j</sub> = -40°C-85°C (typical value is under 25°C)		35		mΩ
R <sub>Q3_ON</sub>	Boost low-side switching MOSFET turnon resistance between SW2 and PGND	T <sub>j</sub> = -40°C-85°C (typical value is under 25°C)		28		mΩ
R <sub>Q4_ON</sub>	Boost high-side switching MOSFET turnon resistance between SW2 and SYS	T <sub>j</sub> = -40°C-85°C (typical value is under 25°C)		17		mΩ
OTG MODE CON	IVERTER					
V <sub>OTG_RANGE</sub>	Typical OTG mode voltage regulation range		2.8		22	V
V <sub>OTG_STEP</sub>	Typical OTG mode voltage regulation step			10		mV
	OTG mode voltage regulation	IVBUS = 0A, VOTG = 20V	-3.5		3	%
$V_{OTG\_ACC}$	accuracy	IVBUS = 0A, VOTG = 12V	-3.5		3	%
		IVBUS = 0A, VOTG = 5V	-3.5		3	%
I <sub>OTG_RANGE</sub>	Typical OTG mode current regulation range		0.12		3.32	Α
I <sub>OTG_STEP</sub>	Typical OTG mode current regulation step			40		mA
	OTC made assessed to mulation	VBUS = 9V, IOTG = 3.0A	-2.2		2.2	%
I <sub>OTG_ACC</sub>	OTG mode current regulation accuracy	VBUS = 9V, IOTG = 1.52A	-5		3	%
	<u> </u>	VBUS = 9V, IOTG = 0.52A	-15		8	%
$V_{OTG\_UVP}$	OTG mode under voltage falling threshold		2.1	2.2	2.3	V
V <sub>OTG_OVP</sub>	OTG mode overvoltage rising threshold	As percentage of VOTG regulation, OTG mode OOA disabled.	104	113	120	%
VOIG_OVP	OTG mode overvoltage falling threshold	As percentage of VOTG regulation	90	98	104	%
	The falling threshold to trigger the	V <sub>VBUS_BACKUP</sub> = 40%*VINDPM, VINDPM=12V.	37		43	%
V	backup power mode, it is defined as a ratio of VINDPM. When	V <sub>VBUS_BACKUP</sub> = 60%*VINDPM, VINDPM=12V.	54		65	%
V <sub>VBUS</sub> BACKUP	VBUS is lower than this threshold, the charger turns to OTG mode to hold up VBUS voltage from	V <sub>VBUS_BACKUP</sub> = 80%*VINDPM, VINDPM=12V.	77		82	%
	dropping.	V <sub>VBUS_BACKUP</sub> = 100%*VINDPM, VINDPM=12V.	97		102	%
		IBAT_REG_1:0 = 00, VBAT=8V, VOTG=9V	2.8	3	3.2	Α
I <sub>OTG_BAT</sub>	Battery current regulation in OTG mode	IBAT_REG_1:0 = 01, VBAT=8V, VOTG=9V	3.8	4	4.2	Α
		IBAT_REG_1:0 = 10, VBAT=8V, VOTG=9V	4.8	5	5.3	Α
REGN LDO	·					
V	REGN LDO output voltage	V <sub>VBUS</sub> = 5V, I <sub>REGN</sub> = 20mA	4.6	4.8	5	V
$V_{REGN}$	NEGN EDO output voltage	V <sub>VBUS</sub> = 15V, I <sub>REGN</sub> = 20mA	4.8	5	5.2	V
I <sub>REGN</sub>	REGN LDO current limit	V <sub>VBUS</sub> = 5V, V <sub>REGN</sub> = 4.5V	30			mA
I2C INTERFACE	(SCL, SDA)					
V <sub>IH_SDA</sub>	Input high threshold level, SDA	Pull up rail 1.8V	1.3	_		V

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 $V_{VBUS\ UVLOZ} < V_{VBUS\ OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>IL_SDA</sub>	Input low threshold level	Pull up rail 1.8V			0.4	V
V <sub>OL_SDA</sub>	Output low threshold level	Sink current = 5mA			0.4	V
I <sub>BIAS_SDA</sub>	High-level leakage current	Pull up rail 1.8V			1	μΑ
V <sub>IH_SCL</sub>	Input high threshold level, SDA	Pull up rail 1.8V	1.3			V
V <sub>IL_SCL</sub>	Input low threshold level	Pull up rail 1.8V			0.4	V
I <sub>BIAS_SCL</sub>	High-level leakage current	Pull up rail 1.8V		,	1	μA
LOGIC I PIN (CE	, ILIM_HIZ, QON)		1	,		
V <sub>IH_CE</sub>	Input high threshold level, CE		1.3			V
V <sub>IL_CE</sub>	Input low threshold level, CE				0.4	V
I <sub>IN BIAS CE</sub>	High-level leakage current, CE	Pull up rail 1.8V			1	μA
V <sub>IH_QON</sub>	Input high threshold level, QON		1.3			V
V <sub>IL_QON</sub>	Input low threshold level, QON				0.4	V
V <sub>QON</sub>	Internal QON pull up	QON is pulled up internally		3.2		V
R <sub>QON</sub>	Internal QON pull up resistance			200		kΩ
V <sub>IH_ILIM_HIZ</sub>	Input high threshold level, ILIM_HIZ		1			V
V <sub>IL_ILIM_HIZ</sub>	Input low threshold level, ILIM HIZ				0.75	V
LOGIC O PIN (IN	TT, STAT)					
V <sub>OL_INT</sub>	Output low threshold level, INT	Sink current = 5mA			0.4	V
IOUT BIAS INT	High-level leakage current, INT	Pull up rail 1.8V			1	μA
V <sub>OL_STAT</sub>	Output low threshold level, STAT	Sink current = 5mA			0.4	V
I <sub>OUT BIAS STAT</sub>	High-level leakage current, STAT	Pull up rail 1.8V			1	μA
	MENT ACCURACY AND PERFORMA	<u> </u>				'
		ADC_SAMPLE[1:0] = 00		24		ms
		ADC_SAMPLE[1:0] = 01		12		ms
t <sub>ADC CONV</sub>	Conversion time, each	ADC_SAMPLE[1:0] = 10		6		ms
	measurement	ADC_SAMPLE[1:0] = 11 (Not				
		recommended)		3		ms
		ADC_SAMPLE[1:0] = 00	14	15		bits
		ADC_SAMPLE[1:0] = 01	13	14		bits
ADC <sub>RES</sub>	Effective resolution	ADC_SAMPLE[1:0] = 10	12	13		bits
		ADC_SAMPLE[1:0] = 11 (Not recommended)	10	11		bits
ADC MEASURE	MENT RANGE AND LSB		'			ı
IDIJO ADO	ADC VBUS current reading	Range	0		5	Α
IBUS_ADC	(forward and OTG)	LSB		1		mA
	1501/51/0 // //	Range	0		30	V
VBUS_ADC	ADC VBUS voltage reading	LSB		1		mV
	150140 11 11	Range	0		30	V
VAC_ADC	ADC VAC voltage reading	LSB		1		mV
		Range	0		20	V
VBAT_ADC	ADC BAT voltage reading	LSB		1		mV
		Range	0		24	V
VSYS_ADC	ADC SYS voltage reading	LSB		1		mV

 $V_{VBUS\_UVLOZ} < V_{VBUS\_OVP}, T_J = -40^{\circ}C$  to +125°C, and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

*D00_0*L02 *	B00		•		,	
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
IBAT_ADC	ADC BAT current reading	Range	0		8	Α
	ADC BAT current reading	LSB		1		mA
TS_ADC AD	ADC TS voltage reading range	Range	0		99.9	%
	ADC 13 voltage reading range	LSB		0.098		%
TDIE ADC	ADC die temperature reading	Range	-40		150	°C
TDIE_ADC	range	LSB		0.5		°C

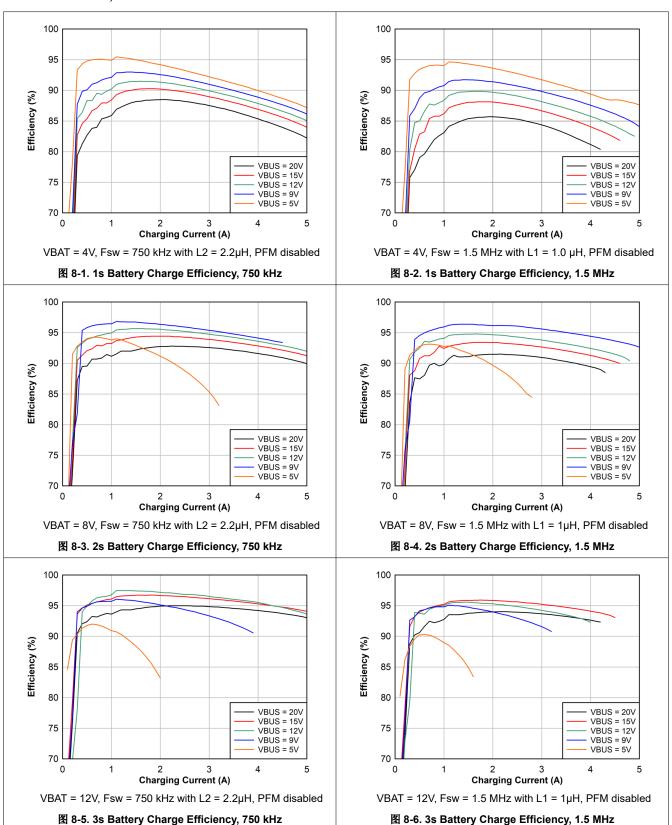
# 8.6 Timing Requirements

	PARAMETER	TEST CONDITIONS	MIN	NOM	MAX	UNIT
BATTERY CHARG	BER					
	Top-off timer accuracy	TOPOFF_TMR[1:0] = 01	12	15	18	min
t <sub>TOP_OFF</sub>		TOPOFF_TMR[1:0] = 10	24	30	36	min
		TOPOFF_TMR[1:0] = 11	36	45	54	min
t <sub>SAFETY_TRKCHG</sub>	Charge safety timer in trickle charge		0.9	1	1.1	hr
t <sub>SAFETY_PRECHG</sub>	Charge safety timer in pre-charge	PRECHG_TMR = 0	1.8	2	2.2	hr
	Charge safety timer accuracy	CHG_TMR[1:0] = 00	4.5	5	5.5	hr
		CHG_TMR[1:0] = 01	7.2	8	8.8	hr
t <sub>SAFETY</sub>		CHG_TMR[1:0] = 10	10.8	12	13.2	hr
		CHG_TMR[1:0] = 11	21.6	24	26.4	hr
I2C INTERFACE						
f <sub>SCL</sub>	SCL clock frequency				1000	kHZ
WATCHDOG TIME	ER .		•	,		
t <sub>LP_WDT</sub>	Watchdog reset time	EN_HIZ = 1, WATCHDOG = 160s	100	160		s
t <sub>WDT</sub>	Watchdog reset time	EN_HIZ = 0, WATCHDOG = 160s	136	160		s

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# 8.7 Typical Characteristics

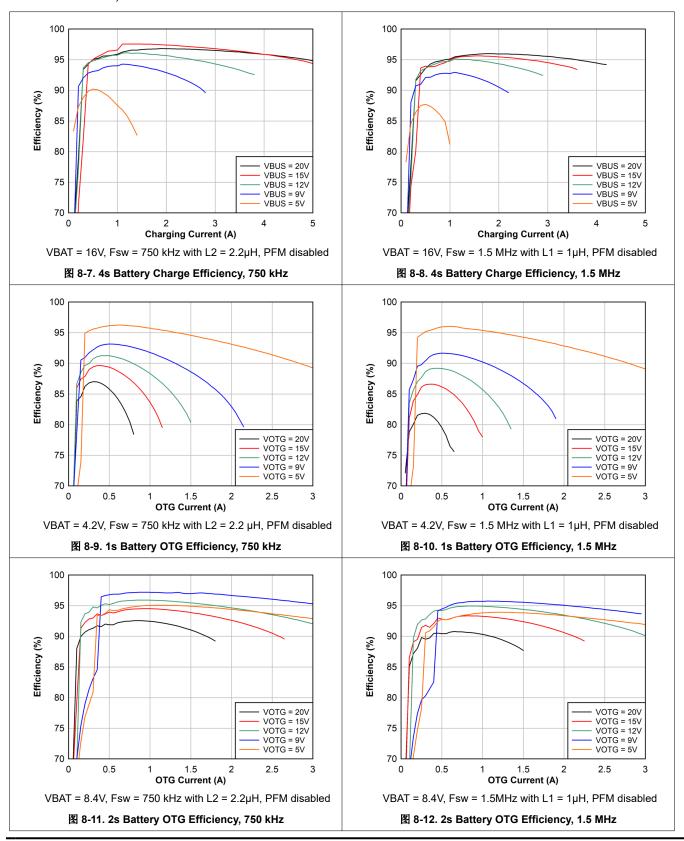
 $C_{VBUS}$  = 2\*10 $\mu$ F,  $C_{PMID}$ = 3\*10 $\mu$ F,  $C_{SYS}$  = 5\*10 $\mu$ F,  $C_{BAT}$  = 2\*10 $\mu$ F, L1 = 1 $\mu$ H (SPM6530T-1R0M120) and L2 = 2.2 $\mu$ H (WE-LHMI-74437346022)





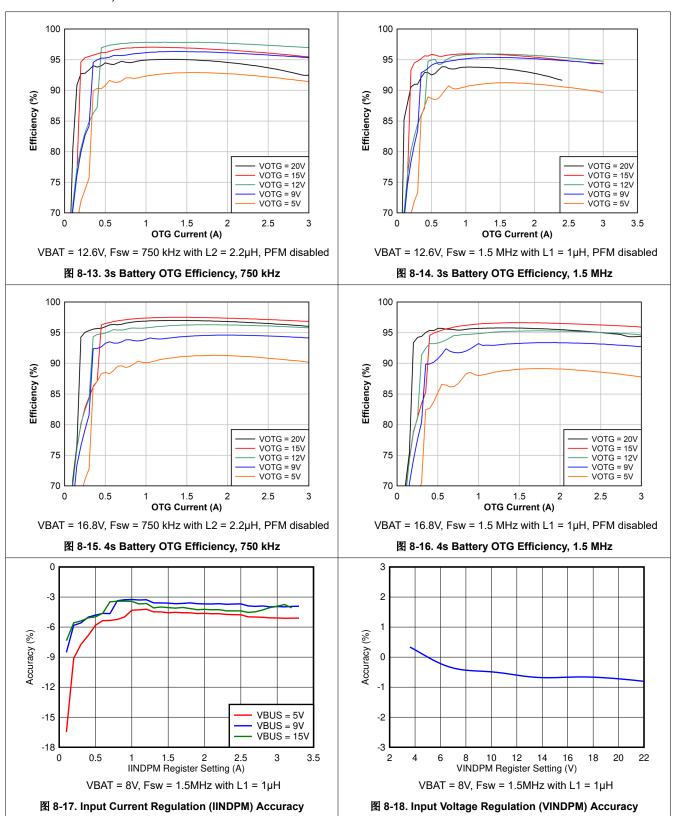
# 8.7 Typical Characteristics (continued)

 $C_{VBUS}$  = 2\*10 $\mu$ F,  $C_{PMID}$ = 3\*10 $\mu$ F,  $C_{SYS}$  = 5\*10 $\mu$ F,  $C_{BAT}$  = 2\*10 $\mu$ F, L1 = 1 $\mu$ H (SPM6530T-1R0M120) and L2 = 2.2 $\mu$ H (WE-LHMI-74437346022)



# 8.7 Typical Characteristics (continued)

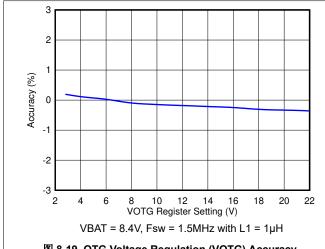
 $C_{VBUS}$  = 2\*10 $\mu$ F,  $C_{PMID}$ = 3\*10 $\mu$ F,  $C_{SYS}$  = 5\*10 $\mu$ F,  $C_{BAT}$  = 2\*10 $\mu$ F, L1 = 1 $\mu$ H (SPM6530T-1R0M120) and L2 = 2.2 $\mu$ H (WE-LHMI-74437346022)





# 8.7 Typical Characteristics (continued)

 $C_{VBUS} = 2*10 \mu F, \ C_{PMID} = 3*10 \mu F, \ C_{SYS} = 5*10 \mu F, \ C_{BAT} = 2*10 \mu F, \ L1 = 1 \mu H \ (SPM6530T-1R0M120) \ and \ L2 = 2.2 \mu H \ (WE-100 + 100 +$ LHMI-74437346022)



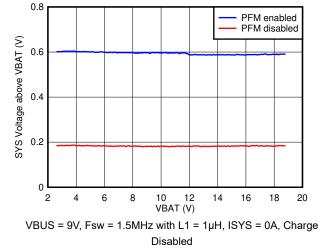


图 8-19. OTG Voltage Regulation (VOTG) Accuracy

图 8-20. Offset Voltage of SYS Regulation above VBAT

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# 9 Detailed Description

#### 9.1 Overview

The BQ25798 is a fully integrated, switch-mode buck-boost charger for a 1 cell  $\sim$  4 cell Li-ion battery and Li-polymer battery. For compact design and minimum component count, the charger integrates the 4 switching MOSFETs (Q<sub>1</sub>, Q<sub>2</sub>, Q<sub>3</sub>, Q<sub>4</sub>), input and charging current sensing circuits, the battery FET (BATFET) and all the loop compensation of the buck-boost converter. It provides high power density and design flexibility to charge batteries across the full input voltage range for USB Type-C  $^{\text{TM}}$  and USB-PD applications such as digital cameras, drones and mobile printers.

The charger supports narrow VDC (NVDC) power path management, in which the system is regulated at a voltage slightly higher than the battery voltage, without dropping below a configurable minimum system voltage. The system keeps operating even when the battery is completely discharged or removed. When load power exceeds the input source rating, the battery gets into supplement mode and prevents the input source from being overloaded and the system from crashing.

The device charges a battery from a wide range of input sources including legacy USB adapter to high voltage USB-PD adapter and traditional barrel adapter. The charger seamlessly transitions between buck, boost and buck-boost modes based on input voltage and battery voltage without host control. The optional dual-input source selector manages the power flowing from two different input sources, prioritizing the first available input source. The host may manually transition between input sources using I<sup>2</sup>C.

To support fast charging using adjustable high voltage adapter (HVDCP), the device provides D+/D- handshake. The device is compliant with USB 2.0 and USB 3.0 power delivery specification with input current and voltage regulation. In addition, the Input Current Optimizer (ICO) allows the detection of maximum power point of an unknown input source. The BQ25798 also features a Maximum Power Point Tracking (MPPT) algorithm to optimize the energy drawn from a low-power photovoltaic panel. This MPPT algorithm measures the open-circuit voltage of the panel on a user-configurable period, then adjusts the VINDPM using the VOC\_PCT setting to calculate the maximum power point as a percentage of the measured open-circuit voltage.

In addition to the  $I^2C$  host controlled charging mode, BQ25798 also supports autonomous charging mode. After power up, the charging is defaulted enabled with all the registers default settings. The device can complete a charging cycle without any software engagements. It detects battery voltage and charges the battery in different phases: trickle charging, pre-charging, constant current (CC) charging and constant voltage (CV) charging. At the end of the charging cycle, the charger automatically terminates when the charge current is below a pre-set limit (termination current) in the constant voltage phase. When the full battery falls below the recharge threshold, the charger will automatically start another charging cycle.

In the absence of input sources, BQ25798 supports USB On-the-Go (OTG) function, discharging the battery to generate an adjustable 2.8V~22V voltage on VBUS with 10mV step size. This is compliant with the USB PD 3.0 specification defined PPS feature. The BQ25798 also supports a backup feature using this same mechanism in which a system load connected at PMID may be supplied with the adjustable OTG voltage when the adapter is removed. Once configured, the integrated backup comparator automatically triggers the converter to discharge the battery, holding up the PMID node and transitioning into backup mode without host intervention.

The charger provides various safety features for battery charging and system operations, including battery temperature negative thermistor (NTC) monitoring, trickle charge, pre-charge and fast charge timers and over-voltage/over-current protections on the battery and the charger power input pin. The thermal regulation reduces charge current when the die temperature exceeds a programmable threshold. The STAT output of the device reports the charging status and any fault conditions. The  $\overline{\text{INT}}$  pin immediately notifies the host when a fault occurs.

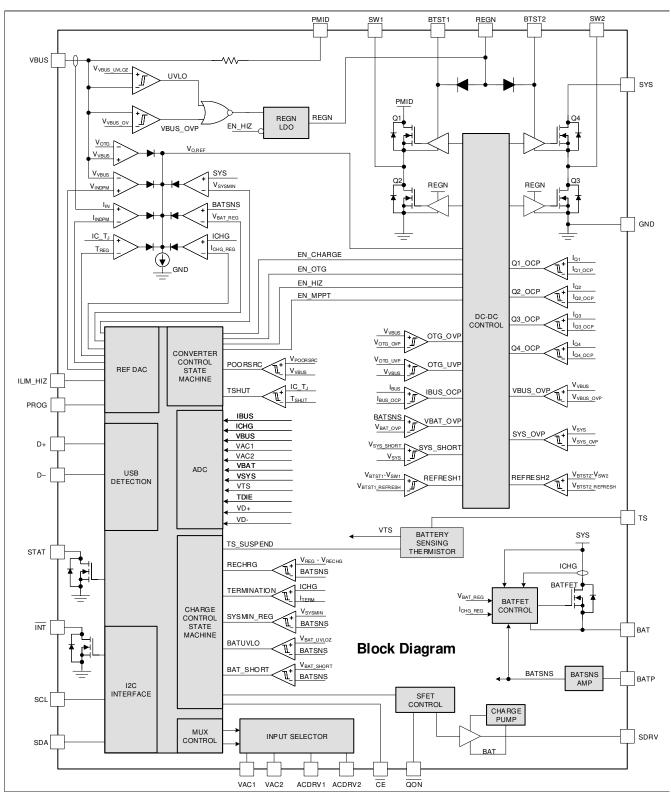
The device also provides a 16-bit analog-to-digital converter (ADC) for monitoring charge current and input/battery/system voltages, the TS pin voltage and the die temperature. It is available in a 29-pin 4.0 mm  $\times$  4.0 mm QFN package.

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# 9.2 Functional Block Diagram



13.7 k Ω

17.4 kΩ

27.0 kΩ

# 9.3 Feature Description

#### 9.3.1 Device Power-On-Reset

The internal bias circuits of the BQ25798 are powered from the higher of either  $V_{VBUS}$  or  $V_{BAT}$  through an integrated power selector. The valid voltage to power up the device has to be greater than  $V_{VBUS\_UVLOZ}$  when powering from VBUS or  $V_{BAT\_UVLOZ}$  when powering from BAT. When  $V_{VBUS} < V_{VBUS\_UVLOZ}$ ,  $V_{BAT} < V_{BAT\_UVLOZ}$  and a voltage higher than  $V_{AC\_PRESENT}$  is present at either VAC1 or VAC2, the device will be powered from  $V_{AC1}$  or  $V_{AC2}$ , depending on which comes first.

## 9.3.2 PROG Pin Configuration

750 kHz

1.5 MHz

750 kHz

At POR, the charger detects the PROG pin pull down resistance, then sets the charger default POR switching frequency and the battery cell count. Please follow the resistance list in 表 9-1 to set the desired POR switching frequency and battery cell count. The surface mount resistor with ±1% or ±2% tolerance is recommended.

**SWITCHING FREQUENCY CELL COUNT** TYPICAL RESISTANCE AT PROG PIN 1.5 MHz 1s  $3.0 k\Omega$ 750 kHz 1s  $4.7 k\Omega$ 1.5 MHz 2s  $6.04 k\Omega$ 750 kHz 2s  $8.2 k\Omega$ 1.5 MHz 3s 10.5 k Ω

3s

4s

4s

表 9-1. PROG Pin Resistance to Set Default Switching Frequency and Battery Cell Count

Some of the charging parameters default values are determined by the battery cell count identified by PROG pin configuration, which are summarized in the table below.

CELL (REG0x0A[7:6])	1s	2s	3s	4s
ICHG (REG0x03/04)	1A	1 A	1 A	1 A
VSYSMIN (REG0x00[5:0])	3.5 V	7 V	9 V	12 V
VREG (REG0x01/02)	4.2 V	8.4 V	12.6 V	16.8 V
VREG Range	3 V - 4.99 V	5 V - 9.99 V	10 V - 13.99 V	14 V - 18.8 V

表 9-2. Charging Parameters Dependent on Battery Cell Count

After POR, the host can program the ICHG and VSYSMIN registers to any values within the ranges defined in the register tables. However, when programming the battery charging voltage (VREG), the host must ensure the VREG value is in the allowed range associated with the CELL register (REG0x0A[7:6]) setting defined in the table above. When the CELL register is changed, the ICHG, VSYSMIN and VREG registers are reset to the POR default values associated with the CELL setting.

For example, if the PROG pin resistance is a 2s battery configuration, the default POR CELL, ICHG, VSYSMIN and VREG settings will be 2s, 1 A, 7 V and 8.4 V respectively. After POR, the host can change ICHG and VSYSMIN to any values, and can change VREG to any value between 5V and 9.99V. Assuming that the CELL bits remain at the 2s battery configuration, then when the REG\_RST bit is set or the watchdog timer expires, the registers are reset to default values with ICHG, VSYSMIN and VREG automatically returing to 1 A, 7V and 8.4V respectively.

When the CELL register is 2s battery configuration, any write out of the range of VREG (5 V - 9.99 V) is ignored by the charger. If VREG needs to be programmed out of the 5 V - 9.9 V range, such as 11 V, the CELL bits have to be changed to the 3s setting. Setting the CELL bits will also cause the ICHG, VSYSMIN and VREG registers to reset to their 3s POR default values of 1 A, 9 V and 12.6 V. Then the host can program VREG in the range of

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10 V - 13.99 V. If, after changing the CELL bits to 3S, the REG\_RST bit is set or the watchdog timer expires, the ICHG, VSYSMIN and VREG will then be reset to 1 A, 9 V and 12.6 V, regardless of the state of the PROG pin.

#### 9.3.3 Device Power Up from Battery without Input Source

If only battery is present and the voltage is above UVLO threshold (VBAT UVLOZ), the BATFET turns on and connects the battery to the system. The REGN LDO stays off to minimize the quiescent current. The low R<sub>DS(ON)</sub> of BATFET and the low quiescent current on BAT minimize the conduction loss and maximize the battery run

The POR sequence when the charger is powered from V<sub>BAT</sub> is described as below:

- 1. 5 ms (typical) after  $V_{BAT} > V_{BAT\ UVLOZ}$ , the charger starts ACFET-RBFET detection, reads the resistance at the PROG pin, and then configures the charger POR register set accordingly.
- 2. 20 ms (typical) after  $V_{BAT} > V_{BAT}$  uvLOZ, the I<sup>2</sup>C registers become accessible to the host...
- 3. The charger turns the battery FET on to allow the battery to power the system.

#### 9.3.4 Device Power Up from Input Source

When an input source is present at VBUS, the device checks the input source voltage to turn on REGN LDO and all the bias circuits. It detects and sets the input current limit before the buck-boost converter is started. The power up sequence from input source is as listed below:

- 1. The device begins the POR sequence when  $V_{VBUS} > V_{VBUS}$  uvloz if there is a direct path from input to VBUS, or otherwise when  $V_{AC1}$  or  $V_{AC2} > V_{AC\ PRESENT}$ .
- 2. 5 ms (typical) after a valid voltage is first present at either VBUS or VAC1/VAC2 pins, the charger starts the ACFET-RBFET detection, reads the resistance at PROG pin, and then configures the charger power on reset (POR) default register settings accordingly.
- 3. If ACFET-RBFET are detected on the input source pathway, the corresponding ACDRV turns on the pair.
- 4. 20 ms (typical) after valid voltage voltage presence, the I<sup>2</sup>C registers become accessible to the host.
- 5. As soon as V<sub>VBUS</sub> > V<sub>VBUS</sub> <sub>LIVI OZ</sub> (in step 1 or after step 3), VBUS PRESENT STAT is set to 1. 150 ms (typical) later, REGN is turned on.
- 6. Once REGN is on, the charger starts the poor source detection. After a good input source is detected (typically 30 ms if there is no retry), PG\_STAT is set to 1, then the ADC reads the ILIM\_HIZ pin voltage and VBUS voltage and updates the IINDPM and VINDPM registers accordingly.
- 7. When the poor source detection completes, the charger performs D+/D- detection and updates the VBUS STAT and IINDPM registers accordingly.
- 8. 30 ms (typical) after the D+/D- detection completes, the converter starts switching to power SYS and charge the battery.

## 9.3.4.1 Power Up REGN LDO

When the device is powered up from VBUS, the LDO is turned on when  $V_{VBUS\ PRESENT}$  < VBUS <  $V_{VBUS\ OVP}$ . When the device is powered up from battery only condition, the LDO is turned on at either one of the following conditions:

- The charger is operated in the OTG mode
- VBAT is higher than 3.2V, and ADC TS channel is on (ADC EN = 1 and TS ADC DIS = 0)

The REGN LDO supplies internal bias circuits and the MOSFETs gate drivers. The pull-up rails of ILIM\_HIZ, TS, and STAT can be connected to REGN. The INT pin pull-up rail is recommended to be an external 1.8V or 3.3V voltage source, rather than REGN, because at battery only condition, the REGN might not be available. Except the charger related pull up rails, the REGN is not recommended to source any other external circuit. The REGN has to power the internal MOSFETs gate drivers, which is very critical for the charger normal operation.

#### 9.3.4.2 Poor Source Qualification

After the REGN LDO powers up, the device checks the current capability of the input source. The input source has to meet the following requirements in order to move forward to the next power on steps.

- VBUS voltage below V<sub>VBUS OVP</sub>
- 2. VBUS voltage above V<sub>POORSRC</sub> when pulling I<sub>POORSRC</sub> (typical 10 mA)

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Once the conditions are met, the status register bit PG\_STAT is set high and the  $\overline{\text{INT}}$  pin is pulsed to signal the host.

If VBUS\_OVP is detected (failing condition 1 above), an INT pulse is asserted to alert the host if the VBUS\_OVP\_MASK = 0 or the PG\_MASK = 0. The VBUS\_OVP\_STAT and VBUS\_OV\_FLAG fault registers get set, and the PG\_STAT bit remains low. The device automatically retries input source qualification once the overvoltage fault goes away.

If a poor source is detected (when pulling  $I_{POORSRC}$ , the VBUS voltage drops below  $V_{POORSRC}$ ), the EN\_HIZ bit is set to 1, PG\_STAT bit remains low, PG\_FLAG will be set to 1, and an  $\overline{INT}$  pulse will be asserted if PG\_MASK = 0. The device will repeat the poor source qualification routine every 7 minutes until either the adapter is removed or the source is qualified. Each failed poor source qualification will cause EN\_HIZ and PG\_FLAG to be set to 1, and an  $\overline{INT}$  pulse will be asserted if PG\_MASK = 0. In the 7 minute interim between poor source qualification attempts, the host may set EN\_HIZ = 0 to force an immediate retry of the poor source qualification. The EN\_HIZ bit is cleared automatically when the adapter is plugged in, so cycling the adapter will also force an immediate retry of the poor source qualification.

#### 9.3.4.3 ILIM HIZ Pin

At POR, before the charger converter starts switching, the charger ADC reads the ILIM\_HIZ pin voltage, and calculates the input current limit (ILIM) set by this ILIM\_HIZ pin, according to:

$$V_{\text{ILIM HIZ}} = 1V + 800 \text{ m} \Omega \times \text{ILIM}$$
 (1)

The ILIM\_HIZ pin sets a high clamp for the IINDPM register. If the IINDPM setting from the D+/D- detection or the POR default 3A IINDPM setting is higher than the ILIM clamp, the IINDPM register stays at this ILIM clamp. In addition, the host cannot program the IINDPM register to any values higher than this ILIM clamp after POR, unless the register bit EN\_EXTILIM is set to 0.

The ILIM\_HIZ pin can be biased from a resistor voltage divider tied to either REGN or another external voltage source. For both the forward charging mode and the OTG mode, when the ILIM\_HIZ pin is pulled lower than 0.75V, the charger stops switching and REGN stays on. The charger resumes switching if the ILIM\_HIZ pin voltage becomes higher than 1V.

If the ADC reads the ILIM\_HIZ pin voltage is lower than 1.08V (1V + 800 m $\Omega$  × 100 mA), the charger considers the ILIM clamp to be 100mA, which is the minimal setting of the IINDPM register.

#### 9.3.4.4 Default VINDPM Setting

In the POR sequence, right after the D+/D- detection, the charger initiates an ADC reading on the VBUS pin voltage without any load current (VBUS at no load condition, VBUS<sub>0</sub>) before the converter starts switching. The default VINDPM threshold is set to be VBUS<sub>0</sub> - 1.4 V (VBUS<sub>0</sub> >= 7 V) or VBUS<sub>0</sub> - 0.7V (VBUS<sub>0</sub> < 7 V).

The VBUS $_0$  can be remeasured at any time by setting the register bit FORCE\_VINDPM\_DET=1. The converter stops switching, the ADC measures the VBUS voltage, the VINDPM register field is updated, and then the FORCE\_VINDPM\_DET bit returns to 0. The force VINDPM detection only can be done when VSYS\_STAT = 0 (VBAT > VSYSMIN), otherwise stopping the converter would cause VSYS to drop below VSYSMIN. If VSYS\_STAT = 1 (VBAT < VSYSMIN), VBUS $_0$  measurement does not start, the FORCE\_VINDPM\_DET bit resets to 0 and the VINDPM register retains its current value. The host must ensure there is a battery present prior to setting FORCE\_VINDPDM\_DET = 1, or to allow system to be supported by the battery during detection.

When the measured VBUS<sub>0</sub> is out of the VINDPM register range, the changer sets the VINDPM register to the minimum value (3.6V) or maximum (22V) value as appropriate.

## 9.3.4.5 Input Source Type Detection

After the input source is qualified, the charger runs Input Source Type Detection if AUTO\_INDET\_EN bit is set (default enabled).

The charger follows the USB Battery Charging Specification 1.2 (BC1.2) to detect SDP/CDP/DCP/HVDC input sources and the non-standard adapters through the USB D+/D- lines. After BC1.2 detection is completed, the BC1.2\_DONE\_STAT bit is set to 1, and an INT pulse and BC1.2\_DONE\_FLAG are asserted if

BC1.2\_DONE\_MASK = 0. In addition, when USB DCP is detected, the charger initiates adjustable high voltage adapter handshake on D+/D- if HVDCP detection is enabled by the host. The input type might be changed after HVDCP detection is completed.

After input source type detection, the following registers are changed:

- 1. Input Current Limit (IINDPM) register is changed to set current limit
- 2. VBUS STAT bits change to reflect the detected source

After detection is completed, the host can over-write IINDPM registers to change the input current limit if necessary. The charger input current is limited by the lower of IINDPM register or ILIM\_HIZ pin (when EN\_EXTILIM = 1) regardless of Input Current Optimizer (ICO) setting. When AUTO\_INDET\_EN is disabled, the Input Source Type Detection is bypassed, and the Input Current Limit (IINDPM) register remains unchanged from its previous value.

#### 9.3.4.5.1 D+/D - Detection Sets Input Current Limit

The device contains a D+/D- based input source detection to set the input current limit. The D+/D- detection has four major steps: Data Contact Detect (DCD), Primary Detection, Secondary Detection and High Voltage DCP (HVDCP) detection.

The D+/D- Primary Detection includes standard USB BC1.2 and non-standard adapters. When an input source is plugged in, the device starts standard USB BC1.2 detection first. The USB BC1.2 is capable of identifying Standard Downstream Port (SDP), Charging Downstream Port (CDP) and Dedicated Charging Port (DCP). The non-standard detection is used to distinguish vendor specific adapters based on the unique dividers they apply to the D+/D- pins. The secondary detection is used to distinguish two types of charging ports, CDP and DCP.

A CDP usually requires the attached device to send back an enumeration within 2.5 seconds of CDP plug-in. Otherwise, the port will power cycle back to SDP even the D+/D- detection indicates CDP. This enumeration must be handled externally to the charger.

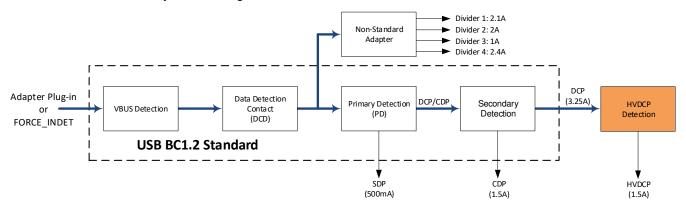


图 9-1. D+/D - Detection Flow

表 9-3. Non-Standard Adapter Detection

NON-STANDARD ADAPTER	D+ THRESHOLD	D - THRESHOLD	INPUT CURRENT LIMIT
Divider 1	$V_{D^+}$ within $V_{2P8\_VTH}$	V <sub>D</sub> within V <sub>2P0_VTH</sub>	2.1 A
Divider 2	$V_{D+}$ within $V_{1P2\_VTH}$	V <sub>D+</sub> within V <sub>1P2_VTH</sub>	2A
Divider 3	$V_{D^+}$ within $V_{2P0\_VTH}$	V <sub>D</sub> within V <sub>2P8_VTH</sub>	1 A
Divider 4	V <sub>D+</sub> within V <sub>2P8_VTH</sub>	V <sub>D</sub> within V <sub>2P8_VTH</sub>	2.4 A

When a Dedicated Charging Port (DCP) is detected, the charger initiates two high voltage adapter (HVDCP) handshakes to enable the corresponding adapter to output a higher voltage for fast charging. The HVDCP detection can be enabled by setting EN\_HVDCP=1 and then setting either EN\_9V=1 to increase the input voltage to 9V or EN\_12V=1 to increase the input voltage to 12V. When EN\_12V and EN\_9V are both set to 1, the charger starts 12V first.

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After the input source type detection is done, the DPDM\_STAT bit is set to 0, an  $\overline{\text{INT}}$  pulse and DPDM\_DONE\_FLAG are asserted if DPDM\_DONE\_MASK = 0. In addition, REG06\_Input\_Current\_Limit and VBUS\_STAT are updated as shown in  $\frac{1}{8}$  9-4.

表 9-4. Input Current Limit Setting from D+/D - Detection

D+/D - DETECTION	INPUT CURRENT LIMIT (IINDPM)	VBUS_STAT_3:0
USB SDP	500 mA	0001
USB CDP	1.5 A	0010
USB DCP	3.25 A	0011
Adjustable High Voltage DCP (HVDCP)	1.5A	0100
Unknown Adapter	3 A	0101
Non-Standard Adapter, Divider 1	2.1 A	0110
Non-Standard Adapter, Divider 2	2 A	0110
Non-Standard Adapter, Divider 3	1 A	0110
Non-Standard Adapter, Divider 4	2.4 A	0110

#### 9.3.4.5.2 HVDCP Detection Procedure

№ 9-1 shows that an HVDCP source is first qualified as a DCP source in the USB BC1.2 standard detection stage, then qualified in the following HVDCP detection stage as an HVDCP source. When the HVDCP is first qualified as a DCP, the charger sets an IINDPM limit of 3.25A. The IIDPM is then updated to the HVDCP limit of 1.5A after the HVDCP handshake completes. In some cases the higher IINDPM limit of 3.25A may interfere with the source's ability to transition to 9V or 12V if the transition is attempted before the IINDPM is updated to 1.5A.

The recommended procedure for enabling detection of HVDCP sources is completed in the following steps:

- Before adapter insertion, the charger is configured with AUTO\_INDET\_EN = 1 and HVDCP\_EN = 0. EN\_12V and EN\_9V are set as desired for the system.
- When an adapter is inserted, it will be detected as SDP, CDP, DCP or a Non-Standard adapter and an I<sup>2</sup>C interrupt is sent to the host. If any detection other than DCP is made, the host proceeds as usual.
- If the adapter is detected as DCP (VBUS\_STAT[3:0] = 0011), the host first changes the Input Current Limit register to 1.5A and then changes HVDCP EN = 1.
- After HVDCP detection is complete, the host sets HVDCP\_EN = 0 to disable HVDCP support in preparation for the next input source detection sequence.

#### 9.3.4.5.3 Connector Fault Detection

The host can apply different status on D+ pin including HIZ, 0V, 0.6V, 1.2V, 2.0V, 2.7V, 3.3V or "short to D-", and different status on D- pin including HIZ, 0.6V, 1.2V, 2.0V, 2.7V or 3.3V. The device also provides ADC readings of the D+ and D- pin voltages. The host can use the information to determine if connector is normal or in any faults. The voltage values are set using the DPLUS\_DAC and DMINUS\_DAC register. The D+/D- pins are only applied at the VAC1 input source. If the DPLUS\_DAC or DMINUS\_DAC are programmed when the adapter is plugged in and the D+/D- detection is in process, the device will ignore the register programming.

## 9.3.5 Dual-Input Power Mux

The BQ25798 has two ACDRV drivers to control two optional sets of back-to-back power N-FETs, selecting and managing the power from two different input sources. In the POR sequence, the charger detects whether the ACFETs-RBFETs are present, then updates the ACRB1\_STAT or ACRB2\_STAT status bits accordingly. The ACFET1-RBFET1 or ACFET2-RBFET2 can be controlled by setting the register bit EN\_ACDRV1 or EN\_ACDRV2. If the external ACFET-RBFET is not present, then tie VAC1 / VAC2 to VBUS and connect ACDRV1 / ACDRV2 to GND. The power MUX drivers support three different application cases, which are elaborated below.

#### 9.3.5.1 ACDRV Turn On Condition

The ACDRV1 and ACDRV2 control the input power MUX. In order to turn on either ACDRV1 or ACDRV2, all of the following conditions must be valid:



- The corresponding ACFET-RBFET was detected at power on: ACDRV is not short to ground.
- VAC is above V<sub>VACpresent</sub> threshold
- VAC is below V<sub>ACOVP</sub> threshold 3.
- 4. DIS ACDRV BOTH is not set to '1'
- 5. EN HIZ is not set to '1'
- 6. VBUS is below V<sub>VBUSpresent</sub> threshold

#### 9.3.5.2 VBUS Input Only

In this configuration, only a single input is connected to VBUS, so that no power MOSFETs are required. VAC1 and VAC2 are shorted to VBUS, and ACDRV1 and ACDRV2 are pulled down to GND, as shown in \ 9-2. At POR, the charger detects that no ACFETs or RBFETs are present by sensing that the ACDRV1 and ACDRV2 pins are both shorted to GND and configures power mux register fields as shown in 表 9-5.

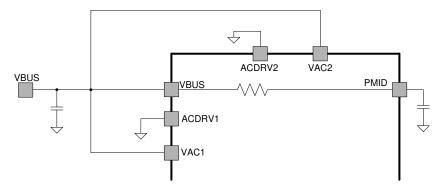


图 9-2. Single Input Connected to VBUS Directly Without ACFET-RBFET

PIN OR REGISTER FIELD	STATE
External MOSFETs	No external power mux MOSFETs.
VAC1 pin	Shorted to VBUS
VAC2 pin	Shorted to VBUS
ACDRV1 pin	Shorted to GND
ACDRV2 pin	Shorted to GND
ACRB1_STAT	0 (Read Only)
ACRB2_STAT	0 (Read Only)
DIS_ACDRV	1
EN_ACDRV1	Locked at 0
EN_ACDRV2	Locked at 0

表 9-5. Single Input Configuration Summary

#### 9.3.5.3 One ACFET-RBFET

In this configuration, only ACFET1-RBFET1 is present, ACFET2-RBFET2 is not. VAC1 is tied to the drain of ACFET1, ACDRV1 is connected to the gates of ACFET1 and RBFET1. VAC2 is shorted to VBUS, ACDRV2 is pulled down to GND. This structure is illustrated in 

9-3, which is able to support either single input (one from VAC1 to VBUS through ACFET1-RBFET1) or dual-input (one from VAC1 to VBUS through ACFET1-RBFET1, the other one connected directly to VBUS) applications. At POR, the charger detects only ACFET1-RBFET1 present and configures the power mux register fields as shown in 表 9-6.

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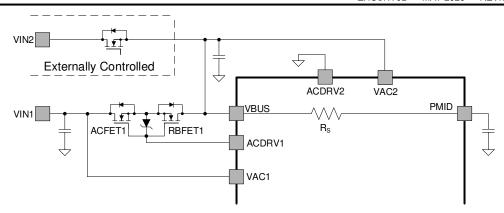


图 9-3. One ACFET-RBFET Structure Supporting One Input at VAC1 and/or One Input at VBUS

表 9-6. Single Input Configuration	Summarv
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₹ 0 0. Only of input Configuration Cummary		
PIN OR REGISTER FIELD	STATE	
External MOSFETs	ACFET1 and RBFET1 only	
VAC1	Connected to input source 1	
VAC2	Shorted to VBUS	
ACDRV1	Connected to ACFET1/RBFET1 gate terminals	
ACDRV2	Shorted to GND	
ACRB1_STAT	0: ACFET1/RBFET1 Open (Path Disabled)	
	1: ACFET1/RBFET1 Closed (Path Enabled)	
ACRB2_STAT	0 (Read Only)	
DIS_ACDRV	0: Allow ACDRV1 On if all requirements met	
	1: Force ACDRV1 Off	
EN_ACDRV1	0: Force ACDRV1 Off	
	1: Turn ACDRV1 On if all requirements met	
EN_ACDRV2	Locked at 0	

When a valid input is presented at VAC1, the charger will set EN\_ACDRV1 = 1 and turn ACFET1-RBFET1 on. To swap from the input at VAC1 to the input at VBUS, the host has to turn off the ACFET1-RBFET1 first by setting DIS\_ACDRV=1 (forcing EN\_ACDRV1 = 0), then enable the other input source which is connected directly to VBUS. To swap from the input at VBUS to the input at VAC1, the host has to disable the input source connected to VBUS, wait for VBUS to fall below  $V_{BUS\_PRESENT}$ , then turn on the ACFET1-RBFET1 by setting DIS\_ACDRV = 0.

#### 9.3.5.4 Two ACFETs-RBFETs

In this scenario, both ACFET1-RBFET1 and ACFET2-RBFET2 are present. VAC1 / VAC2 is tied to the drain of ACFET1 / ACFET2, ACDRV1 / ACDRV2 is connected to the gate of ACFET1 / ACFET2. This structure is developed to support dual-input connected at VAC1 and VAC2. At POR, the charger detects both ACFET1-RBFET1 and ACFET2-RBFET2 present, then updates ACRB1\_STAT and ACRB2\_STAT to 1.



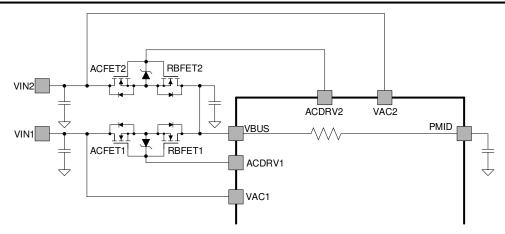


图 9-4. Two ACFETs-RBFETs Structure Supporting One Input at VAC1 and One Input at VAC2

表 9-7. Dual Input Configuration Summary

PIN OR REGISTER FIELD	STATE
External MOSFETs	ACFET1, RBFET1, ACFET2, RBFET2
VAC1 pin	Connected to input source 1
VAC2 pin	Connected to input source 2
ACDRV1 pin	Connected to ACFET1/RBFET1 gate terminals
ACDRV2 pin	Connected to ACFET2/RBFET2 gate terminals
ACRB1_STAT	0: ACFET1/RBFET1 Open (Path Disabled) 1: ACFET1/RBFET1 Closed (Path Enabled)
ACRB2_STAT	0: ACFET2/RBFET2 Open (Path Disabled) 1: ACFET2/RBFET2 Closed (Path Enabled)
DIS_ACDRV	0: Allow ACDRV1 or ACDRV2 on if all requirements met  1: Force ACDRV1 and ACDRV2 off
EN_ACDRV1	0: Force ACDRV1 Off 1: Turn ACDRV1 On if all requirements met
EN_ACDRV2	0: Force ACDRV2 Off 1: Turn ACDRV2 On if all requirements met

In dual input mode, the ACDRV automatically turns on the ACFET-RBFET of the path where a valid input is first presented, without host intervention. If the two inputs are presented at VAC1 and VAC2 exactly at the same time, ACFET1-RBFET1 with higher priority (port #1 is primary) is turned on while ACFET2-RBFET2 stays off (port #2 is secondary). EN\_ACDRV1 is automatically set to 1. If a valid input is presented on the second path while the first path is already on with a valid input, the ACFET-RBFET of the second path remains off. If desired, the host may manually perform a switch between power paths by switching the values of EN\_ACDRV1 and EN\_ACDRV2. Both EN\_ACDRV bits may be updated in a single I<sup>2</sup>C write operation to minimize the transition time. Note that programming EN\_ACDRV1 = 1, EN\_ACDRV2 = 1 at the same time to turn on both ACFET1-RBFET1 and ACFET2-RBFET2 is not allowed, and will be ignored by the charger.

To transition from one input to the other, the device first turns off the initially active ACFET-RBFET pair, waits until the VBUS voltage drops lower than V<sub>BUS\_PRESENT</sub>, and then enables the new ACFET-RBFET pair. During this change over, the converter stops switching for a short period of time.

If two valid voltages are present at VAC1 and VAC2 and the source on the connected path becomes invalid because of VAC\_UVLO, VAC\_OV or IBUS\_OC, the charger automatically swaps the input without any host engagement. Any time that the converter autonomously swaps the source paths, it will also update the EN ACDRV1 and EN ACDRV2 bits accordingly in order to indicate the active power path.

With only one valid input presented at either VAC1 or VAC2, the ACFET1-RBFET1 and ACFET2-RBFET2 can not be both turned off by setting REG0x13[7:6] = 00. Instead, the host should set DIS\_ACDRV = 1 to force both ACFET-RBFET pairs off. With input sources present at both VAC1 and VAC2, the host can turn off the two ACFET-RBFET pairs by setting either REG0x13[7:6] = 00 or DIS ACDRV = 1.

#### 9.3.6 Buck-Boost Converter Operation

The charger employs a synchronous buck-boost converter that allows charging the 1s to 4s battery from a legacy 5V USB input source, HVDCP and USB-PD power sources. The converter operates uninterruptedly and continuously in buck, boost or buck-boost mode depending on the input to system output voltage difference. When the input voltage is close to the system output voltage, the converter operates in a proprietary buck-boost mode.

With a battery attached at BAT and input power at VBUS, the charger can provide at least the MINSYS voltage at SYS and charge current for the battery at BAT. Once the battery voltage reaches the MINSYS voltage, the SYS voltage follows the BAT voltage up. With no battery attached to BAT and input power at VBUS, the voltages at SYS and BAT vary depending on the whether or not charge is enabled as explained below.

- 1. No battery or battery removed and charge disabled by CE pin or EN\_CHG register or thermistor removed from TS pin The charger keeps the BAT pin voltage at low-level, steady-state voltage and regulates SYS pin to MINSYS. The host can monitor the ADC BAT pin voltage and TS fault register to determine when a valid battery is attached.
- 2. No battery or battery removed while charge enabled and TS pin function is disabled The charger continuously tries to charge the BAT capacitance, typically resulting in the BAT voltage alternating between a low level and BATOVP fault. The SYS voltage follows the battery voltage up, potentially reaching SYSOVP fault. In order to determine if a battery is attached, the host must periodically disable charge, force IBAT discharge current and then read the ADC BAT pin voltage. Alternatively, the host can monitor the INT pin for rapid interrupts and then read the charge status bits for fast (<1 s for typical BAT pin capacitance) toggling between charging, taper and termination.</p>

#### 9.3.6.1 Force Input Current Limit Detection

In host mode, the host can force the device to run Input Current Limit Detection by setting FORCE\_INDET bit to 1. After the detection is completed, FORCE\_INDET bit automatically returns to 0. After the detection is completed, the input REG06\_Input\_Current\_Limit (IINDPM), and the VBUS\_STAT bits may be changed by the device according to the detection result.

#### 9.3.6.2 Input Current Optimizer (ICO)

The device provides Input Current Optimizer (ICO) to identify maximum power point in order to avoid overloading the input source. The algorithm automatically identifies maximum input current limit of an unknown power source and sets the charger IINDPM register properly, in order to prevent from entering the charger input voltage (VINDPM) regulation. This feature is disabled by default at POR (EN\_ICO = 0) and only activates when EN\_ICO bit is set to 1.

After DCP type input source is detected based on the procedures described in † 9.3.4.5, the algorithm runs automatically if EN\_ICO bit is set. The algorithm can also be forced to execute by setting FORCE\_ICO bit regardless of input source type detected. Please note that EN\_ICO = 1 is required for FORCE\_ICO to work.

The actual input current limit used by the Dynamic Power Management is reported in the ICO\_ILIM register whether set by ICO if enabled or IINDPM register if not. In addition, the current limit is clamped by the ILIM\_HIZ pin unless EN EXT ILIM bit is 0 to disable the ILIM HIZ pin function.

When V(BAT) > VMINSYS, the ICO algorithm starts with the maximum allowed input current as reported in ICO\_ILIM register as 500 mA then continually increases this limit until the optimal limit is found. When VBAT <



VSYSMIN, the battery voltage can be too low to supplement a large system load if the charger buck converter is limited to 500 mA and then ramped up by the ICO algorithm. Therefore, when a VBAT < VSYSMIN, the ICO algorithm starts with the maximum allowed input current as reported in ICO\_ILIM register to the input current-limit register value in REG0x06 and then continually decreses this limit until the optimal limit is found.

Once the optimal input current is identified, the ICO\_STAT[1:0] and ICO\_FLAG bits are set. The actual input current is reported in the ICO\_ILIM register and does not change unless the algorithm is triggered again by the following events:

- 1. A new input source is plugged-in, or EN\_HIZ bit is toggled
- 2. IINDPM register is changed
- 3. VINDPM register is changed
- 4. FORCE ICO bit is set to 1
- 5. VBUS OVP event

These events also reset the ICO STAT[1:0] bits to 01

#### 9.3.6.3 Maximum Power Point Tracking for Small PV Panel

The device implements a simple algorithm to track the maximum power point (MPP) when the input source is a solar panel. The I-V and P-V curves of a solar panel are most strongly dependent on irradiation and temperature. The MPP is most commonly located between 70%~90% of the Open Circuit Voltage (VOC) of the solar panel. The algorithm automatically and periodically detects the charger input source VOC, and sets the VINDPM to be a ratio of the measured VOC. It is recommended to set the charging current to the maximum value, so that the VINDPM is always triggered and activated. The MPPT algorithm is disabled by default at POR (EN\_MPPT = 0). The algorithm runs automatically when EN MPPT bit is set to 1.

Similar to the FORCE\_VINDPM\_DET feature, when the battery voltage is lower than VSYSMIN (VSYS\_STAT = 1), the MPPT algorithm can not be enabled. The EN\_MPPT bit will be reset back to 0 if it is written to 1. In the MPPT process, the buck-boost charger stops switching and keeps in the non-switching status for a time period programmed by VOC\_DLY[1:0]. When the charger stops switching, the system is powered by the battery discharging. Then the charger measures the open-circuit voltage of the input soruce attached at VBUS and updates the VINDPM to be VOC\_PCT[2:0]\*VOC. The converter starts up again for the VOC\_RATE[1:0] time interval, stops switching for another VOC\_DLY[1:0], measures VOC, and updates the VINDPM register to complete the next cycle. When VBUS goes below VBUS\_PRESENT, the EN\_MPPT bit will be reset to 0, and forced to be 0 even if the host writes it to 1.

For the EN\_ICO, FORCE\_VINDPM\_DET and EN\_MPPT three register bits, only one of them can be set to 1 at a given time. If one of them is enabled, the charger will block the host from enabling the other two features until the first is disabled.

#### 9.3.6.4 Pulse Frequency Modulation (PFM)

In order to improve converter light-load efficiency, the device switches to PFM control at light load condition. The effective switching frequency decreases accordingly as load current decreases. The PFM operation can be disabled by setting PFM\_FWD\_DIS = 1. With PFM disabled, the converter stays at the PWM mode switching frequency and transitions into DCM operation at light load condition. The minimum effective switching frequency in PFM can be limited to 25 kHz to eliminate the audible noise concern if the out of audio (OOA) feature is enabled by setting DIS\_FWD\_OOA = 0. The host can disable the OOA by setting DIS\_FWD\_OOA = 1, which may result in the converter effective switching frequency dropping below 25 kHz at extremely light load. The PFM operation of OTG mode can be independently controlled using the PFM\_OTG\_DIS and DIS\_OTG\_OOA bits. In PFM mode, the converter limits peak inductor current to 2 A, when OOA is enabled, and 3.3 A if OOA is disabled or if the load has increased close to the point of exiting PFM.

## 9.3.6.5 Device HIZ State

The charger enters HIZ mode when EN\_HIZ bit is set to 1. The HIZ mode refers to a charger state, in which the REGN LDO is off, and the converter stops switching even if the adapter is present. Similar to the battery only condition, the charger is in a low quiescent current mode, turns off the ADC and turns on the BATFET to support the system load. The ADC can be re-enabled during HIZ by setting EN ADC =1.

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Some of the faults, such as VBUS\_OVP, VSYS\_OVP, VBAT\_OVP and OTG\_OVP, force the converter to stop switching but keep the REGN and other internal circuits powered on. Alternatively, some of the faults, like VSYS SHORT and IBUS OCP, force the charger into HIZ mode by setting EN HIZ=1. More details could be found in the  $\dagger$  9.3.13.

#### 9.3.7 USB On-The-Go (OTG)

#### 9.3.7.1 OTG Mode to Power External Devices

The device supports the OTG operation to deliver power from the battery to other external devices through the USB ports. The OTG voltage regulation is set in VOTG[10:0] register bits. The OTG current regulation is set in IOTG[6:0] register bits. To enable the OTG operation, the following conditions have to be valid:

- The battery voltage is higher than V<sub>BAT\_OTG</sub> rising threshold, and not trigger the VBAT\_OVP protection.
- The VBUS is below  $V_{VBUS\ UVLO}$ .
- The voltage at TS pin is within the range configured by BHOT and BCOLD register bits

The population of ACFET1-RBFET1 and ACFET2-RBFET2 as detected at POR affects the operation of the converter in OTG mode as summarized in 表 9-8.



ACRB1_STAT	ACRB2_STAT	DIS_ACDRV	OTG BEHAVIOR
0	0	0	Converter starts 5 ms after EN_OTG = 1
0	1	0	EN_OTG = 1 does not start converter until EN_ACDRV2 = 1
1	0	0	EN_OTG = 1 does not start converter until EN_ACDRV1 = 1
1	1	0	EN_OTG = 1 does not start converter until either EN_ACDRV1 = 1 or EN_ACDRV2 = 1
X	Х	1	Converter starts 5 ms after EN_OTG = 1

For swapping the OTG output from port 1 to port 2, assuming EN\_ACDRV2 is already 0, the host has to set  $EN_ACDRV1 = 0$  to turn off ACFET1\_RBFET1 first, which causes the converter to stop switching and VBUS to drop below  $V_{BUS\_PRESENT}$ . The host then sets  $EN_ACDRV2 = 1$ , and the converter starts switching again and ACDRV2 turns on ACFET2-RBFET2, which allows VBUS to ramp up. The similar procedure can be applied to the case of swapping the OTG output from port 2 to port 1.

In OTG mode, the converter PFM operation can be disabled by setting PFM\_OTG\_DIS = 1 and the OOA can be disabled by setting DIS\_OTG\_OOA = 1.

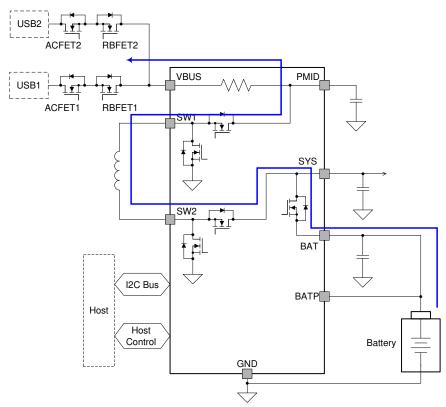


图 9-5. The Simplified Application Diagram for the OTG Mode Operation

The simplified application diagram for the OTG mode operation is shown in 39-5, in which the power flow is illustrated by the blue arrows.

The charger regulates the battery discharging current in OTG mode. When IBAT rises higher than the IBAT\_REG[1:0] register setting, the charger reduces the OTG output current and prioritizes the system load current if there is any. The IBAT\_REG\_STAT bit is set to 1 and an INT pulse is asserted, and if IBAT\_REG\_MASK = 0, the IBAT\_REG\_FLAG is set to 1. If the OTG output current is decreased to zero and the system load pulls even more current, the charger can no longer limit the battery discharging current.

When IBAT\_REG[1:0] is set to 00, 01 or 10 (3A, 4A or 5A), there is a soft-start applied to the OTG ouput current. When IBAT\_REG[1:0] is set to 11 (Disabled) no soft-start is applied.

### 9.3.7.2 Backup Power Supply Mode

By utilizing the charger bidirectional buck-boost operation, BQ25798 supports the backup power supply mode. In this mode, the charger discharges the energy stored in the battery or the capacitors to hold the VBUS voltage for certain amount of time after the adapter is disconnected. The backup mode only can be enabled when VBUS is high, by setting EN\_BACKUP = 1. When VBUS becomes low, the charger resets EN\_BACKUP bit to 0.

A comparator is monitoring the VBUS voltage. Once the adapter is disconnected, and the VBUS drops lower than the pre-set threshold, the charger terminates the forward charging mode, forces EN\_OTG = 1, starts discharging the battery or supercapacitor to regulate the VBUS voltage at the VOTG register setting. After the charger enters the backup mode, the VBUS\_STAT[3:0] is changed to "In the backup OTG mode" status (VBUS\_STAT[3:0] = 1100). At the same time, an  $\overline{\text{INT}}$  pulse is asserted and the VBUS\_FLAG is set to 1, if VBUS MASK = 0.

The comparator thresholds monitoring VBUS to trigger backup mode are programmed in the VBUS\_BACKUP[1:0] register bits, as a ratio of VINDPM values. The host is not able to write EN\_OTG = 1 when VBUS is high. Only when EN\_BACKUP = 1 and VBUS drops lower than the threshold, the charger itself forces EN\_OTG = 1 to enter the backup mode.

The ACFET1-RBFET1 is required for the backup mode operation. Once the backup mode is triggered, the charger turns off the ACFET1-REFET1 by setting DIS\_ACDRV = 1, to avoid back driving the adapter in the event when the adapter is still physically connected at VAC1. The ACFET1-RBFET1 also provides the charger input over-voltage (VAC\_OVP) protection. When the input voltage is higher than the programmable VAC\_OVP threshold (VAC\_OVP[1:0]), the charger turns off the ACFET1-RBFET1, changes from forward charging mode to backup mode. If there is no ACFET1-RBFET1 detected at POR, the charger blocks backup mode from being enabled by forcing EN\_BACKUP = 0.

If the charger is running in backup mode, either of the two conditions listed below can force the charger to exit the backup operation:

- When the battery or the capacitors voltage is discharged lower than  $V_{BAT\ OTGZ}$
- The host sets the EN\_OTG bit from 1 to 0

If there is an adapter reconnected while the charger is in backup mode, the user may transition the source which powers the PMID load from the battery back to the adapter. The following sequence is used to switch from the battery power back to ACIN1 while simultaneously re-arming the backup mode:

- 1. Write BKUP\_ACFET1\_ON (REG0x16[0]) register bit to 1. Setting BKUP\_ACFET1\_ON = 1 will cause the device to set DIS\_ACDRV = 0 and EN\_ACDRV1 = 1. After that, backup mode is disabled, however, the charger remains in the normal OTG mode. The ACFET1-RBFET1 is turned on to connect the adapter to VBUS. The user must ensure the adapter voltage is equal to or higher than the charger VOTG voltage setting, otherwise, the charger OTG output might back drive the adapter connected to VBUS.
- 2. Determine the source at ACIN1 is valid (is not in overvoltage and did not fail poor source detection) by reading back EN\_ACDRV1 as 1.
- 3. Set EN\_OTG = 0, in order to exit OTG mode and enter the forward charging mode without PMID voltage crash. Setting BKUP\_ACFET1\_ON = 1, also clears BKUP\_ACFET1\_ON to 0 and sets EN\_BACKUP to 1.

In a normal adapter attach sequence, the poor source detection is run, the ILIM pin is measured to set IINDPM and the VBUS is measured to set the VINDPM. In order to complete step 3 in the above sequence to re-arm the backup mode without allowing the power stage to be turned off, this sequence is skipped. This allows the converter to quickly transition back into backup mode if the adapter is unexpectedly removed during the sequence. This only occurs when EN\_OTG is set to 0 while BKUP\_ACFET1\_ON = 1. If BKUP\_ACFET1\_ON = 0, or EN\_OTG is already 0 when the adapter is attached, the charger powers up normally. It is generally recommended to allow 5 seconds of settling time before attempting to re-arm backup mode.

Because VBUS is not measured during the re-arming sequence, the VINDPM is not updated. In most applications, the device is expected to support a single adapter so that the previously-set VINDPM value is still accurate. For those applications where different adapter voltages are possible, the user can manually set the

VINDPM value by measuring VBUS with the ADC before initiating the re-arming sequence, scaling the value and writing into the REG05 Input Voltage Limit Register.

In order to transition back to adapter power without dropping VBUS, but keep backup mode disarmed, the following sequence is used:

- 1. Write BKUP\_ACFET1\_ON (REG0x16[0]) register bit to 1. Setting BKUP\_ACFET1\_ON = 1 will cause the device to change EN\_BACKUP = 0, DIS\_ACDRV = 0 and EN\_ACDRV1 = 1. After that, backup mode is disabled, however, the charger remains in the normal OTG mode. The ACFET1-RBFET1 is turned on to connect the adapter to VBUS. The user must ensure the adapter voltage is equal to or higher than the charger VOTG voltage setting, otherwise, the charger OTG output might back drive the adapter connected to VBUS.
- 2. Determine the source at ACIN1 is valid (is not in overvoltage and did not fail poor source detection) by reading back EN ACDRV1 as 1.
- 3. Set BKUP ACFET1 ON = 0
- 4. Set EN\_OTG = 0, in order to exit OTG mode and enter the forward charging mode without PMID voltage crash. Since BKUP ACFET1 ON is 0, EN BCKUP will remain at 0.

The simplified application diagram for the backup mode is shown as the figure below, in which the power flow is illustrated by the blue arrow.

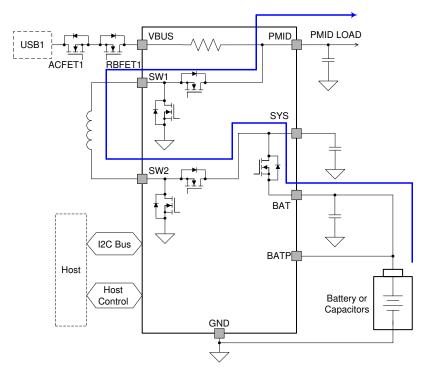


图 9-6. The Simplified Application Diagram for the Backup Mode

The battery discharge current will be limited during backup mode if IBAT\_REG[1:0] is set to 00, 01 or 10 (3A, 4A or 5A.) It is recommended to set IBAT\_REG[1:0] = 11 (Disabled) when using backup mode in order to have optimal response. Depending on the loading at PMID, additional low ESR capacitance up to 200  $\,\mu$ F may be necessary to prevent PMID dipping below the VINDPM set point.

### 9.3.7.3 Backup Mode with Dual Input Mux

BQ25798 backup mode has been optimized for use with a single input source, populating ACFET1-RBFET1 as described in  $\ddagger$  9.3.7.2.

It is possible to use the backup power supply mode in conjuntion with the dual-input mux. Either ACIN1 or ACIN2 can transition into backup mode without dropping PMID when backup mode is enabled and the currently active

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source is removed. However, when BQ25798 transitions from backup mode to ACIN2, PMID will drop to GND for a brief period of time. Only ACIN1 supports transitioning back from backup mode without dropping PMID.

The following sequence is used to transition the source which powers the PMID load from the battery to the ACIN2 source while optionally re-arming the backup mode:

- 1. Set EN BACKUP = 0.
- 2. Set DIS\_BOTH\_ACDRV = 0
- 3. Set EN ACDRV2 = 1
- 4. Determine the source at ACIN2 is valid (is not in overvoltage and did not fail poor source detection) by reading back EN ACDRV2 as 1.
- 5. Set EN\_OTG = 0, in order to exit OTG mode and enter the forward charging mode without PMID voltage crash.
- 6. (Optional) Set EN BACKUP to 1 to rearm backup mode.

### 9.3.8 Power Path Management

The device accommodates a wide range of input voltage range from 3.6V to 24V covering the legacy 5V USB input, HVDCP, USB-PD input and the wall adapter. The device provides automatic power path selection to supply the system (SYS) from input source (VBUS), battery (BAT) or both.

#### 9.3.8.1 Narrow VDC Architecture

The device deploys Narrow VDC architecture (NVDC) with BATFET separating system from battery. The minimum system voltage is set by VSYSMIN bits. Even with a fully depleted battery, the system is regulated above the minimum system voltage. The default minimum system voltage at POR is determined according to the PROG pin configuration resistor.

The NVDC architecture also provides charging termination when the battery is fully charged. By turning off the BATFET, the adapter power is prioritized to support the system, which avoids having the battery continuously charged and discharged by the system load even if the adapter is present. This is important for extending the battery life time.

When the battery voltage is below the minimum system voltage setting, the BATFET operates in linear mode (LDO mode), and the system is regulated at around 200 mV above the minimum system voltage setting. As the battery voltage rises above the minimum system voltage, the BATFET is fully on and the voltage difference between the system and battery is the  $R_{\rm DS(ON)}$  of the BATFET multiplied by the charging current. When battery charging is disabled and VBAT is above the minimum system voltage setting or charging is terminated, the system is always regulated at 200mV (typical, PWM switching) or 600mV (typical, PFM switching) above battery voltage. The status register VSYS\_STAT bit goes high when the system is in minimum system voltage regulation.

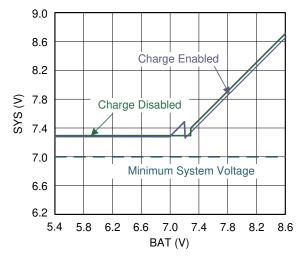


图 9-7. Typical System Voltage vs Battery Voltage for a 2S Battery Configuration

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### 9.3.8.2 Dynamic Power Management

To use the maximum available current from the input power source without over loading the adapter, the BQ25798 features Dynamic Power Management (DPM), which continuously monitors the input current and input voltage. When the input power at the VBUS pin is too low to support the load from SYS pin and the battery charge current from BAT pin, the charger engages either IINDPM to limit its current or VINDPM to prevent further reduction in VBUS pin voltage.

When the system voltage is regulated at VSYSMIN and SYS voltage temporarily drops lower than VSYSMIN, the VSYSMIN loop reduces charging current so that the SYS voltage remains at the VSYSMIN level. If the charge current falls to zero, but the input source is still overloaded, the SYS voltage will drop. Once the SYS voltage falls below the battery voltage, the device automatically enters supplement mode in which the BATFET turns on. The battery starts discharging so that the system is supported from both the input source and battery. The battery FET operates in ideal diode mode, driving the battery FET gate voltage to regulate the BATFET  $V_{DS}$  at 25 mV for low current. This prevents SYS voltage oscillations from entering and exiting the supplement mode. As the discharge current increases, the ideal diode loop drives the BATFET gate to a higher voltage, in order to reduce the battery FET  $R_{DS(ON)}$  until the BATFET is fully turned on. Once the BATFET is fully on, the  $V_{DS}$  linearly increases with the discharge current.  $\mathbb{Z}$  9-8 shows the V-I curve of the BATFET ideal diode operation. The BATFET turns off to exit supplement mode when the battery is below battery depletion threshold.

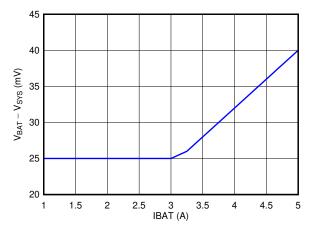


图 9-8. BATFET I-V Curve

During DPM mode, the status register bits VINDPM\_STAT (VINDPM) and/or IINDPM\_STAT (IINDPM) go high. 

9-9 shows the DPM response with 5V/3A adapter, 6.4V battery, 1.5A charge current and 6.8V minimum system voltage setting.

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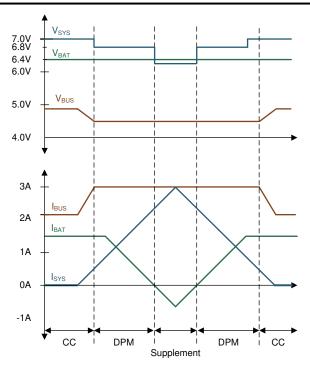


图 9-9. DPM Response

### 9.3.9 Battery Charging Management

BQ25798 charges 1S~4S Li-Ion batteries with up to 5A charge current for high capacity cells. The battery charging in different stages is controlled by the integrated BATFET. The low R<sub>DS(ON)</sub> BATFET improves charging efficiency and minimizes the voltage drop during discharging.

#### 9.3.9.1 Autonomous Charging Cycle

When battery charging is enabled (EN\_CHG bit =1 and  $\overline{\text{CE}}$  pin is LOW), the device autonomously completes a charging cycle without host involvement. The device default charging parameters are listed in  $\frac{1}{8}$  9-9. The host can always control the charging operation and optimize the charging parameters by writing to the corresponding registers through I<sup>2</sup>C.

**DEFAULT MODE** BQ25798 Charging voltage (REG01\_Charge\_Voltage\_Limit) 4.2 V (1S), 8.4 V (2S), 12.6 V (3S), 16.8 V (4S) Recharging voltage threshold (VRECHG) 200 mV Fast charge current (REG03\_Charge\_Current\_Limit) 2 A (1S and 2S), 1 A (3S and 4S) Pre-charge current (IPRECHG) 120 mA Trickle charge current (fixed value) 100 mA Termination current (ITERM) 200 mA Temperature profile (REG17 NTC Control 0, **JEITA** REG18\_NTC\_Control\_1) Fast charge safety timer (CHG TMR) 12 hours Pre-charge safety Timer (PRECHG TMR) 2 hours Trickle charge safety Timer (fixed value) 1 hour

表 9-9. Charging Parameter Default Settings

A new charge cycle starts when the following conditions are valid:

- VBUS > V<sub>VBUS\_PRESENT</sub>
- VBAT < VRECHG for TRECHG deglitch time</li>

- Battery charging is enabled by setting register bit EN CHG = 1 and keeping CE pin LOW
- No thermistor fault on TS pin
- · No safety timer fault

The charger automatically terminates the charging cycle when the charging current is below termination threshold, charge voltage is above recharge threshold, and the device is not in DPM mode or thermal regulation. When a fully charged battery voltage is discharged below recharge threshold (threshold selectable via VRECHG[1:0] bits), the device automatically starts a new charging cycle. After the charging terminates, toggling either  $\overline{\text{CE}}$  pin or EN CHG bit initiates a new charging cycle.

The STAT output indicates the charging status of: charging (LOW), charging complete or charging disabled (HIGH) or charging fault (Blinking). The STAT output can be disabled by setting DIS\_STAT = 1. In addition, the status register (CHG\_STAT) indicates the different charging phases as:

- 000 Not Charging
- 001 Trickle Charge (VBAT < V<sub>BAT SHORTZ</sub>)
- 010 Pre-charge (V<sub>BAT SHORTZ</sub> < VBAT < V<sub>BAT LOWV</sub>)
- 011 Fast Charge (CC mode)
- 100 Taper Charge (CV mode)
- 101 Reserved
- 110 Top-off Timer Active Charging
- 111 Charge Termination Done

When the charger transitions to any of these states, including when the charge cycle completes, an  $\overline{\text{INT}}$  is asserted to notify the host.

### 9.3.9.2 Battery Charging Profile

The device charges the battery in five phases: trickle charge, pre-charge, constant current, constant voltage, and top-off trickle charging (optional). At the beginning of a charging cycle, the device checks the battery voltage and regulates current/voltage accordingly.

	70 To Boldan Granging Garront Gotting									
VBAT	CHARGING CURRENT	REGISTER DEFAULT SETTING	CHRG_STAT							
< V <sub>BAT_SHORT</sub>	I <sub>BAT_SHORT</sub>	100 mA (fixed value)	001							
V <sub>BAT_SHORTZ</sub> to V <sub>BAT_LOWV</sub>	I <sub>PRECHG</sub>	120 mA	010							
> V <sub>BAT LOWV</sub>	ICHG	1 A	011							

表 9-10. Default Charging Current Setting

If the charger is in DPM regulation or thermal regulation during charging, the actual charging current is less than the programmed value. In this case, termination is temporarily disabled and the charging safety timer is counted at half the clock rate, as explained in  $\ddagger 9.3.9.4$ .

During SYSMIN regulation with BATFET LDO operation, the charge current is limited to 2 A maximum, regardless of the charge current register setting being set higher than 2 A, in order to protect the BATFET. It is not recommended to set the battery regulation voltage lower than the SYSMIN regulation voltage. The BATFET LDO operation can be disabled by setting DIS\_LDO = 1. In this state, charge current is regulated according to  $\frac{1}{8}$  9-10 and SYS voltage is V(BAT) plus the IR drop through the BATFET, regardless of battery voltage. No VSYSMIN is maintained. Note that, when in trickle charge, setting DIS\_LDO = 1 does not affect I<sub>BAT\_SHORT</sub>.

 $V_{BAT\_SHORTZ}$  is the battery voltage threshold for transition from trickle charge to precharge, which is fixed at 2.25V typical. During the trickle charge to precharge transition, the charger regulates the battery voltage to 2.5V/cell typical for  $t_{BAT\_SHORTZ}$  duration.  $V_{BAT\_LOWV}$  is the battery voltage threshold for the transition from precharge to fast charge. It is defined as a ratio of battery voltage regulation limit (VREG).

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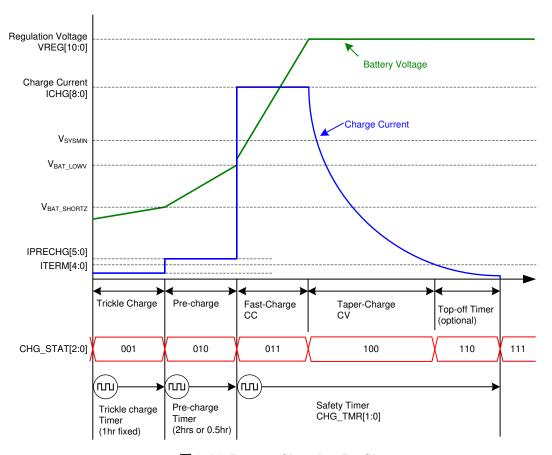


图 9-10. Battery Charging Profile

### 9.3.9.3 Charging Termination

The device terminates a charge cycle when the battery voltage is above the recharge threshold, the converter is operated in the battery constant voltage regulation loop and the current is below the termination current. After the charging cycle is completed, the BATFET turns off. The converter keeps running to power the system and the BATFET can turn on again if the supplement mode is triggered.

When termination is done, the status register CHG\_STAT is set to 111 and an  $\overline{\text{INT}}$  pulse is asserted to the host. Termination is temporarily disabled when the charger device is in input current (IINDPM), input voltage (VINDPM) or thermal (TREG) regulation. Termination can be permanently disabled by writing 0 to EN\_TERM bit prior to charging termination. Writing 0 to EN\_TERM when the termination has already occurred or in the top-off charging stage does not disable termination, until the next charging cycle has been restarted. If termination is enabled by setting EN\_TERM = 1 during an active charging cycle, the change is applied immediately.

At low termination currents (from 40mA to 160mA), due to the comparator offset, the actual termination current may be up to 20%~40% higher than the termination target. In order to compensate for the comparator offset, a programmable top-off timer (default disabled) can be activated after termination. While the top-off timer is running, the device continues to charge the battery in constant voltage mode (BATFET stays on) until the top-off time expires. The top-off timer follows safety timer constraints, such that if the safety timer is suspended, so is the top-off timer, and if the safety timer is doubled, so is the top-off timer. CHG\_STAT reports whether the top off timer is active via the 110 code. Once the top-off timer expires, charging terminates, the CHG\_STAT register is set to 111 and an  $\overline{\text{INT}}$  pulse is asserted to the host.

The top-off timer gets reset (set to 0 and counting resumes when appropriate) for any of the following conditions:

- 1. Charge disable to enable
- 2. Termination status low to high
- 3. REG RST register bit is set (disables top-off timer)

Once the charger detects termination, the charger reads the top-off timer (TOPOFF\_TMR) settings. Programming the top-off timer value after termination has no effect unless a recharge cycle is initiated. The top-off timer only starts to count when the charger's termination criteria are met. If EN\_TERM = 0, the charger never terminates charging, so the top-off timer does not start counting, even if it is enabled. An  $\overline{\text{INT}}$  is asserted to the host when the top-off timer starts counting as well as when the top-off timer expires. All charge cycle related  $\overline{\text{INT}}$  pulses (including top-off timer  $\overline{\text{INT}}$  pulse) can be masked by CHG MASK bit.

#### 9.3.9.4 Charging Safety Timer

The device has a built-in safety timer to prevent an extended charging cycle due to abnormal battery conditions. The user can program the fast charge safety timer through I<sup>2</sup>C (CHG\_TMR bits). When the fast charge safety timer expires, the fault register CHG\_TMR\_STAT bit is set to 1, and an  $\overline{\text{INT}}$  pulse is asserted to the host. The trickle charge timer is fixed 1 hour. The pre-charge safety timer is adjustable 2 hours (POR default) or 0.5 hour. The fast charging timer POR default setting is 12 hours.

The trickle charge, pre-charge and fast charge safety timers can be disabled by setting EN\_TRICHG\_TMR, EN\_PRECHG\_TMR or EN\_CHG\_TMR bit to 0. Each charging safety timer can be enabled anytime regardless of the current charging state. Each timer restarts counting when it is enabled. As soon as each charging stage is initiated, the associated safety timer starts to count, which is illustrated in the battery charging profile chart shown in  $\ddagger$  9.3.9.2.

During input voltage, current or thermal regulation, the safety timer counts at half-clock rate as the actual charge current is likely to be below the register setting. For example, if the charger is in input current regulation (IINDPM\_STAT = 1) throughout the whole charging cycle, and the safety timer is set to 5 hours, then the timer will expire in 10 hours. This half-clock rate feature can be disabled by setting TMR2X\_EN = 0. If the host disables the half-clock rate while the charger is already running at half-clock rate, the charger keeps running at the half-clock rate and the half-clock rate is not disabled until the charger exit the voltage, current or thermal regulation.

During faults which disable charging or supplement mode, the timer is suspended. Since the timer is not counting in this state, the TMR2X\_EN bit has no effect. Once the fault goes away, the safety timer resumes. The pre-charge safety timer and the trickle charge safety timer follow the same rules as the fast charge safety timer in terms of getting suspended, reset and counting at half-rate when TMR2X\_EN is set.

The fast charge timer is reset at the following events:

- 1. Charging cycle stop and restart (toggle  $\overline{\text{CE}}$  pin, EN\_CHG bit, or charged battery falls below recharge threshold after termination)
- 2. BAT voltage changes from pre-charge to fast-charge or vice versa (in host-mode or default mode)
- 3. A change of the value of CHG\_TMR[1:0] register bits

The pre-charge timer is reset at the following events:

- 1. Charging cycle stop and restart (toggle  $\overline{\text{CE}}$  pin, EN\_CHG bit, or charged battery falls below recharge threshold)
- 2. BAT voltage changes from trickle charge to pre-charge or vice versa, pre-charge to fast charge or vice versa (in host-mode or default mode)
- 3. A change of the value of PRECHG\_TMR register bit.

The trickle charge timer is reset at the following events:

- 1. Charging cycle stop and restart (toggle  $\overline{\text{CE}}$  pin, EN\_CHG bit, or charged battery falls below recharge threshold)
- 2. BAT voltage changes from trickle charge to pre-charge or vice versa (in host-mode or default mode)

#### 9.3.9.5 Thermistor Qualification

The charger device provides a single thermistor input for battery temperature monitoring.

#### 9.3.9.5.1 JEITA Guideline Compliance in Charge Mode

To improve the safety of charging Li-ion batteries, JEITA guideline was released on April 20, 2007. The guideline emphasized the importance of avoiding a high charge current and high charge voltage at certain low and high temperature ranges.

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To initiate a charge cycle, the voltage on TS pin must be within the VT1 to VT5 thresholds. If TS voltage exceeds the VT1-VT5 range, the controller suspends charging and waits until the battery temperature is within the T1 to T5 range.

At cool temperature T1-T2, JEITA recommends to reduce the charge current to be lower than half of the charge current at normal temperature T2-T3. The device provides the programmability of the charge current at T1-T2, to be 20%, 40% or 100% of the charge current at T2-T3 or charge suspend, which is controlled by the register bits JEITA ISETC.

The device provides the programmability of the charge voltage at T3-T5, to be with a voltage offset (0mV, 100mV or 200mV) less than charge voltage at T2-T3 or charge suspend, which is controlled by the register bits JEITA VSET.

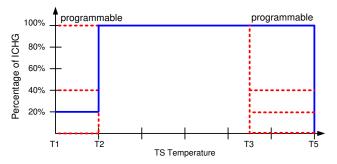
The charger also provides flexible voltage/current settings beyond the JEITA requirements. The charge current setting at warm temperature T3-T5 can be configured to be 20%, 40% or 100% of the charge current at T2-T3 or charge suspend, which is programmed by the register bits JEITA ISETH.

The charge termination is still enabled (when EN\_TERM=1) at cool temperature T1-T2 and warm temperature T3-T5. The termination current will be kept as the same in all different temperature ranges. In the normal operation, the charge will be terminated based on the charge current is lower than the termination current, the battery voltage is higher than the battery recharge voltage and the charger is in the battery voltage regulation loop. When the temperature enters T1-T2 or T3-T5, the charge current might drop to 20% or 40% of that at T2-T3, which might be lower than the termination current setting. If at this moment, the battery voltage is already higher than the battery recharge voltage and the charger is in the battery voltage regulation loop, the charge will be terminated.

At warm temperature T3-T5, the battery charge voltage will becomes lower. If the battery voltage is already very close to the battery charge voltage at T2-T3, to reduce the charge voltage by an offset might trigger the VBAT\_OVP. The charger should response as the normal VBAT\_OVP protection under this scenario.

At cool temperature T1-T2 or warm temperature T3-T5, the charge current will become different from that at the normal temperature range T2-T3, the safety timer should be adjusted accordingly. The safety timer will be suspended when the charge is suspended, and will run at half of the clock rate when the charge current is reduced to 20% or 40%, and will keep the same when the charge current is unchanged.

JEITA charging values are shown in 🛭 9-11, in which the blue real line is the default setting and the red dash line is the programmable options.



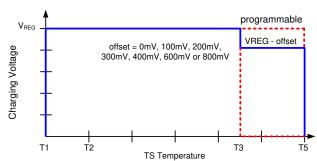


图 9-11. TS Charging Values

The NTC monitoring on the battery temperature can be ignored by the charger if TS\_IGNORE = 1. When the TS pin feedback is ignored, the charger considers the TS is always good for charging and OTG modes. The TS\_STAT including TS\_COLD\_STAT, TS\_COOL\_STAT, TS\_WARM\_STAT and TS\_HOT\_STAT, always report 000 with TS\_IGNORE = 1.

When TS\_IGNORE = 0, the charger adjusts the charging profile based on the TS pin feedback information. When the battery temperature crosses from one temperature range to the other one, the associated TS status bits are updated accordingly. The TS flag bits are set for the temperature range for which the TS voltage is reporting, and an  $\overline{\text{INT}}$  pulse is asserted to alert the host if TS\_MASK is low. The FLAG and  $\overline{\text{INT}}$  pulse can be

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individually masked by properly setting the associated mask bit, to prevent the  $\overline{\text{INT}}$  pulse from alerting the host of battery temperature range changes.

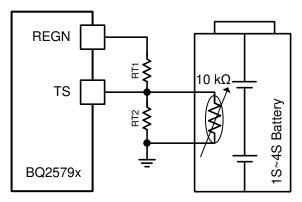


图 9-12. TS Resistor Network

Assuming a 103AT NTC thermistor on the battery pack, the value of TSR1 and TSR2 can be determined by:

$$RT2 = \frac{RTH_{COLD} \times RTH_{HOT} \times \left(\frac{1}{VT1} - \frac{1}{VT5}\right)}{RTH_{HOT} \times \left(\frac{1}{VT5} - 1\right) - RTH_{COLD} \times \left(\frac{1}{VT1} - 1\right)}$$
(2)

$$RT1 = \frac{\frac{1}{VT1} - 1}{\frac{1}{RT2} + \frac{1}{RTH_{COLD}}}$$
(3)

where VT# are the percentages of V(REGN) per the electrical spec table. The BQ25798 provides comparators with fixed thresholds for VT1 x V(REGN) and VT5 x V(REGN), and comparators with programmable thresholds for VT2 x V(REGN) and VT3 x V(REGN). The thresholds for VT2 x V(REGN) and VT3 x V(REGN) are controlled by TS\_COOL and TS\_WARM. This programmability gives more flexibility for the configuration of the JEITA profile. Select T1=0°C and T5=60°C for Li-ion or Li-polymer battery, the RT1 and RT2 are calculated to be  $5.24 \mathrm{K}\,\Omega$  and  $30.31 \mathrm{K}\,\Omega$  respectively.

#### 9.3.9.5.2 Cold/Hot Temperature Window in OTG Mode

For battery protection during OTG mode, the device monitors the battery temperature to be within the VBCOLD to VBHOT thresholds. When RT1 is 5.24 K $\Omega$  and RT2 is 31.31 K $\Omega$ , TBCOLD default is -10°C and TBHOT default is 60°C. When the temperature is outside of this range, OTG mode is suspended, the converter stops switching. The charger waits in OTG mode (EN\_OTG = 1). In addition, the VBUS\_STAT bits are set to 000 and the corresponding TS\_COLD\_STAT or TS\_HOT\_STAT is reported. Once temperature returns to the normal temperature range, OTG mode is recovered and TS stauts bit is cleared. During TS fault, REGN remains on.

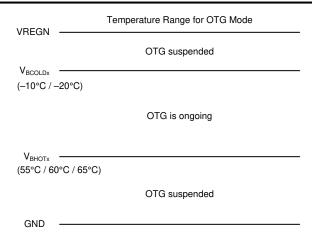


图 9-13. TS Pin Thermistor Sense Threshold in OTG Mode

### 9.3.10 Integrated 16-Bit ADC for Monitoring

The device has an integrated 16-bit ADC to provide the user with critical system information for optimizing the behavior of the charger. The ADC is controlled through the ADC Control register. The ADC\_EN bit provides the ability to disable the ADC in order to conserve power dissipation. The ADC\_RATE bit allows continuous conversion or one-shot behavior. After a 1-shot conversion finishes, the ADC\_EN bit is cleared, and must be reasserted to start a new conversion. The ADC\_AVG bit enables or disables (default) averaging. ADC\_AVG\_INIT starts average using the existing (default) or using a new ADC value.

To enable the ADC, the ADC\_EN bit must be set to 1. The ADC is allowed to operate if either VBUS > 3.4 V or VBAT > 2.9 V is valid. If ADC\_EN is set to 1 before VBUS or VBAT reaches its valid threshold, then the ADC conversion is postponed until one of the power supplies reaches the threshold. If the charger is in HIZ mode, the ADC still can be enabled by setting ADC\_EN = 1. At battery only condition, if the TS\_ADC channel is enabled, the ADC only works when battery voltage is higher than 3.2V, otherwise, the ADC works when the battery voltage is higher than 2.9V.

The ADC\_SAMPLE bits control the ADC sample speed, with conversion times of  $t_{ADC\_CONV}$ . If the host changes the sample speed in the middle of an ADC conversion, the ADC conversion stops the channel being converted, and that channel is reconverted at the new rate. At that point, some of the ADC register values might have been converted with one sample rate and others with a different sample rate.

By default, all ADC channels are enabled with 1-shot or continuous conversion mode unless the channel is disabled in the ADC\_Function\_Disable\_0 or ADC\_Function\_Disable\_1 register. If an ADC channel is disabled by setting the corresponding register bit, then the value in that register is from the last valid ADC conversion or the default POR value (all zeros.) If an ADC channel is disabled in the middle of an ADC measurement cycle, the device finishes the conversion of that channel. Even though no conversion takes place when all ADC channels are disabled, the ADC circuitry is active and ready to begin conversion as soon as one of the bits in the ADC\_Function\_Disable\_0 or ADC\_Function\_Disable\_1 register is set to 0. In order to achieve the lowest quiescent current when disabling all ADC channels, set EN\_ADC to 0 instead of disabling with ADC\_Function\_Disable\_0 and ADC\_Function\_Disable\_1.

The ADC\_DONE\_STAT and ADC\_DONE\_FLAG bits are set when a conversion is complete in 1-shot mode only. This event produces an  $\overline{\text{INT}}$  pulse, which can be masked with ADC\_DONE\_MASK. During continuous conversion mode, the ADC\_DONE\_STAT and ADC\_DONE\_FLAG bits have no meaning and remain 0.

ADC conversion operates independently of the faults present in the device. ADC conversion continues even after a fault has occurred. ADC readings are only valid for DC states and not for transients.

If the host wants to exit the ADC more gracefully, it is recommended to write ADC\_RATE to one-shot in order to force the ADC to stop at the end of a complete cycle of conversions.

ADC Measurement Channels:



- IBUS (positive in forward converter mode)
- IBAT (positive for charging)
- VBUS
- VPMID
- VBAT
- VSYS
- TS
- TDIE

### 9.3.11 Status Outputs (STAT, and INT)

### 9.3.11.1 Charging Status Indicator (STAT Pin)

The device indicates charging state on the open drain STAT pin. The STAT pin can drive an LED. The STAT pin function can be disabled via the DIS\_STAT bit.

#### 表 9-11. STAT Pin State

CHARGING STATE	STAT INDICATOR
Charging in progress (including recharge and charging in top-off timer)	LOW
Charging complete	HIGH
HIZ mode, charge disable	HIGH
Battery only mode and OTG mode	HIGH
Charge suspend (A fault condition which disable charging)	Blinking at 1 Hz

### 9.3.11.2 Interrupt to Host ( INT)

In some applications, the host does not always monitor charger operation. The  $\overline{\text{INT}}$  pin notifies the system host on the device operation. By default, the following events generate an active-low, 256µs  $\overline{\text{INT}}$  pulse.

- 1. Good input source detected
  - V<sub>VBUS</sub> < V<sub>VBUS</sub> OVP threshold
  - V<sub>VBUS</sub> > V<sub>POORSRC</sub> (typical 3.4 V) when I<sub>POORSRC</sub> (typical 30 mA) current is applied (not a poor source)
- 2. VBUS\_STAT changes state (VBUS\_STAT any bit change)
- 3. Good input source removed
- 4. Entering IINDPM regulation
- 5. Entering VINDPM regulation
- 6. Entering IC junction temperature regulation (TREG)
- 7. I<sup>2</sup>C Watchdog timer expired
  - At initial power up, this INT gets asserted to signal I<sup>2</sup>C is ready for communication
- 8. Charger status changes state (CHRG STAT value change), including Charge Complete
- 9. TS STAT changes state (TS\_STAT any bit change)
- 10. VBUS over-voltage detected (VBUS\_OVP)
- 11. VAC over-voltage detected (VAC\_OVP for VAC1 or VAC2)
- 12. Junction temperature shutdown (TSHUT)
- 13. Battery over-voltage detected (BATOVP)
- 14. System over-voltage detected (VSYS OVP)
- 15. IBUS over-current detected (IBUS\_OCP)
- 16. IBAT over-current detected (IBAT OCP)
- 17. Charge safety timer expired, including trickle charge and pre-charge and fast charge safety timer expired
- 18. A rising edge on any of the other \* STAT bits

Each one of these  $\overline{\text{INT}}$  sources can be masked off to prevent  $\overline{\text{INT}}$  pulses from being sent out when they occur. Three bits exist for each one of these events:

- The STAT bit holds the *current status* of each INT source
- The FLAG bit holds information on which source produced an INT, regardless of the current status

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• The MASK bit is used to prevent the device from sending out INT for each particular event

When one of the above conditions occurs (a rising edge on any of the \*\_STAT bits), the device sends out an INT pulse and keeps track of which source generated the INT via the FLAG registers. The FLAG register bits are automatically reset to zero after the host reads them, and a new edge on STAT bit is required to re-assert the FLAG. This sequence is illustrated in  $\boxed{\$}$  9-14.

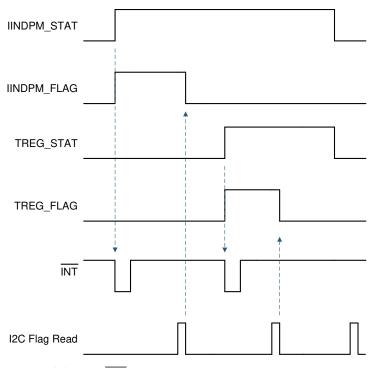


图 9-14. INT Generation Behavior Example

#### 9.3.12 Ship FET Control

The charger provides an N-FET driving pin (SDRV) to control an external ship FET. The SDRV pin is the output of a charge pump that provides 100 nA typical drive current to drive the ship FET gate to typically 5-V above the battery voltage. When this ship FET is off, it removes leakage current from the battery to the system. The ship FET is controlled by the SDRV\_CTRL[1:0] register bits, to support the shutdown mode, ship mode and the system power reset.

- **IDLE Mode** when SDRV\_CTRL[1:0] = 00, POR default. The external ship FET is fully on, I<sup>2</sup>C is enabled. The internal BATFET status is determined by the charging status. This mode is valid with adapter present, during forward charging, in OTG mode or in the battery only condition.
- **Shutdown Mode** when SDRV\_CTRL[1:0] = 01. The ship FET turns off. The I<sup>2</sup>C is disabled. The charger is totally shutdown and can only be woken up by an adapter plug-in. This mode can only be entered when no adapter is present. If SDRV\_CTRL[1:0] is written to 01 with an adapter present, the write is ignored.
- **Ship Mode** when SDRV\_CTRL[1:0] = 10. The ship FET turns off. The I<sup>2</sup>C is still enabled. The charger can be woken up by setting SDRV\_CTRL[1:0] back to 00, or pulling the QON pin low, or an adapter plug-in. This mode can only be entered when no adapter is present. If SDRV\_CTRL[1:0] is written to 01 with an adapter present, the write is ignored.
- System Power Reset when SDRV\_CTRL[1:0] = 11. The ship FET is turned off for typical 350ms to reset the system power (converter goes to HIZ mode if VBUS is high), then the ship FET is fully turned on again. The BATFET keeps the status unchanged during the system power reset. After the reset is done, SDRV\_CTRL[1:0] goes back to 00.

When the host changes SDRV\_CTRL[1:0] from 00 to the other values, the charger turns off the ship FET immediately or delays by  $t_{SM\_DLY}$  as configured by SDRV\_DLY bit. The application diagram when the battery is connected to the charger through an external ship FET is illustrated in the figure below.



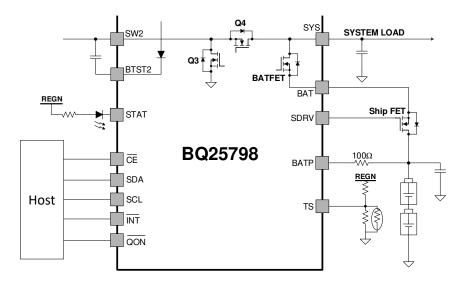


图 9-15. The Application Diagram for the External Ship FET

#### 9.3.12.1 Shutdown Mode

To further reduce battery leakage current, the host can shut down the charger by setting the register bits SDRV\_CTRL[1:0] to 01. In this mode, the I<sup>2</sup>C is disabled and the charger is totally shut down. The device can only be woken up by plugging in an adapter.

After the SDRV\_CTRL[1:0] is set to 01, the external ship FET turns off either immediately or after waiting for 10s as configured by SDRV\_DLY register bit. When VBUS is high because of an adapter being present or the OTG mode being enable, SDRV\_CTRL[1:0] will be reset to 00 if the host writes it to 01.

When the device exits shutdown mode, the SDRV\_CTRL bits are reset to the POR default values (00).

### 9.3.12.2 Ship Mode

To extend battery life and minimize the system power loss when system is powered off during idle, shipping or storage, the device can turn off BATFET and external ship FET to minimize the battery leakage current. The ship mode is enabled when the host sets SDRV\_CTRL[1:0] to 10. The I<sup>2</sup>C is still enabled, but the charger system clock slows down to minimize the device guiescent current.

After the SDRV\_CTRL[1:0] is set to 10, the external ship FET is turned off either immediately or after waiting 10 seconds as configured by SDRV\_DLY register bit. When VBUS is high because of an adapter being present or OTG mode being enabled, SDRV\_CTRL[1:0] automatically resets to 00 if the host writes it to 10.

The following events will cause an exit from ship mode:

- · Plug in an adapter
- Set SDRV CTRL[1:0] = 00
- Set REG\_RST = 1, to reset all the registers including SDRV\_CTRL bits back to default (00)
- A logic low of t<sub>SM EXIT</sub> (typical 1s or 15ms programmed by WKUP DLY bit) duration on QON pin

The charger exits ship mode by turning on the ship FET and internal BATFET to reconnect the battery to the system and resetting SDRV\_CTRL bits to their POR default value (00).

#### 9.3.12.3 System Power Reset

The host can reset the system power by:

- Set the register bits SDRV\_CTRL[1:0] to 11
- A logic low of t<sub>RST</sub> (typical 10s) duration on QON pin

When the system power reset is enabled, the device turns off the ship FET for  $t_{RST\_SFET}$  (typical 350ms) and also sets the charger in HIZ mode if VBUS is high. After the  $t_{RST\_SFET}$  completes, the device then turns on the

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ship FET and disables the charger HIZ mode. While the SFET is off, the charger applies a 30mA (typical) sink current on SYS to discharge system voltage.

Regardless of whether the charger is at battery only condition or in the forward charging mode with adapter present, the charger resets the system power when the SDRV CTRL[1:0] bits are set to 11 or the QON pin is pulled low for t<sub>RST</sub> duration.

#### 9.3.13 Protections

### 9.3.13.1 Voltage and Current Monitoring

The device closely monitors the input, system and battery voltage and current, as well as internal FET currents for safe converter operation. It provides the following protection faults:

- VAC Over-voltage Protection (VAC\_OVP)
- VBUS Over-voltage Protection (VBUS OVP)
- VBUS Under-voltage Protection (POORSRC)
- System Over-voltage Protection (VSYS OVP)
- System Short Protection (VSYS SHORT)
- Battery Over-voltage Protection (VBAT OVP)
- Battery Over-current Protection (IBAT OCP)
- Input Over-current Protection (IBUS OCP)
- OTG Over-voltage Protection (OTG OVP)
- OTG Under-voltage Protection (OTG UVP)

#### 9.3.13.1.1 VAC Over-voltage Protection (VAC OVP)

The charger has a programmable  $V_{VAC\ OVP}$  threshold. When the VAC1 or VAC2 voltage is higher than  $V_{VAC\ OVP}$ threshold per I2C register field, the corresponding ACDRV pin turns off the ACFET-RBFET. An /INT pulse is asserted to alert the host, if the related MASK is low, and the related VACx\_OVP\_STAT and VAC\_OVP\_FLAG report the fault. The charger automatically changes to the valid VAC input if available The ACDRV pin automatically turns the ACFET-RBFET on again when the over-voltage condition goes away.

### 9.3.13.1.2 VBUS Over-voltage Protection (VBUS OVP)

When the VBUS voltage is higher than V<sub>VBUS OVP</sub> (typical 26 V), the converter stops switching immediately to protect the internal power MOSFETs. As the SYS voltage falls below the battery voltage, the BATFET is turned on to supplement the system load. During VBUS over-voltage, an INT pulse is asserted to alert the host, if the VBUS OVP MASK is low, the VBUS OVP STAT and VBUS OV FLAG registers report the fault. The device automatically starts switching again when the VBUS voltage drops below the threshold.

#### 9.3.13.1.3 VBUS Under-voltage Protection (POORSRC)

At power up, the charger pulls IPOORSRC from the input source. If the VBUS voltage falls below VPOORSRC, the charger considers the input voltage as being under-voltage and stops switching. The charger issues an INT pulse is asserted to alert the host if the PG\_MASK is low and the POORSRC\_FLAG, PG\_FLAG and PG STATUS registers report the fault. The charger repeatedly tests for poor source again after 7 minutes typical until a valid source is attached.

#### 9.3.13.1.4 System Over-voltage Protection (VSYS OVP)

If the system voltage rises higher than VSYS OVP threshold, the converter stops switching to protect the power MOSFETs. A /INT pulse is asserted to alert the host if VSYS\_OVP\_MASK is low and the VSYS\_OVP\_STAT and VSYS OVP FLAG registers report the fault. Normal switching resumes when the system voltage returns to its regulation point.

#### 9.3.13.1.5 System Short Protection (VSYS SHORT)

When VSYS drops below VSYS SHORT (2.2V typical), the charger limits the converter output current to less than 1 A. An /INT pulse is asserted to alert the host if VSYS SHORT MASK is low and the VSYS\_SHORT\_STAT and VSYS\_SHORT\_FLAG registers report the fault.

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### 9.3.13.1.6 Battery Over-voltage Protection (VBAT OVP)

When the battery voltage is detected to be higher than 104% typical of the battery charging regulation voltage, the charger turns off the converter to prevent the battery voltage from further increasing. When the battery voltage drops below 102% typical of the battery charging regulation voltage, the converter automatically restarts. The system load is supplied by battery through battery FET when the converter is disabled. A /INT pulse is asserted to alert the host if the VBAT OVP MASK is low and the VBAT OVP STAT and VBAT OVP FLAG register bits report the fault.

#### 9.3.13.1.7 Battery Over-current Protection (IBAT OCP)

Battery over-current protection is available when external ship FET (SFET) is assembled, SFET PRESENT bit is set to 1, and EN BATOC bit is set to 1. When discharge current exceeds IBAT OCP, the SFET turns off to stop the discharge current. Regardless of the EN BATOC bit setting, when the battery discharging current becomes higher than IBATOC, an /INT pulse is asserted to alert the host if IBAT OCP MASK is low and the IBAT OCP STAT and IBAT OCP FLAG register bits report the fault.

#### 9.3.13.1.8 Input Over-current Protection (IBUS OCP)

When EN IBUS OCP=1, the charger monitors the input current in forward charging mode in order to provide IBUS over current protection. If the input current exceeds the IBUS over current threshold IBUS OCP (typical 8A), the charger disables the converter by setting the EN HIZ bit to 1. In addition, the charger sets DIS ACDRV=1 in order to disable both ACDRV1 and ACDRV2. The battery FET turns on to supplement the system load as needed. The host must set EN HIZ and DIS ACDRV bits to 0 in order to restart the converter. Alternatively, removing and replacing the adapter resets the EN HIZ bit and the DIS ACDRV bit to 0. When EN IBUS OCP=0, IBUS over current protection is disabled. Regardless of the EN IBUS OCP bit setting, when the IBUS input current becomes higher than IBUS OCP, an /INT pulse is asserted to alert the host if IBUS OCP MASK is low, the IBUS OCP STAT and IBUS OCP FLAG register bits report the fault.

### 9.3.13.1.9 OTG Over-voltage Protection (OTG OVP)

When the VBUS voltage rises above VOTG\_OVP rising threshold, the converter stops switching in the next switching cycle in order to protect the power MOSFETs. The converter resumes switching when the VBUS voltage falls below the VOTG\_OVP falling threshold. When OTG\_OVP is detected, a /INT pulse is asserted to alert the host if OTG OVP MASK is low and the VOTG OVP STAT and VOTG OVP FLAG fault registers report the fault.

#### 9.3.13.1.10 OTG Under-voltage Protection (OTG\_UVP)

After the converter turns on if the VBUS voltage is lower than VOTG UVP threshold, the charger shuts down for 500ms and retry to turn on. An /INT pulse is asserted to alert the host if OTG UVP MASK is low and the OTG\_UVP\_FLAG register reports the fault.

#### 9.3.13.2 Thermal Regulation and Thermal Shutdown

The device monitors its internal junction temperature (T<sub>J</sub>) to avoid overheating and to limit the IC surface temperature. When the internal junction temperature exceeds the preset thermal regulation limit (TREG bits), the device reduces the charge current or OTG output current to maintain the junction temperature at the thermal regulation limit. A wide thermal regulation range from 60°C to 120°C allows optimization of the system thermal performance. During thermal regulation, the actual charging current is usually below the programmed value in the ICHG registers. Therefore, termination is disabled, the fast charging safety timer runs at half the clock rate, the status register TREG STAT bit goes high, TREG FLAG bit is set to 1, and an INT is asserted to alert host unless TREG MASK is set to 1.

Additionally, the device has thermal shutdown to turn off the converter when the IC junction temperature exceeds the TSHUT threshold. The fault register bits TSHUT STAT and TSHUT FLAG are set and an INT pulse is asserted to the host, unless TSHUT MASK is set to 1. The BATFET and the converter resumes normal operation when the IC die temperature decreases lower than TSHUT threshold by T<sub>SHUT HYS</sub>.

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#### 9.3.14 Serial Interface

The device uses I<sup>2</sup>C compatible interface for flexible charging parameter programming and instantaneous device status reporting. I<sup>2</sup>C is a bi-directional 2-wire serial interface. Only two open-drain bus lines are required: a serial data line (SDA), and a serial clock line (SCL). Devices can be considered as controllers or targets when performing data transfers. A controller is a device which initiates a data transfer on the bus and generates the clock signals to permit that transfer. At that time, any device addressed is considered a target.

The device operates as a target device with 7-bit address 0x6B, receiving control inputs from the controller device like micro-controller or digital signal processor through REG00 - REG25. Register read beyond REG25 (0x25), returns 0xFF. The I<sup>2</sup>C interface supports both standard mode (up to 100 kbits/s), and fast mode (up to 400 kbits/s). When the bus is free, both lines are HIGH. The SDA and SCL pins are open drain and must be connected to the positive supply voltage via a current source or pull-up resistor.

### 9.3.14.1 Data Validity

The data on the SDA line must be stable during the HIGH period of the clock. The HIGH or LOW state of the data line can only change when the clock signal on SCL line is LOW. One clock pulse is generated for each data bit transferred.

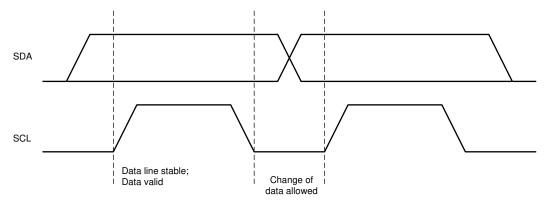


图 9-16. Bit Transfers on the I<sup>2</sup>C Bus

#### 9.3.14.2 START and STOP Conditions

All transactions begin with a START (S) and are terminated with a STOP (P). A HIGH to LOW transition on the SDA line while SCL is HIGH defines a START condition. A LOW to HIGH transition on the SDA line when the SCL is HIGH defines a STOP condition.

START and STOP conditions are always generated by the controller. The bus is considered busy after the START condition, and free after the STOP condition.

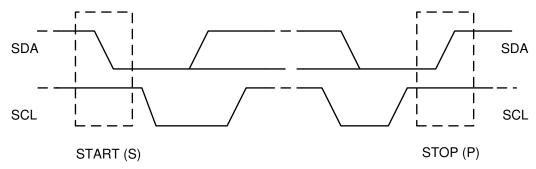


图 9-17. START and STOP Conditions on the I<sup>2</sup>C Bus

### 9.3.14.3 Byte Format

Every byte on the SDA line must be 8 bits long. The number of bytes to be transmitted per transfer is unrestricted. Each byte has to be followed by an ACKNOWLEDGE (ACK) bit. Data is transferred with the Most

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Significant Bit (MSB) first. If a target cannot receive or transmit another complete byte of data until it has performed some other function, it can hold the SCL line low to force the controller into a wait state (clock stretching). Data transfer then continues when the target is ready for another byte of data and releases the SCL line.

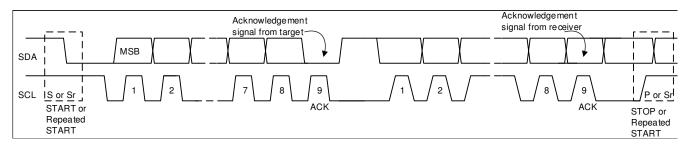


图 9-18. Data Transfer on the I<sup>2</sup>C Bus

### 9.3.14.4 Acknowledge (ACK) and Not Acknowledge (NACK)

The ACK signaling takes place after each transmitted byte. The ACK bit allows the receiver to signal the transmitter that the byte was successfully received and another byte may be sent. All clock pulses, including the acknowledge 9<sup>th</sup> clock pulse, are generated by the controller.

The transmitter releases the SDA line during the acknowledge clock pulse so the receiver can pull the SDA line LOW and it remains stable LOW during the HIGH period of this 9<sup>th</sup> clock pulse.

A NACK is signaled when the SDA line remains HIGH during the 9<sup>th</sup> clock pulse. The controller can then generate either a STOP to abort the transfer or a repeated START to start a new transfer.

### 9.3.14.5 Target Address and Data Direction Bit

After the START signal, a target address is sent. This address is 7 bits long, followed by the 8 bit as a data direction bit (bit R/ $\overline{W}$ ). A zero indicates a transmission (WRITE) and a one indicates a request for data (READ). The BQ25798 7-bit address is defined as 1101 011' (0x6B). The address bit arrangement is shown below.



图 9-19. 7-Bit Addressing (0x6B)

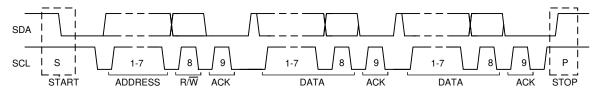


图 9-20. Complete Data Transfer on the I<sup>2</sup>C Bus

#### 9.3.14.6 Single Write and Read



图 9-21. Single Write

图 9-22. Single Read

If the register address is not defined, the charger IC sends back NACK and returns to the idle state.

#### 9.3.14.7 Multi-Write and Multi-Read

The charger device supports multi-byte read and multi-byte write of all registers. These multi-byte operations are allowed to cross register boundaries. For instance, the entire regiser map may be read in a single operation with a 49-byte read that starts at register address 0x0.

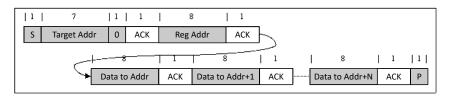


图 9-23. Multi-Write

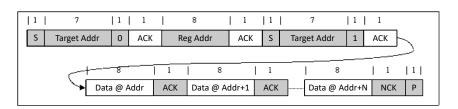


图 9-24. Multi-Read

### 9.4 Device Functional Modes

#### 9.4.1 Host Mode and Default Mode

The device is a host controlled charger, but it can operate in default mode without host management. In default mode, the device can be used as an autonomous charger with no host or while host is in sleep mode. When the charger is in default mode, WD\_STAT bit becomes HIGH, WD\_FLAG is set to 1, and an  $\overline{\text{INT}}$  is asserted low to alert the host (unless masked by WD\_MASK). The WD\_FLAG bit would read as 1 upon the first read and then 0 upon subsequent reads. When the charger is in host mode, WD\_STAT bit is LOW.

After power-on-reset, the device starts in default mode with watchdog timer expired. All the registers are in the default settings.

In default mode, the device keeps charging the battery with default 1-hour trickle charging safety timer, 2-hour pre-charging safety timer and the 12-hour fast charging safety timer. At the end of the 1-hour or 2-hour or 12-hour timer expired, the charging is stopped and the buck-boost converter continues to operate to supply system load.

A write to any  $I^2C$  register transitions the charger from default mode to host mode, and initiates the watchdog timer. All the device parameters can be programmed by the host. To keep the device in host mode, the host has to reset the watchdog timer by writing 1 to WD\_RST bit before the watchdog timer expires (WD\_STAT bit is set), or disable watchdog timer by setting WATCHDOG bits = 00.

When the watchdog timer is expired, the device returns to default mode and all registers are reset to default values except the ones described in † 9.5. The watchdog timer will be reset on any write if the watchdog timer



has expired. When watchdog timer expires, WD\_STAT and WD\_FLAG is set to 1, and an  $\overline{\text{INT}}$  is asserted low to alert the host (unless masked by WD\_MASK).

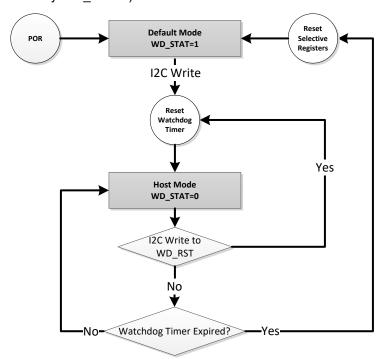


图 9-25. Watchdog Timer Flow Chart

#### 9.4.2 Register Bit Reset

Beside the register reset by the watchdog timer in the default mode, the register and the timer could be reset to the default value by writing the REG\_RST bit to 1. The register bits, which can be reset by the REG\_RST bit, are noted in the Register Map section. After the register reset, the REG\_RST bit will go back from 1 to 0 automatically.

The register reset by the REG\_RST bit will not initiate the ACFET-RBFET detection, which is only done at the charger first time POR. It will not repeat the open-circuit adapter measurements for the default VINDPM setting, which in only done when an adapter is plugged in. In addition, if the charger is in the process of forced ICO, the forced open-circuit adapter measurements or the forced D+/D- detection, set the REG\_RST to 1 will terminate all of these processes, because reset the register to default values will set FORCE\_ICO, FORCE\_INDET and FORCE\_VINDPM\_DET bits to 0.



# 9.5 Register Map

## 9.5.1 I2C Registers

 $\frac{1}{2}$  9-12 lists the I2C registers. All register offset addresses not listed in  $\frac{1}{2}$  9-12 should be considered as reserved locations and the register contents should not be modified.

表 9-12. I2C Registers

		₹ 9-12. IZC Registers	
Offset	Acronym	Register Name	Section
0h	REG00_Minimal_System_Voltage	Minimal System Voltage	节 9.5.1.2
1h	REG01_Charge_Voltage_Limit	Charge Voltage Limit	节 9.5.1.3
3h	REG03_Charge_Current_Limit	Charge Current Limit	节 9.5.1.4
5h	REG05_Input_Voltage_Limit	Input Voltage Limit	节 9.5.1.5
6h	REG06_Input_Current_Limit	Input Current Limit	节 9.5.1.6
8h	REG08_Precharge_Control	Precharge Control	节 9.5.1.7
9h	REG09_Termination_Control	Termination Control	节 9.5.1.8
Ah	REG0A_Re-charge_Control	Re-charge Control	节 9.5.1.9
Bh	REG0B_VOTG_regulation	VOTG regulation	节 9.5.1.10
Dh	REG0D_IOTG_regulation	IOTG regulation	节 9.5.1.11
Eh	REG0E_Timer_Control	Timer Control	节 9.5.1.12
Fh	REG0F_Charger_Control_0	Charger Control 0	节 9.5.1.13
10h	REG10_Charger_Control_1	Charger Control 1	节 9.5.1.14
11h	REG11_Charger_Control_2	Charger Control 2	节 9.5.1.15
12h	REG12_Charger_Control_3	Charger Control 3	节 9.5.1.16
13h	REG13_Charger_Control_4	Charger Control 4	节 9.5.1.17
14h	REG14_Charger_Control_5	Charger Control 5	节 9.5.1.18
15h	REG15_MPPT_Control	MPPT Control	节 9.5.1.19
16h	REG16_Temperature_Control	Temperature Control	节 9.5.1.20
17h	REG17_NTC_Control_0	NTC Control 0	节 9.5.1.21
18h	REG18_NTC_Control_1	NTC Control 1	节 9.5.1.22
19h	REG19_ICO_Current_Limit	ICO Current Limit	节 9.5.1.23
1Bh	REG1B_Charger_Status_0	Charger Status 0	节 9.5.1.24
1Ch	REG1C_Charger_Status_1	Charger Status 1	节 9.5.1.25
1Dh	REG1D_Charger_Status_2	Charger Status 2	节 9.5.1.26
1Eh	REG1E_Charger_Status_3	Charger Status 3	节 9.5.1.27
1Fh	REG1F_Charger_Status_4	Charger Status 4	节 9.5.1.28
20h	REG20_FAULT_Status_0	FAULT Status 0	节 9.5.1.29
21h	REG21_FAULT_Status_1	FAULT Status 1	节 9.5.1.30
22h	REG22_Charger_Flag_0	Charger Flag 0	节 9.5.1.31
23h	REG23_Charger_Flag_1	Charger Flag 1	节 9.5.1.32
24h	REG24_Charger_Flag_2	Charger Flag 2	节 9.5.1.33
25h	REG25_Charger_Flag_3	Charger Flag 3	节 9.5.1.34
26h	REG26_FAULT_Flag_0	FAULT Flag 0	节 9.5.1.35
27h	REG27_FAULT_Flag_1	FAULT Flag 1	节 9.5.1.36
28h	REG28_Charger_Mask_0	Charger Mask 0	节 9.5.1.37
29h	REG29_Charger_Mask_1	Charger Mask 1	节 9.5.1.38
2Ah	REG2A_Charger_Mask_2	Charger Mask 2	节 9.5.1.39



表 9-12. I2C Registers (continued)

Offset	Acronym	Register Name	Section
2Bh	REG2B_Charger_Mask_3	Charger Mask 3	节 9.5.1.40
2Ch	REG2C_FAULT_Mask_0	FAULT Mask 0	节 9.5.1.41
2Dh	REG2D_FAULT_Mask_1	FAULT Mask 1	节 9.5.1.42
2Eh	REG2E_ADC_Control	ADC Control	节 9.5.1.43
2Fh	REG2F_ADC_Function_Disable_0	ADC Function Disable 0	节 9.5.1.44
30h	REG30_ADC_Function_Disable_1	ADC Function Disable 1	节 9.5.1.45
31h	REG31_IBUS_ADC	IBUS ADC	节 9.5.1.46
33h	REG33_IBAT_ADC	IBAT ADC	节 9.5.1.47
35h	REG35_VBUS_ADC	VBUS ADC	节 9.5.1.48
37h	REG37_VAC1_ADC	VAC1 ADC	节 9.5.1.49
39h	REG39_VAC2_ADC	VAC2 ADC	节 9.5.1.50
3Bh	REG3B_VBAT_ADC	VBAT ADC	节 9.5.1.51
3Dh	REG3D_VSYS_ADC	VSYS ADC	节 9.5.1.52
3Fh	REG3F_TS_ADC	TS ADC	节 9.5.1.53
41h	REG41_TDIE_ADC	TDIE_ADC	节 9.5.1.54
43h	REG43_D+_ADC	D+ ADC	节 9.5.1.55
45h	REG45_DADC	D- ADC	节 9.5.1.56
47h	REG47_DPDM_Driver	DPDM Driver	节 9.5.1.57
48h	REG48_Part_Information	Part Information	节 9.5.1.58

Complex bit access types are encoded to fit into small table cells. The following table shows the codes that are used for access types in this section.

### 表 9-13. I2C Access Type Codes

Code	Description
R	Read
1	
W	Write
	The register bits are only valid in this defined range.
	Any write on the register lower than the minimal value of the valid range, will be ignored by the charger
	Any write on the register higher than the maximum value of the valid range, will be ignored by the charger
	R

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## 9.5.1.1 REG00\_Minimal\_System\_Voltage Register (Offset = 0h) [reset = X]

REG00\_Minimal\_System\_Voltage is shown in 图 9-26 and described in 表 9-14.

Return to the 表 9-12.

Minimal System Voltage

### 图 9-26. REG00\_Minimal\_System\_Voltage Register

7	6	5	4	3	2	1	0
RESE	RVED	VSYSMIN_5:0					
R/W	V-0h	R/W-X					

### 表 9-14. REG00\_Minimal\_System\_Voltage Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7-6	RESERVED	R/W	0h		RESERVED
5-0	VSYSMIN_5:0	R/W	X	Reset by: REG_RST	Minimal System Voltage: During POR, the device reads the resistance tie to PROG pin, to identify the default battery cell count and determine the default power on VSYSMIN list below: 1s: 3.5V 2s: 7V 3s: 9V 4s: 12V Type: RW Range: 2500mV-16000mV Fixed Offset: 2500mV Bit Step Size: 250mV Clamped High



## 9.5.1.2 REG01\_Charge\_Voltage\_Limit Register (Offset = 1h) [reset = X]

REG01\_Charge\_Voltage\_Limit is shown in 图 9-27 and described in 表 9-15.

Return to the 表 9-12.

Charge Voltage Limit

## 图 9-27. REG01\_Charge\_Voltage\_Limit Register

		• •			•			
15	14	13	12	11	10	9	8	
		RESERVED		VREG_10:0				
		R-0h		R/W-X				
7	6	5	4	3	2	1	0	
VREG_10:0								
R/W-X								

### 表 9-15. REG01\_Charge\_Voltage\_Limit Register Field Descriptions

	* 0 1011CE01_Undago_Limit regioter Field Decomptions								
Bit	Field	Туре	Reset	Notes	Description				
15-11	RESERVED	R	0h		RESERVED				
10-0	VREG_10:0	R/W	Х	Reset by: REG_RST	Battery Voltage Limit: During POR, the device reads the resistance tie to PROG pin, to identify the default battery cell count and determine the default power-on battery voltage regulation limit: 1s: 4.2V 2s: 8.4V 3s: 12.6V 4s: 16.8V Type: RW Range: 3000mV-18800mV Fixed Offset: 0mV Bit Step Size: 10mV Clamped Low				

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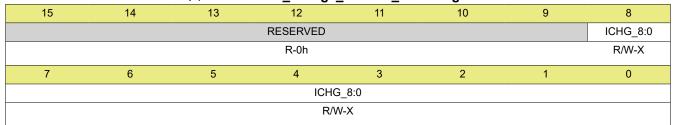
## 9.5.1.3 REG03\_Charge\_Current\_Limit Register (Offset = 3h) [reset = X]

REG03\_Charge\_Current\_Limit is shown in 图 9-28 and described in 表 9-16.

Return to the 表 9-12.

**Charge Current Limit** 

## 图 9-28. REG03\_Charge\_Current\_Limit Register



### 表 9-16. REG03\_Charge\_Current\_Limit Register Field Descriptions

	₹ 0 10.112.000_0110111_2111111 110910101 1 1010 D00011ption0								
Bit	Field	Туре	Reset	Notes	Description				
15-9	RESERVED	R	0h		RESERVED				
8-0	ICHG_8:0	R/W	X	Reset by: WATCHDOG REG_RST	Charge Current Limit During POR, the device reads the resistance tie to PROG pin, to identify the default battery cell count and determine the default power-on battery charging current: 1A Type: RW Range: 50mA-5000mA Fixed Offset: 0mA Bit Step Size: 10mA Clamped Low				



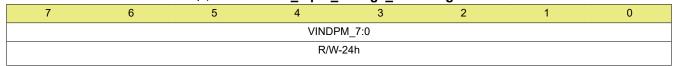
## 9.5.1.4 REG05\_Input\_Voltage\_Limit Register (Offset = 5h) [reset = 24h]

REG05\_Input\_Voltage\_Limit is shown in 图 9-29 and described in 表 9-17.

Return to the 表 9-12.

Input Voltage Limit

## 图 9-29. REG05\_Input\_Voltage\_Limit Register



### 表 9-17. REG05\_Input\_Voltage\_Limit Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	VINDPM_7:0	R/W	24h	Absolute VINDPM Threshold
				VINDPM register is reset to 3600mV upon adapter unplugged and it
				is set to the value based on the VBUS measurement when the
				adapter plugs in. It is not reset by the REG_RST and the
				WATCHDOG
				Type : RW
				POR: 3600mV (24h)
				Range : 3600mV-22000mV
				Fixed Offset : 0mV
				Bit Step Size : 100mV
				Clamped Low

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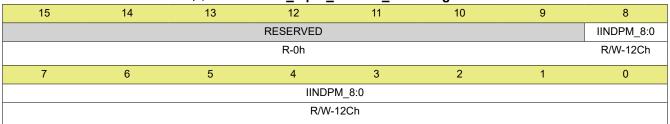
## 9.5.1.5 REG06\_Input\_Current\_Limit Register (Offset = 6h) [reset = 12Ch]

REG06\_Input\_Current\_Limit is shown in 图 9-30 and described in 表 9-18.

Return to the 表 9-12.

Input Current Limit

## 图 9-30. REG06\_Input\_Current\_Limit Register



## 表 9-18. REG06\_Input\_Current\_Limit Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
15-9	RESERVED	R	0h		RESERVED
8-0	IINDPM_8:0	R/W	12Ch	Reset by: REG_RST	Based on D+/D- detection results: USB SDP = 500mA USB CDP = 1.5A USB DCP = 3.25A Adjustable High Voltage DCP = 1.5A Unknown Adapter = 3A Non-Standard Adapter = 1A/2A/2.1A/2.4A Type: RW POR: 3000mA (12Ch) Range: 100mA-3300mA Fixed Offset: 0mA Bit Step Size: 10mA Clamped Low

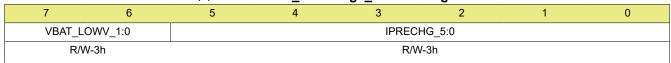
## 9.5.1.6 REG08\_Precharge\_Control Register (Offset = 8h) [reset = C3h]

REG08\_Precharge\_Control is shown in 图 9-31 and described in 表 9-19.

Return to the 表 9-12.

**Precharge Control** 

### 图 9-31. REG08\_Precharge\_Control Register



### 表 9-19. REG08\_Precharge\_Control Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7-6	VBAT_LOWV_1:0	R/W	3h	Reset by: REG_RST	Battery voltage thresholds for the transition from precharge to fast charge, which is defined as a ratio of battery regulation limit (VREG) Type: RW POR: 11b 0h = 15%*VREG 1h = 62.2%*VREG 2h = 66.7%*VREG 3h = 71.4%*VREG
5-0	IPRECHG_5:0	R/W	3h	Reset by: WATCHDOG REG_RST POR: 120mA (3h) Range : 40mA-2000mA Fixed Offset : 0mA Bit Step Size : 40mA Clamped Low	

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## 9.5.1.7 REG09\_Termination\_Control Register (Offset = 9h) [reset = 5h]

REG09\_Termination\_Control is shown in 图 9-32 and described in 表 9-20.

Return to the 表 9-12.

**Termination Control** 

### 图 9-32. REG09\_Termination\_Control Register

7	6	5	4	3	2	1	0	
RESERVED	REG_RST	RESERVED	ITERM_4:0					
R-0h	R/W-0h	R-0h	R/W-5h					

## 表 9-20. REG09\_Termination\_Control Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	RESERVED	R	0h		RESERVED
6	REG_RST	R/W	0h		Reset registers to default values and reset timer Type: RW POR: 0b 0h = Not reset 1h = Reset
5	STOP_WD_CHG	RW	0h		Defines whether a watchdog timer expiration will disable charging Type: RW POR: 0b0h = WD timer expiration keeps existing EN_CHG setting 1h = WD timer expiration sets EN_CHG=0
4-0	ITERM_4:0	R/W	5h	Reset by: WATCHDOG REG_RST	Termination current Type: RW POR: 200mA (5h) Range: 40mA-1000mA Fixed Offset: 0mA Bit Step Size: 40mA Clamped Low

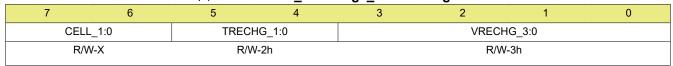
## 9.5.1.8 REG0A\_Re-charge\_Control Register (Offset = Ah) [reset = X]

REG0A\_Re-charge\_Control is shown in 图 9-33 and described in 表 9-21.

Return to the 表 9-12.

Re-charge Control

### 图 9-33. REG0A\_Re-charge\_Control Register



### 表 9-21. REG0A\_Re-charge\_Control Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7-6	CELL_1:0	R/W	X		At POR, the charger reads the PROG pin resistance to determine the battery cell count and update this CELL bits accordingly.  Type: RW  0h = 1s  1h = 2s  2h = 3s  3h = 4s
5-4	TRECHG_1:0	R/W	2h	Reset by: WATCHDOG REG_RST	Battery recharge deglich time Type: RW POR: 10b 0h = 64ms 1h = 256ms 2h = 1024ms (default) 3h = 2048ms
3-0	VRECHG_3:0	R/W	3h	Reset by: WATCHDOG REG_RST	Battery Recharge Threshold Offset (Below VREG) Type: RW POR: 200mV (3h) Range: 50mV-800mV Fixed Offset: 50mV Bit Step Size: 50mV

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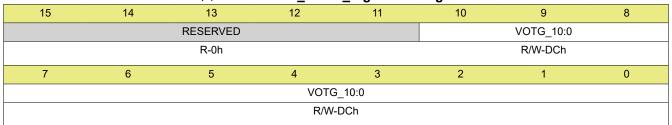
## 9.5.1.9 REG0B\_VOTG\_regulation Register (Offset = Bh) [reset = DCh]

REG0B\_VOTG\_regulation is shown in 图 9-34 and described in 表 9-22.

Return to the 表 9-12.

VOTG regulation

## 图 9-34. REG0B\_VOTG\_regulation Register



### 表 9-22. REG0B\_VOTG\_regulation Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
15-11	RESERVED	R	0h		RESERVED
10-0	VOTG_10:0			Type: RW POR: 5000mV (DCh) Range: 2800mV-22000mV Fixed Offset: 2800mV Bit Step Size: 10mV	

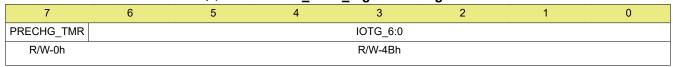
## 9.5.1.10 REG0D\_IOTG\_regulation Register (Offset = Dh) [reset = 4Bh]

REG0D\_IOTG\_regulation is shown in 图 9-35 and described in 表 9-23.

Return to the 表 9-12.

**IOTG** regulation

## 图 9-35. REG0D\_IOTG\_regulation Register



### 表 9-23. REG0D\_IOTG\_regulation Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	PRECHG_TMR	R/W	0h Reset by: WATCHDOG REG_RST Pre-charge safety timer setting Type: RW POR: 0b 0h = 2 hrs (default) 1h = 0.5 hrs		
6-0	IOTG_6:0	R/W	4Bh	Reset by: WATCHDOG REG_RST	OTG current limit Type: RW POR: 3040mA (4Bh) Range: 160mA-3360mA Fixed Offset: 0mA Bit Step Size: 40mA Clamped Low

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## 9.5.1.11 REG0E\_Timer\_Control Register (Offset = Eh) [reset = 3Dh]

REG0E\_Timer\_Control is shown in 图 9-36 and described in 表 9-24.

Return to the 表 9-12.

**Timer Control** 

# 图 9-36. REG0E\_Timer\_Control Register

7	6	5	4	3	2	1	0
TOPOFF_	TMR_1:0	EN_TRICHG_T MR	EN_PRECHG_ TMR	EN_CHG_TMR	CHG_TN	MR_1:0	TMR2X_EN
R/W	′-0h	R/W-1h	R/W-1h	R/W-1h	R/W	-2h	R/W-1h

## 表 9-24. REG0E\_Timer\_Control Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description		
7-6	TOPOFF_TMR_1:0	R/W	Oh	Reset by: WATCHDOG REG_RST	Top-off timer control Type: RW POR: 00b 0h = Disabled (default) 1h = 15 mins 2h = 30 mins 3h = 45 mins		
5	EN_TRICHG_TMR	R/W	1h	Reset by: WATCHDOG REG_RST	Enable trickle charge timer (fixed as 1hr) Type: RW POR: 1b 0h = Disabled 1h = Enabled (default)		
4	EN_PRECHG_TMR	R/W	1h	Reset by: WATCHDOG REG_RST	Enabled (default)  Enable pre-charge timer Type: RW POR: 1b 0h = Disabled 1h = Enabled (default)		
3	EN_CHG_TMR	R/W	1h	Reset by: WATCHDOG REG_RST	Enable fast charge timer Type : RW POR: 1b 0h = Disabled 1h = Enabled (default)		
2-1	CHG_TMR_1:0	R/W	2h	Reset by: WATCHDOG REG_RST	Fast charge timer setting Type: RW POR: 10b 0h = 5 hrs 1h = 8 hrs 2h = 12 hrs (default) 3h = 24 hrs		
0	TMR2X_EN	R/W	1h	Reset by: WATCHDOG REG_RST	TMR2X_EN Type: RW POR: 1b 0h = Trickle charge, pre-charge and fast charge timer NOT slowed by 2X during input DPM or thermal regulation. 1h = Trickle charge, pre-charge and fast charge timer slowed by 2X during input DPM or thermal regulation (default)		

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## 9.5.1.12 REG0F\_Charger\_Control\_0 Register (Offset = Fh) [reset = A2h]

REG0F\_Charger\_Control\_0 is shown in 图 9-37 and described in 表 9-25.

Return to the 表 9-12.

Charger Control 0

### 图 9-37. REG0F\_Charger\_Control\_0 Register

					•		
7	6	5	4	3	2	1	0
EN_AUTO_IBA TDIS	FORCE_IBATDI S	EN_CHG	EN_ICO	FORCE_ICO	EN_HIZ	EN_TERM	EN_BACKUP
R/W-1h	R/W-0h	R/W-1h	R/W-0h	R/W-0h	R/W-0h	R/W-1h	R-0h

## 表 9-25. REG0F\_Charger\_Control\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description		
7	EN_AUTO_IBATDIS	R/W	1h	Reset by: REG_RST	Enable the auto battery discharging during the battery OVP fault Type: RW POR: 1b 0h = The charger will NOT apply a discharging current on BAT during battery OVP		
					1h = The charger will apply a discharging current on BAT during battery OVP		
6	FORCE_IBATDIS	R/W	Oh	Reset by: REG_RST	Force a battery discharging current Type: RW POR: 0b 0h = IDLE (default) 1h = Force the charger to apply a discharging current on BAT regardless the battery OVP status		
5	EN_CHG	R/W	1h	Reset by: WATCHDOG REG_RST	Charger Enable Configuration Type: RW POR: 1b 0h = Charge Disable 1h = Charge Enable (default)		
4	EN_ICO	R/W	0h	Reset by: REG_RST	Input Current Optimizer (ICO) Enable Type: RW POR: 0b 0h = Disable ICO (default) 1h = Enable ICO		
3	FORCE_ICO	R/W	Oh	Reset by: WATCHDOG REG_RST	Force start input current optimizer (ICO) Note: This bit can only be set and returns 0 after ICO starts. This bit only valid when EN_ICO = 1 Type: RW POR: 0b 0h = Do NOT force ICO (Default) 1h = Force ICO start		
2	EN_HIZ	R/W	Oh	Reset by: REG_RST	Enable HIZ mode. This bit will be also reset to 0, when the adapter is plugged in at VBUS. Type: RW POR: 0b 0h = Disable (default) 1h = Enable		
1	EN_TERM	R/W	1h	Reset by: WATCHDOG REG_RST	Enable termination Type: RW POR: 1b 0h = Disable 1h = Enable (default)		

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# 表 9-25. REG0F\_Charger\_Control\_0 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Notes	Description		
0	EN_BACKUP	R/W	0h	Reset by: WATCHDOG REG_RST	Enables backup mode where OTG automatically engages when VBUS droops below voltage set in REG10. Type: RW POR: 0b 0h = Disable (default) 1h = Enable		

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## 9.5.1.13 REG10\_Charger\_Control\_1 Register (Offset = 10h) [reset = 85h]

REG10\_Charger\_Control\_1 is shown in 图 9-38 and described in 表 9-26.

Return to the 表 9-12.

**Charger Control 1** 

## 图 9-38. REG10\_Charger\_Control\_1 Register

7	6	5	4	3	2	1	0		
VBUS_BAG	CKUP_1:0	VAC_O	VP_1:0	WD_RST	WATCHDOG_2:0				
R/W	R/W-2h		/-3h	R/W-0h	R/W-5h				

## 表 9-26. REG10\_Charger\_Control\_1 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7-6	VBUS_BACKUP_1:0	R/W	2h	Reset by: REG_RST	The thresholds to trigger the backup mode, defined as a ratio of VINDPM Type: RW POR: 10b 0h = 40%*VINDPM 1h = 60%*VINDPM 2h = 80%*VINDPM (default) 3h = 100%*VINDPM
5-4	VAC_OVP_1:0	R/W	3h	Reset by: REG_RST	VAC_OVP thresholds Type: RW POR: 11b 0h = 26V 1h = 22V 2h = 12V 3h = 7V (default)
3	WD_RST	R/W	Oh	Reset by: WATCHDOG REG_RST	I2C watch dog timer reset Type: RW POR: 0b 0h = Normal (default) 1h = Reset (this bit goes back to 0 after timer resets)
2-0	WATCHDOG_2:0	R/W	5h	Reset by: REG_RST	Watchdog timer settings Type: RW POR: 101b 0h = Disable 1h = 0.5s 2h = 1s 3h = 2s 4h = 20s 5h = 40s (default) 6h = 80s 7h = 160s

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## 9.5.1.14 REG11\_Charger\_Control\_2 Register (Offset = 11h) [reset = 40h]

REG11\_Charger\_Control\_2 is shown in 图 9-39 and described in 表 9-27.

Return to the 表 9-12.

**Charger Control 2** 

## 图 9-39. REG11\_Charger\_Control\_2 Register

					•		
7	6	5	4	3	2	1	0
FORCE_INDET	AUTO_INDET_ EN	EN_12V	EN_9V	HVDCP_EN	SDRV_CTF	RL_1:0	SDRV_DLY
R/W-0h	R/W-1h	R/W-0h	R/W-0h	R/W-0h	R/W-0	h	R/W-0h

#### 表 9-27. REG11\_Charger\_Control\_2 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	FORCE_INDET	R/W	0h	Reset by: WATCHDOG REG_RST	Force D+/D- detection Type: RW POR: 0b 0h = Do NOT force D+/D- detection (default) 1h = Force D+/D- algorithm, when D+/D- detection is done, this bit will be reset to 0
6	AUTO_INDET_EN	R/W	1h	Reset by: WATCHDOG REG_RST	Automatic D+/D- Detection Enable Type: RW POR: 1b Oh = Disable D+/D- detection when VBUS is plugged- in 1h = Enable D+/D- detection when VBUS is plugged-in (default)
5	EN_12V	R/W	Oh	Reset by: REG_RST	EN_12V HVDC Type: RW POR: 0b 0h = Disable 12V mode in HVDCP (default) 1h = Enable 12V mode in HVDCP
4	EN_9V	R/W	Oh	Reset by: REG_RST	EN_9V HVDC Type: RW POR: 0b 0h = Disable 9V mode in HVDCP (default) 1h = Enable 9V mode in HVDCP
3	HVDCP_EN	R/W	Oh	Reset by: REG_RST	High voltage DCP enable. Type: RW POR: 0b 0h = Disable HVDCP handshake (default) 1h = Enable HVDCP handshake
2-1	SDRV_CTRL_1:0	R/W	Oh	Reset by: REG_RST	SFET control The external ship FET control logic to force the device enter different modes. Type: RW POR: 00b 0h = IDLE (default) 1h = Shutdown Mode 2h = Ship Mode 3h = System Power Reset

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## 表 9-27. REG11\_Charger\_Control\_2 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Notes	Description
0	SDRV_DLY	R/W	0h	Reset by: REG_RST	Delay time added to the taking action in bit [2:1] of the SFET control Type: RW POR: 0b 0h = Add 10s delay time (default) 1h = Do NOT add 10s delay time

## 9.5.1.15 REG12\_Charger\_Control\_3 Register (Offset = 12h) [reset = 0h]

REG12\_Charger\_Control\_3 is shown in 图 9-40 and described in 表 9-28.

Return to the 表 9-12.

**Charger Control 3** 

## 图 9-40. REG12\_Charger\_Control\_3 Register

					•		
7	6	5	4	3	2	1	0
DIS_ACDRV	EN_OTG	PFM_OTG_DIS	PFM_FWD_DIS	WKUP_DLY	DIS_LDO	DIS_OTG_OOA	DIS_FWD_OO A
R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h

## 表 9-28. REG12\_Charger\_Control\_3 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	DIS_ACDRV	R/W	0h		When this bit is set, the charger will force both EN_ACDRV1=0 and EN_ACDRV2=0 Type: RW POR: 0b
6	EN_OTG	R/W	Oh	Reset by: WATCHDOG REG_RST	OTG mode control Type: RW POR: 0b 0h = OTG Disable (default) 1h = OTG Enable
5	PFM_OTG_DIS	R/W	Oh	Reset by: WATCHDOG REG_RST	Disable PFM in OTG mode Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
4	PFM_FWD_DIS	R/W	Oh	Reset by: REG_RST	Disable PFM in forward mode Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
3	WKUP_DLY	R/W	Oh	Reset by: REG_RST	When wake up the device from ship mode, how much time ( $t_{SM\_EXIT}$ ) is required to pull low the $\overline{QON}$ pin. Type: RW POR: 0b 0h = 1s (Default) 1h = 15ms
2	DIS_LDO	R/W	0h	Reset by: WATCHDOG REG_RST	Disable BATFET LDO mode in pre-charge stage.  Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
1	DIS_OTG_OOA	R/W	Oh	Reset by: WATCHDOG REG_RST	Disable OOA in OTG mode Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
0	DIS_FWD_OOA	R/W	Oh	Reset by: REG_RST	Disable OOA in forward mode Type: RW POR: 0b 0h = Enable (Default) 1h = Disable

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## 9.5.1.16 REG13\_Charger\_Control\_4 Register (Offset = 13h) [reset = X]

REG13\_Charger\_Control\_4 is shown in 图 9-41 and described in 表 9-29.

Return to the 表 9-12.

**Charger Control 4** 

#### 图 9-41. REG13\_Charger\_Control\_4 Register

				, – –	•		
7	6	5	4	3	2	1	0
EN_ACDRV2	EN_ACDRV1	PWM_FREQ	DIS_STAT	DIS_VSYS_SH ORT	DIS_VOTG_UV P	FORCE_VINDP M_DET	EN_IBUS_OCP
R/W-0h	R/W-0h	R/W-X	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-1h

## 表 9-29. REG13\_Charger\_Control\_4 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	EN_ACDRV2	R/W	Oh		External ACFET2-RBFET2 gate driver control At POR, if the charger detects that there is no ACFET2-RBFET2 populated, this bit will be locked at 0 Type: RW POR: 0b 0h = turn off (default) 1h = turn on
6	EN_ACDRV1	R/W	Oh		External ACFET1-RBFET1 gate driver control At POR, if the charger detects that there is no ACFET1-RBFET1 populated, this bit will be locked at 0 Type: RW POR: 0b 0h = turn off (default) 1h = turn on
5	PWM_FREQ	R/W	X		Switching frequency selection, this bit POR default value is based on the PROG pin strapping.  Type: RW  0h = 1.5 MHz  1h = 750 kHz
4	DIS_STAT	R/W	Oh	Reset by: WATCHDOG REG_RST	Disable the STAT pin output Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
3	DIS_VSYS_SHORT	R/W	0h	Reset by: REG_RST	Disable forward mode VSYS short hiccup protection.  Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
2	DIS_VOTG_UVP	R/W	0h	Reset by: REG_RST	Disable OTG mode VOTG UVP hiccup protection. Type: RW POR: 0b 0h = Enable (Default) 1h = Disable



# 表 9-29. REG13\_Charger\_Control\_4 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Notes	Description
1	FORCE_VINDPM_D ET	R/W	Oh	Reset by: REG_RST	Force VINDPM detection Note: only when VBAT>VSYSMIN, this bit can be set to 1. Once the VINDPM auto detection is done, this bits returns to 0. Type: RW POR: 0b 0h = Do NOT force VINDPM detection (default) 1h = Force the converter stop switching, and ADC measures the VBUS voltage without input current, then the charger updates the VINDPM register accordingly.
0	EN_IBUS_OCP	R/W	1h	Reset by: REG_RST	Enable IBUS_OCP in forward mode Type : RW POR: 1b 0h = Disable 1h = Enable (default)



## 9.5.1.17 REG14\_Charger\_Control\_5 Register (Offset = 14h) [reset = 16h]

REG14\_Charger\_Control\_5 is shown in 图 9-42 and described in 表 9-30.

Return to the 表 9-12.

**Charger Control 5** 

#### 图 9-42. REG14\_Charger\_Control\_5 Register

				_	_ 0		
7	6	5	4	3	2	1	0
SFET_PRESEN T	RESERVED	EN_IBAT	IBAT_REG_1:0		EN_IINDPM	EN_EXTILIM	EN_BATOC
R/W-0h	R-0h	R/W-0h	R/V	V-2h	R/W-1h	R/W-1h	R/W-0h

## 表 9-30. REG14\_Charger\_Control\_5 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	SFET_PRESENT	R/W	Oh		The user has to set this bit based on whether a ship FET is populated or not. The POR default value is 0, which means the charger does not support all the features associated with the ship FET. The register bits list below all are locked at 0.  EN_BATOC=0 SDRV_CTRL=00 When this bit is set to 1, the register bits list above become programmable, and the charger can support the features associated with the ship FET Type: RW POR: 0b 0h = No ship FET populated 1h = Ship FET populated
6	RESERVED	R	0h		Reserved
5	EN_IBAT	R/W	Oh	Reset by: WATCHDOG REG_RST	IBAT discharge current sensing enable Type: RW POR: 0b 0h = Disable the IBAT discharge sensing at battery only or OTG condition (default) 1h = Enable the IBAT discharge sensing at battery only or OTG condition
4-3	IBAT_REG_1:0	R/W	2h	Reset by: WATCHDOG REG_RST	Battery discharging current regulation in OTG mode Type: RW POR: 10b 0h = 3A 1h = 4A 2h = 5A 3h = Disable (default)
2	EN_IINDPM	R/W	1h	Reset by: WATCHDOG REG_RST	Enable the internal IINDPM register input current regulation Type: RW POR: 1b 0h = Disable 1h = Enable (default)
1	EN_EXTILIM	R/W	1h	Reset by: REG_RST	Enable the external ILIM_HIZ pin input current regulation Type: RW POR: 1b 0h = Disable 1h = Enable (default)

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# 表 9-30. REG14\_Charger\_Control\_5 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Notes	Description
0	EN_BATOC	R/W	Oh	WATCHDOG REG_RST	Enable the battery discharging current OCP Type: RW POR: 0b 0h = Disable (default) 1h = Enable



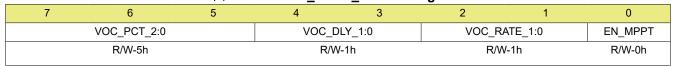
## 9.5.1.18 REG15\_MPPT\_Control Register (Offset = 15h) [reset = AAh]

REG15\_MPPT\_Control is shown in 图 9-43 and described in 表 9-31.

Return to the 表 9-12.

MPPT Control

## 图 9-43. REG15\_MPPT\_Control Register



#### 表 9-31. REG15\_MPPT\_Control Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7-5	VOC_PCT_2:0	R/W	5h	Reset by: REG_RST	To set the VINDPM as a percentage of the VBUS open circuit voltage when the VOC measurement is done. Type: RW POR: 101b 0h = 0.5625 1h = 0.625 2h = 0.6875 3h = 0.75 4h = 0.8125 5h = 0.875 (default) 6h = 0.9375 7h = 1
4-3	VOC_DLY_1:0	R/W	1h	Reset by: REG_RST	After the converter stops switching, the time delay before the VOC is measured.  Type: RW POR: 01b 0h = 50ms 1h = 300ms (default) 2h = 2s 3h = 5s
2-1	VOC_RATE_1:0	R/W	1h	Reset by: REG_RST	The time interval two VBUS open circuit voltage measurements.  Type: RW POR: 01b 0h = 30s 1h = 2mins (default) 2h = 10mins 3h = 30mins
0	EN_MPPT	R/W	0h	Reset by: REG_RST	Enable the MPPT to measure the VBUS open circuit voltage. Type: RW POR: 0b 0h = Disable (default) 1h = Enable

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## 9.5.1.19 REG16\_Temperature\_Control Register (Offset = 16h) [reset = C0h]

REG16\_Temperature\_Control is shown in 图 9-44 and described in 表 9-32.

Return to the 表 9-12.

**Temperature Control** 

#### 图 9-44. REG16\_Temperature\_Control Register

				_	•		
7	6	5	4	3	2	1	0
TREC	G_1:0	TSHUT_1:0		VBUS_PD_EN	VAC1_PD_EN	VAC2_PD_EN	BKUP_ACFET1 _ON
R/W	/-3h	R/W	'-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h

## 表 9-32. REG16\_Temperature\_Control Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7-6	TREG_1:0	R/W	3h	Reset by: WATCHDOG REG_RST	Thermal regulation thresholds.  Type: RW  POR: 11b  0h = 60°C  1h = 80°C  2h = 100°C  3h = 120°C (default)
5-4	TSHUT_1:0	R/W	Oh	Reset by: WATCHDOG REG_RST	Thermal shutdown thresholds.  Type: RW POR: 00b 0h = 150°C (default) 1h = 130°C 2h = 120°C 3h = 85°C
3	VBUS_PD_EN	R/W	0h	Reset by: REG_RST	Enable VBUS pull down resistor (6k Ohm) Type: RW POR: 0b 0h = Disable (default) 1h = Enable
2	VAC1_PD_EN	R/W	0h	Reset by: REG_RST	Enable VAC1 pull down resistor Type: RW POR: 0b 0h = Disable (default) 1h = Enable
1	VAC2_PD_EN	R/W	0h	Reset by: REG_RST	Enable VAC2 pull down resistor Type : RW POR: 0b 0h = Disable (default) 1h = Enable
0	BKUP_ACFET1_ON	R/W	Oh	Reset by: REG_RST	When the charger is operated in backup mode, ACFET1 is off. Setting this bit to 1, the charger clears the EN_BACKUP bit to 0, sets DIS_ACDRV=0 and EN_ACDRV1=1 to turn on the ACFET1. Type: RW POR: 0b 0h = IDLE (default) 1h = To turn on ACFET1 in backup mode

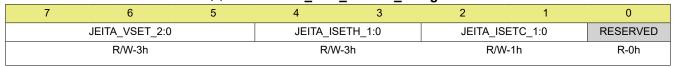
## 9.5.1.20 REG17\_NTC\_Control\_0 Register (Offset = 17h) [reset = 7Ah]

REG17\_NTC\_Control\_0 is shown in 图 9-45 and described in 表 9-33.

Return to the 表 9-12.

NTC Control 0

#### 图 9-45. REG17\_NTC\_Control\_0 Register



#### 表 9-33. REG17\_NTC\_Control\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7-5	JEITA_VSET_2:0	R/W	3h	Reset by: WATCHDOG REG_RST	JEITA high temperature range (TWARN - THOT) charge voltage setting Type: RW POR: 011b 0h = Charge Suspend 1h = Set VREG to VREG-800mV 2h = Set VREG to VREG-600mV 3h = Set VREG to VREG-400mV (default) 4h = Set VREG to VREG-300mV 5h = Set VREG to VREG-200mV 6h = Set VREG to VREG-100mV 7h = VREG unchanged
4-3	JEITA_ISETH_1:0	R/W	3h	Reset by: WATCHDOG REG_RST	JEITA high temperature range (TWARN - THOT) charge current setting Type: RW POR: 11b 0h = Charge Suspend 1h = Set ICHG to 20%* ICHG 2h = Set ICHG to 40%* ICHG 3h = ICHG unchanged (default)
2-1	JEITA_ISETC_1:0	R/W	1h	Reset by: WATCHDOG REG_RST	JEITA low temperature range (TCOLD - TCOOL) charge current setting Type: RW POR: 01b 0h = Charge Suspend 1h = Set ICHG to 20%* ICHG (default) 2h = Set ICHG to 40%* ICHG 3h = ICHG unchanged
0	RESERVED	R	0h		Reserved

Product Folder Links: BQ25798

## 9.5.1.21 REG18\_NTC\_Control\_1 Register (Offset = 18h) [reset = 54h]

REG18\_NTC\_Control\_1 is shown in 图 9-46 and described in 表 9-34.

Return to the 表 9-12.

NTC Control 1

## 图 9-46. REG18\_NTC\_Control\_1 Register

7	6	5	4	3	2	1	0
TS_CO	OL_1:0	TS_WARM_1:0		BHOT_1:0		BCOLD	TS_IGNORE
R/V	/-1h	R/W-1h		R/W	/-1h	R/W-0h	R/W-0h

#### 表 9-34. REG18\_NTC\_Control\_1 Register Field Descriptions

Bit	Field	Туре	Reset	Notes Registr	Description
7-6	TS_COOL_1:0	R/W	1h	Reset by: WATCHDOG REG_RST	JEITA VT2 comparator voltage rising thresholds as a percentage of REGN. The corresponding temperature in the brackets is achieved when a 103AT NTC thermistor is used, RT1= $5.24k\Omega$ and RT2= $30.31k\Omega$ . Type: RW POR: 01b 0h = 71.1% (5°C) 1h = $68.4\%$ (default) ( $10$ °C) 2h = $65.5\%$ ( $15$ °C) 3h = $62.4\%$ ( $20$ °C)
5-4	TS_WARM_1:0	R/W	1h	Reset by: WATCHDOG REG_RST	JEITA VT3 comparator voltage falling thresholds as a percentage of REGN. The corresponding temperature in the brackets is achieved when a 103AT NTC thermistor is used, RT1=5.24k $\Omega$ and RT2=30.31k $\Omega$ . Type: RW POR: 01b 0h = 48.4% (40°C) 1h = 44.8% (default) (45°C) 2h = 41.2% (50°C) 3h = 37.7% (55°C)
3-2	BHOT_1:0	R/W	1h	Reset by: WATCHDOG REG_RST	OTG mode TS HOT temperature threshold Type: RW POR: 01b 0h = 55°C 1h = 60°C (default) 2h = 65°C 3h = Disable
1	BCOLD	R/W	0h	Reset by: WATCHDOG REG_RST	OTG mode TS COLD temperature threshold Type: RW POR: 0b 0h = -10°C (default) 1h = -20°C
0	TS_IGNORE	R/W	Oh	Reset by: WATCHDOG REG_RST	Ignore the TS feedback, the charger considers the TS is always good to allow the charging and OTG modes, all the four TS status bits always stay at 0000 to report the normal condition.  Type: RW POR: 0b 0h = NOT ignore (Default) 1h = Ignore



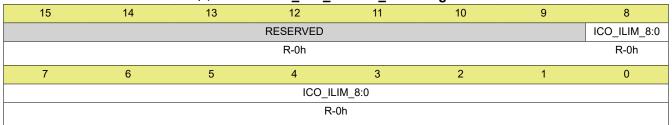
## 9.5.1.22 REG19\_ICO\_Current\_Limit Register (Offset = 19h) [reset = 0h]

REG19\_ICO\_Current\_Limit is shown in 图 9-47 and described in 表 9-35.

Return to the 表 9-12.

**ICO Current Limit** 

## 图 9-47. REG19\_ICO\_Current\_Limit Register



## 表 9-35. REG19\_ICO\_Current\_Limit Register Field Descriptions

Bit	Field	Type	Reset	Description
			1111	<u>'</u>
15-9	RESERVED	R	0h	RESERVED
8-0	ICO_ILIM_8:0	R	0h	Input Current Limit obtained from ICO or ILIM_HIZ pin setting
				Type: R
				POR: 0mA (0h)
				Range : 100mA-3300mA
				Fixed Offset : 0mA
				Bit Step Size : 10mA
				Clamped Low

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## 9.5.1.23 REG1B\_Charger\_Status\_0 Register (Offset = 1Bh) [reset = 0h]

REG1B\_Charger\_Status\_0 is shown in 图 9-48 and described in 表 9-36.

Return to the 表 9-12.

Charger Status 0

#### 图 9-48. REG1B\_Charger\_Status\_0 Register

			_ ,	-	•		
7	6	5	4	3	2	1	0
IINDPM_STAT	VINDPM_STAT	WD_STAT	RESERVED	PG_STAT	AC2_PRESENT _STAT	AC1_PRESENT _STAT	VBUS_PRESE NT_STAT
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

#### 表 9-36. REG1B\_Charger\_Status\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	IINDPM_STAT	R	Oh	IINDPM status (forward mode) or IOTG status (OTG mode) Type: R POR: 0b  0h = Normal  1h = In IINDPM regulation or IOTG regulation
6	VINDPM_STAT	R	Oh	VINDPM status (forward mode) or VOTG status (OTG mode) Type: R POR: 0b 0h = Normal 1h = In VINDPM regulation or VOTG regualtion
5	WD_STAT	R	0h	I2C watch dog timer status Type: R POR: 0b 0h = Normal 1h = WD timer expired
4	RESERVED	R	0h	RESERVED
3	PG_STAT	R	Oh	Power Good Status Type: R POR: 0b  0h = NOT in power good status  1h = Power good
2	AC2_PRESENT_STAT	R	Oh	VAC2 insert status Type: R POR: 0b 0h = VAC2 NOT present 1h = VAC2 present (above present threshold)
1	AC1_PRESENT_STAT	R	Oh	VAC1 insert status Type: R POR: 0b 0h = VAC1 NOT present 1h = VAC1 present (above present threshold)

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表 9-36. REG1B\_Charger\_Status\_0 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
0	VBUS_PRESENT_STAT	R	0h	VBUS present status
				Type : R
				POR: 0b
				0h = VBUS NOT present
				1h = VBUS present (above present threshold)

## 9.5.1.24 REG1C\_Charger\_Status\_1 Register (Offset = 1Ch) [reset = 0h]

REG1C\_Charger\_Status\_1 is shown in 图 9-49 and described in 表 9-37.

Return to the 表 9-12.

Charger Status 1

## 图 9-49. REG1C\_Charger\_Status\_1 Register



#### 表 9-37. REG1C\_Charger\_Status\_1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-5	CHG_STAT_2:0	R	0h	Charge Status bits Type : R
				POR: 000b
				0h = Not Charging
				1h = Trickle Charge
				2h = Pre-charge
				3h = Fast charge (CC mode)
				4h = Taper Charge (CV mode)
				5h = Reserved
				6h = Top-off Timer Active Charging
				7h = Charge Termination Done
4-1	VBUS_STAT_3:0	R	0h	VBUS status bits
				0h: No Input or BHOT or BCOLD in OTG mode
				1h: USB SDP (500mA)
				2h: USB CDP (1.5A)
				3h: USB DCP (3.25A)
				4h: Adjustable High Voltage DCP (HVDCP) (1.5A) 5h: Unknown adaptor (3A)
				6h: Non-Standard Adapter (1A/2A/2.1A/2.4A)
				7h: In OTG mode
				8h: Not qualified adaptor
				9h: Reserved
				Ah: Reserved
				Bh: Device directly powered from VBUS
				Ch: Backup Mode
				Dh: Reserved
				Eh: Reserved
				Fh: Reserved
				Type : R
				POR: 0h

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表 9-37. REG1C\_Charger\_Status\_1 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
0	BC1.2_DONE_STAT	R	0h	BC1.2 status bit
				Type : R
				POR: 0b
				0h = BC1.2 or non-standard detection NOT complete
				1h = BC1.2 or non-standard detection complete

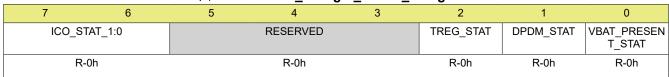
## 9.5.1.25 REG1D\_Charger\_Status\_2 Register (Offset = 1Dh) [reset = 0h]

REG1D\_Charger\_Status\_2 is shown in 图 9-50 and described in 表 9-38.

Return to the 表 9-12.

Charger Status 2

# 图 9-50. REG1D\_Charger\_Status\_2 Register



#### 表 9-38. REG1D\_Charger\_Status\_2 Register Field Descriptions

Bit	Field	Туре	Reset	Description Description
7-6	ICO_STAT_1:0	R	Oh	Input Current Optimizer (ICO) status Type: R POR: 00b  0h = ICO disabled 1h = ICO optimization in progress 2h = Maximum input current detected 3h = Reserved
5-3	RESERVED	R	0h	RESERVED
2	TREG_STAT	R	Oh	IC thermal regulation status Type : R POR: 0b 0h = Normal 1h = Device in thermal regulation
1	DPDM_STAT	R	Oh	D+/D- detection status bits Type: R POR: 0b 0h = The D+/D- detection is NOT started yet, or the detection is done 1h = The D+/D- detection is ongoing
0	VBAT_PRESENT_STAT	R	Oh	Battery present status (V <sub>BAT</sub> > V <sub>BAT_UVLOZ</sub> ) Type : R POR: 0b 0h = V <sub>BAT</sub> NOT present 1h = V <sub>BAT</sub> present

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## 9.5.1.26 REG1E\_Charger\_Status\_3 Register (Offset = 1Eh) [reset = 0h]

REG1E\_Charger\_Status\_3 is shown in 图 9-51 and described in 表 9-39.

Return to the 表 9-12.

Charger Status 3

## 图 9-51. REG1E\_Charger\_Status\_3 Register

7	6	5	4	3	2	1	0
ACRB2_STAT	ACRB1_STAT	ADC_DONE_S TAT	VSYS_STAT	CHG_TMR_ST AT	TRICHG_TMR_ STAT	PRECHG_TMR _STAT	RESERVED
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

## 表 9-39. REG1E\_Charger\_Status\_3 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	ACRB2_STAT	R	0h	The ACFET2-RBFET2 status  Type: R  POR: 0b  0h = ACFET2-RBFET2 is NOT placed  1h = ACFET2-RBFET2 is placed
6	ACRB1_STAT	R	Oh	The ACFET1-RBFET1 status Type : R POR: 0b  0h = ACFET1-RBFET1 is NOT placed  1h = ACFET1-RBFET1 is placed
5	ADC_DONE_STAT	R	Oh	ADC Conversion Status (in one-shot mode only) Type: R POR: 0b 0h = Conversion NOT complete 1h = Conversion complete
4	VSYS_STAT	R	0h	VSYS Regulation Status (forward mode)  Type: R  POR: 0b  0h = Not in VSYSMIN regulation (V <sub>BAT</sub> > V <sub>SYSMIN</sub> )  1h = In VSYSMIN regulation (V <sub>BAT</sub> < V <sub>SYSMIN</sub> )
3	CHG_TMR_STAT	R	0h	Fast charge timer status Type : R POR: 0b 0h = Normal 1h = Safety timer expired
2	TRICHG_TMR_STAT	R	0h	Trickle charge timer status Type : R POR: 0b 0h = Normal 1h = Safety timer expired

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# 表 9-39. REG1E\_Charger\_Status\_3 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description	
1	PRECHG_TMR_STAT	R	0h	The dialog afficiency	
				Type: R	
				POR: 0b	
				0h = Normal	
				1h = Safety timer expired	
0	RESERVED	R	0h	RESERVED	



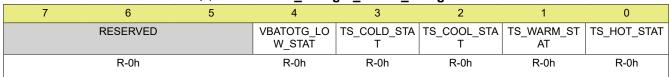
## 9.5.1.27 REG1F\_Charger\_Status\_4 Register (Offset = 1Fh) [reset = 0h]

REG1F\_Charger\_Status\_4 is shown in 图 9-52 and described in 表 9-40.

Return to the 表 9-12.

Charger Status 4

## 图 9-52. REG1F\_Charger\_Status\_4 Register



#### 表 9-40. REG1F\_Charger\_Status\_4 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-5	RESERVED	R	0h	RESERVED
4	VBATOTG_LOW_STAT	R	Oh	The battery voltage is too low to enable OTG mode.  Type: R  POR: 0b  0h = The battery voltage is high enough to enable the OTG operation  1h = The battery volage is too low to enable the OTG operation
3	TS_COLD_STAT	R	Oh	The TS temperature is in the cold range, lower than T1.  Type: R  POR: 0b  0h = TS status is NOT in cold range  1h = TS status is in cold range
2	TS_COOL_STAT	R	Oh	The TS temperature is in the cool range, between T1 and T2.  Type: R  POR: 0b  0h = TS status is NOT in cool range  1h = TS status is in cool range
1	TS_WARM_STAT	R	Oh	The TS temperature is in the warm range, between T3 and T5.  Type: R POR: 0b  0h = TS status is NOT in warm range  1h = TS status is in warm range
0	TS_HOT_STAT	R	Oh	The TS temperature is in the hot range, higher than T5.  Type: R  POR: 0b  0h = TS status is NOT in hot range  1h = TS status is in hot range

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## 9.5.1.28 REG20\_FAULT\_Status\_0 Register (Offset = 20h) [reset = 0h]

REG20\_FAULT\_Status\_0 is shown in 图 9-53 and described in 表 9-41.

Return to the 表 9-12.

**FAULT Status 0** 

#### 图 9-53. REG20\_FAULT\_Status\_0 Register

7	6	5	4	3	2	1	0
IBAT_REG_ST AT	VBUS_OVP_ST AT	VBAT_OVP_ST AT	IBUS_OCP_ST AT	IBAT_OCP_ST AT	CONV_OCP_S TAT	VAC2_OVP_ST AT	VAC1_OVP_ST AT
R-0h							

#### 表 9-41. REG20\_FAULT\_Status\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	IBAT_REG_STAT	R	Oh	IBAT regulation status Type: R POR: 0b 0h = Normal 1h = Device in battery discharging current regulation
6	VBUS_OVP_STAT	R	Oh	VBUS over-voltage status Type: R POR: 0b 0h = Normal 1h = Device in over voltage protection
5	VBAT_OVP_STAT	R	Oh	VBAT over-voltage status Type: R POR: 0b 0h = Normal 1h = Device in over voltage protection
4	IBUS_OCP_STAT	R	Oh	IBUS over-current status Type: R POR: 0b 0h = Normal 1h = Device in over current protection
3	IBAT_OCP_STAT	R	Oh	IBAT over-current status Type: R POR: 0b 0h = Normal 1h = Device in over current protection
2	CONV_OCP_STAT	R	Oh	Converter over current status Type: R POR: 0b 0h = Normal 1h = Converter in over current protection

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表 9-41. REG20\_FAULT\_Status\_0 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
1	VAC2_OVP_STAT	R	0h	VAC2 over-voltage status
				Type : R
				POR: 0b
				0h = Normal
				1h = Device in over voltage protection
0	VAC1_OVP_STAT	R	0h	VAC1 over-voltage status
				Type : R
				POR: 0b
				0h = Normal
				1h = Device in over voltage protection

## 9.5.1.29 REG21\_FAULT\_Status\_1 Register (Offset = 21h) [reset = 0h]

REG21\_FAULT\_Status\_1 is shown in 图 9-54 and described in 表 9-42.

Return to the 表 9-12.

**FAULT Status 1** 

#### 图 9-54. REG21\_FAULT\_Status\_1 Register

			_		•		
7	6	5	4	3	2	1 0	
VSYS_SHORT _STAT	VSYS_OVP_ST AT	OTG_OVP_ST AT	OTG_UVP_STA T	RESERVED	TSHUT_STAT	RESERVED	
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	

## 表 9-42. REG21\_FAULT\_Status\_1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	VSYS_SHORT_STAT	R	Oh	VSYS short circuit status Type: R POR: 0b 0h = Normal 1h = Device in SYS short circuit protection
6	VSYS_OVP_STAT	R	0h	VSYS over-voltage status Type: R POR: 0b 0h = Normal 1h = Device in SYS over-voltage protection
5	OTG_OVP_STAT	R	Oh	OTG over voltage status Type: R POR: 0b 0h = Normal 1h = Device in OTG over-voltage
4	OTG_UVP_STAT	R	0h	OTG under voltage status.  Type: R  POR: 0b  0h = Normal  1h = Device in OTG under voltage
3	RESERVED	R	0h	RESERVED
2	TSHUT_STAT	R	Oh	IC temperature shutdown status Type: R POR: 0b 0h = Normal 1h = Device in thermal shutdown protection
1-0	RESERVED	R	0h	RESERVED

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## 9.5.1.30 REG22\_Charger\_Flag\_0 Register (Offset = 22h) [reset = 0h]

REG22\_Charger\_Flag\_0 is shown in 图 9-55 and described in 表 9-43.

Return to the 表 9-12.

Charger Flag 0

#### 图 9-55. REG22\_Charger\_Flag\_0 Register

			_	<b>U</b> - <b>U</b> -	•		
7	6	5	4	3	2	1	0
IINDPM_FLAG	VINDPM_FLAG	WD_FLAG	POORSRC_FL AG	PG_FLAG	AC2_PRESENT _FLAG	AC1_PRESENT _FLAG	VBUS_PRESE NT_FLAG
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

表 9-43. REG22\_Charger\_Flag\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Description	
7	IINDPM_FLAG	R	Oh	IINDPM / IOTG flag Type: R POR: 0b 0h = Normal 1h = IINDPM / IOTG signal rising edge detected	
6	VINDPM_FLAG	R	Oh	VINDPM / VOTG Flag Type: R POR: 0b 0h = Normal 1h = VINDPM / VOTG regulation signal rising edge detected	
5	WD_FLAG	R	0h	I2C watchdog timer flag Type: R POR: 0b 0h = Normal 1h = WD timer signal rising edge detected	
4	POORSRC_FLAG	R	Oh	Poor source detection flag Type: R POR: 0b 0h = Normal 1h = Poor source status rising edge detected	
3	PG_FLAG	R	Oh	Power good flag Type: R POR: 0b 0h = Normal 1h = Any change in PG_STAT even (adapter good qualification or adapter good going away)	
2	AC2_PRESENT_FLAG	R	0h	VAC2 present flag Type: R POR: 0b 0h = Normal 1h = VAC2 present status changed	

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表 9-43. REG22\_Charger\_Flag\_0 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
1	AC1_PRESENT_FLAG	R	0h	VAC1 present flag
				Type : R
				POR: 0b
				0h = Normal
				1h = VAC1 present status changed
0	VBUS_PRESENT_FLAG	R	0h	VBUS present flag
				Type : R
				POR: 0b
				0h = Normal
				1h = VBUS present status changed



## 9.5.1.31 REG23\_Charger\_Flag\_1 Register (Offset = 23h) [reset = 0h]

REG23\_Charger\_Flag\_1 is shown in 图 9-56 and described in 表 9-44.

Return to the 表 9-12.

Charger Flag 1

#### 图 9-56. REG23\_Charger\_Flag\_1 Register

		• •	_	<b>U</b> - <b>U</b> -	•		
7	6	5	4	3	2	1	0
CHG_FLAG	ICO_FLAG	RESERVED	VBUS_FLAG	RESERVED	TREG_FLAG	VBAT_PRESEN T_FLAG	BC1.2_DONE_ FLAG
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

表 9-44. REG23\_Charger\_Flag\_1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	CHG_FLAG	R	Oh	Charge status flag Type: R POR: 0b 0h = Normal 1h = Charge status changed
6	ICO_FLAG	R	Oh	ICO status flag Type: R POR: 0b 0h = Normal 1h = ICO status changed
5	RESERVED	R	0h	RESERVED
4	VBUS_FLAG	R	Oh	VBUS status flag Type: R POR: 0b 0h = Normal 1h = VBUS status changed
3	RESERVED	R	0h	RESERVED
2	TREG_FLAG	R	Oh	IC thermal regulation flag Type: R POR: 0b 0h = Normal 1h = TREG signal rising threshold detected
1	VBAT_PRESENT_FLAG	R	0h	VBAT present flag Type: R POR: 0b 0h = Normal 1h = VBAT present status changed

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## 表 9-44. REG23\_Charger\_Flag\_1 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
0	BC1.2_DONE_FLAG	R	0h	BC1.2 status Flag
				Type : R
				POR: 0b
				0h = Normal
				1h = BC1.2 detection status changed



## 9.5.1.32 REG24\_Charger\_Flag\_2 Register (Offset = 24h) [reset = 0h]

REG24\_Charger\_Flag\_2 is shown in 图 9-57 and described in 表 9-45.

Return to the 表 9-12.

Charger Flag 2

#### 图 9-57. REG24\_Charger\_Flag\_2 Register

		• •	_	<b>-</b> -	•		
7	6	5	4	3	2	1	0
RESERVED	DPDM_DONE_ FLAG	ADC_DONE_F LAG	VSYS_FLAG	CHG_TMR_FL AG	TRICHG_TMR_ FLAG	PRECHG_TMR _FLAG	TOPOFF_TMR _FLAG
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

表 9-45. REG24\_Charger\_Flag\_2 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	RESERVED	R	0h	RESERVED
6	DPDM_DONE_FLAG	R	Oh	D+/D- detection is done flag.  Type: R  POR: 0b  0h = D+/D- detection is NOT started or still ongoing  1h = D+/D- detection is completed
5	ADC_DONE_FLAG	R	Oh	ADC conversion flag (only in one-shot mode) Type: R POR: 0b 0h = Conversion NOT completed 1h = Conversion completed
4	VSYS_FLAG	R	Oh	VSYSMIN regulation flag Type: R POR: 0b 0h = Normal 1h = Entered or existed VSYSMIN regulation
3	CHG_TMR_FLAG	R	Oh	Fast charge timer flag Type: R POR: 0b 0h = Normal 1h = Fast charge timer expired rising edge detected
2	TRICHG_TMR_FLAG	R	Oh	Trickle charge timer flag Type: R POR: 0b 0h = Normal 1h = Trickle charger timer expired rising edge detected
1	PRECHG_TMR_FLAG	R	0h	Pre-charge timer flag Type: R POR: 0b 0h = Normal 1h = Pre-charge timer expired rising edge detected

表 9-45. REG24\_Charger\_Flag\_2 Register Field Descriptions (continued)

	2 4 40. RESEAL CHARGOLIN REGISTER FISHER DOCUMENTS (CONTINUES)							
Bit	Field	Туре	Reset	Description				
0	TOPOFF_TMR_FLAG	R	0h	Top off timer flag				
				Type : R				
				POR: 0b				
				0h = Normal				
				1h = Top off timer expired rising edge detected				



## 9.5.1.33 REG25\_Charger\_Flag\_3 Register (Offset = 25h) [reset = 0h]

REG25\_Charger\_Flag\_3 is shown in 图 9-58 and described in 表 9-46.

Return to the 表 9-12.

Charger Flag 3

#### 图 9-58. REG25\_Charger\_Flag\_3 Register



表 9-46. REG25\_Charger\_Flag\_3 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-5	RESERVED	R	0h	RESERVED
4	VBATOTG_LOW_FLAG	R	0h	VBAT too low to enable OTG flag Type: R POR: 0b 0h = Normal 1h = VBAT falls below the threshold to enable the OTG mode
3	TS_COLD_FLAG	R	0h	TS cold temperature flag Type: R POR: 0b 0h = Normal 1h = TS across cold temperature (T1) is detected
2	TS_COOL_FLAG	R	0h	TS cool temperature flag Type: R POR: 0b 0h = Normal 1h = TS across cool temperature (T2) is detected
1	TS_WARM_FLAG	R	0h	TS warm temperature flag Type: R POR: 0b 0h = Normal 1h = TS across warm temperature (T3) is detected
0	TS_HOT_FLAG	R	0h	TS hot temperature flag Type: R POR: 0b 0h = Normal 1h = TS across hot temperature (T5) is detected

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## 9.5.1.34 REG26\_FAULT\_Flag\_0 Register (Offset = 26h) [reset = 0h]

REG26\_FAULT\_Flag\_0 is shown in 图 9-59 and described in 表 9-47.

Return to the 表 9-12.

FAULT Flag 0

#### 图 9-59. REG26\_FAULT\_Flag\_0 Register

			_		•		
7	6	5	4	3	2	1	0
IBAT_REG_FL AG	VBUS_OVP_FL AG	VBAT_OVP_FL AG	IBUS_OCP_FL AG	IBAT_OCP_FL AG	CONV_OCP_F LAG	VAC2_OVP_FL AG	VAC1_OVP_FL AG
R-0h							

#### 表 9-47. REG26\_FAULT\_Flag\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	IBAT_REG_FLAG	R	Oh	IBAT regulation flag Type : R POR: 0b Oh = Normal Th = Enter or exit IBAT regulation
6	VBUS_OVP_FLAG	R	Oh	VBUS over-voltage flag Type : R POR: 0b 0h = Normal 1h = Enter VBUS OVP
5	VBAT_OVP_FLAG	R	Oh	VBAT over-voltage flag Type : R POR: 0b 0h = Normal 1h = Enter VBAT OVP
4	IBUS_OCP_FLAG	R	0h	IBUS over-current flag Type : R POR: 0b 0h = Normal 1h = Enter IBUS OCP
3	IBAT_OCP_FLAG	R	0h	IBAT over-current flag Type : R POR: 0b 0h = Normal 1h = Enter discharged OCP
2	CONV_OCP_FLAG	R	0h	Converter over-current flag Type: R POR: 0b 0h = Normal 1h = Enter converter OCP

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表 9-47. REG26\_FAULT\_Flag\_0 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Description
1	VAC2_OVP_FLAG	R	0h	VAC2 over-voltage flag
				Type : R
				POR: 0b
				0h = Normal
				1h = Enter VAC2 OVP
0	VAC1_OVP_FLAG	R	0h	VAC1 over-voltage flag
				Type : R
				POR: 0b
				0h = Normal
				1h = Enter VAC1 OVP

## 9.5.1.35 REG27\_FAULT\_Flag\_1 Register (Offset = 27h) [reset = 0h]

REG27\_FAULT\_Flag\_1 is shown in 图 9-60 and described in 表 9-48.

Return to the 表 9-12.

FAULT Flag 1

#### 图 9-60. REG27\_FAULT\_Flag\_1 Register

7	6	5	4	3	2	1 0	
VSYS_SHORT _FLAG	VSYS_OVP_FL AG	OTG_OVP_FLA G	OTG_UVP_FLA G	RESERVED	TSHUT_FLAG	RESERVED	
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	

#### 表 9-48. REG27\_FAULT\_Flag\_1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7	VSYS_SHORT_FLAG	R	Oh	VSYS short circuit flag Type: R POR: 0b 0h = Normal 1h = Stop switching due to system short
6	VSYS_OVP_FLAG	R	Oh	VSYS over-voltage flag Type : R POR: 0b 0h = Normal 1h = Stop switching due to system over-voltage
5	OTG_OVP_FLAG	R	Oh	OTG over-voltage flag Type: R POR: 0b 0h = Normal 1h = Stop OTG due to VBUS over voltage
4	OTG_UVP_FLAG	R	Oh	OTG under-voltage flag Type: R POR: 0b 0h = Normal 1h = Stop OTG due to VBUS under-voltage
3	RESERVED	R	0h	RESERVED
2	TSHUT_FLAG	R	Oh	IC thermal shutdown flag Type: R POR: 0b 0h = Normal 1h = TS shutdown signal rising threshold detected
1-0	RESERVED	R	0h	RESERVED

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## 9.5.1.36 REG28\_Charger\_Mask\_0 Register (Offset = 28h) [reset = 0h]

REG28\_Charger\_Mask\_0 is shown in 图 9-61 and described in 表 9-49.

Return to the 表 9-12.

Charger Mask 0

## 图 9-61. REG28\_Charger\_Mask\_0 Register

				-	•		
7	6	5	4	3	2	1	0
IINDPM_MASK	VINDPM_MAS K	WD_MASK	POORSRC_MA SK	PG_MASK	AC2_PRESENT _MASK	AC1_PRESENT _MASK	VBUS_PRESE NT_MASK
R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h

## 表 9-49. REG28\_Charger\_Mask\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	IINDPM_MASK	R/W	Oh	Reset by: REG_RST	IINDPM / IOTG mask flag Type: RW POR: 0b 0h = Enter IINDPM / IOTG does produce INT pulse 1h = Enter IINDPM / IOTG does NOT produce INT pulse
6	VINDPM_MASK	R/W	0h	Reset by: REG_RST	VINDPM / VOTG mask flag Type: RW POR: 0b 0h = Enter VINDPM / VOTG does produce INT pulse 1h = Enter VINDPM / VOTG does NOT produce INT pulse
5	WD_MASK	R/W	0h	Reset by: REG_RST	I2C watch dog timer mask flag Type: RW POR: 0b 0h = I2C watch dog timer expired does produce INT pulse 1h = I2C watch dog timer expired does NOT produce INT pulse
4	POORSRC_MASK	R/W	Oh	Reset by: REG_RST	Poor source detection mask flag Type: RW POR: 0b 0h = Poor source detected does produce INT 1h = Poor source detected does NOT produce INT
3	PG_MASK	R/W	Oh	Reset by: REG_RST	Power Good mask flag Type: RW POR: 0b 0h = PG toggle does produce INT 1h = PG toggle does NOT produce INT
2	AC2_PRESENT_MA SK	R/W	0h	Reset by: REG_RST	VAC2 present mask flag Type: RW POR: 0b 0h = VAC2 present status change does produce INT 1h = VAC2 present status change does NOT produce INT
1	AC1_PRESENT_MA SK	R/W	0h	Reset by: REG_RST	VAC1 present mask flag Type: RW POR: 0b 0h = VAC1 present status change does produce INT 1h = VAC1 present status change does NOT produce INT

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## 表 9-49. REG28\_Charger\_Mask\_0 Register Field Descriptions (continued)

Bit	Field	Туре	Reset	Notes	Description
0	VBUS_PRESENT_M ASK	R/W	0h	Reset by: REG_RST	VBUS present mask flag Type: RW POR: 0b 0h = VBUS present status change does produce INT 1h = VBUS present status change does NOT produce INT



## 9.5.1.37 REG29\_Charger\_Mask\_1 Register (Offset = 29h) [reset = 0h]

REG29\_Charger\_Mask\_1 is shown in 图 9-62 and described in 表 9-50.

Return to the 表 9-12.

Charger Mask 1

#### 图 9-62. REG29\_Charger\_Mask\_1 Register

7	6	5	4	3	2	1	0
CHG_MASK	ICO_MASK	RESERVED	VBUS_MASK	RESERVED	TREG_MASK	VBAT_PRESEN T_MASK	BC1.2_DONE_ MASK
R/W-0h	R/W-0h	R-0h	R/W-0h	R-0h	R/W-0h	R/W-0h	R/W-0h

#### 表 9-50. REG29\_Charger\_Mask\_1 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	CHG_MASK	R/W	0h	Reset by: REG_RST	Charge status mask flag Type: RW POR: 0b 0h = Charging status change does produce INT 1h = Charging status change does NOT produce INT
6	ICO_MASK	R/W	Oh	Reset by: REG_RST	ICO status mask flag Type : RW POR: 0b 0h = ICO status change does produce INT 1h = ICO status change does NOT produce INT
5	RESERVED	R	0h		RESERVED
4	VBUS_MASK	R/W	Oh	Reset by: REG_RST	VBUS status mask flag Type : RW POR: 0b 0h = VBUS status change does produce INT 1h = VBUS status change does NOT produce INT
3	RESERVED	R	0h		RESERVED
2	TREG_MASK	R/W	Oh	Reset by: REG_RST	IC thermal regulation mask flag Type: RW POR: 0b 0h = entering TREG does produce INT 1h = entering TREG does NOT produce INT
1	VBAT_PRESENT_M ASK	R/W	Oh	Reset by: REG_RST	VBAT present mask flag Type: RW POR: 0b 0h = VBAT present status change does produce INT 1h = VBAT present status change does NOT produce INT
0	BC1.2_DONE_MAS	R/W	Oh	Reset by: REG_RST	BC1.2 status mask flag Type: RW POR: 0b 0h = BC1.2 status change does produce INT 1h = BC1.2 status change does NOT produce INT

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# 9.5.1.38 REG2A\_Charger\_Mask\_2 Register (Offset = 2Ah) [reset = 0h]

REG2A\_Charger\_Mask\_2 is shown in 图 9-63 and described in 表 9-51.

Return to the 表 9-12.

Charger Mask 2

# 图 9-63. REG2A\_Charger\_Mask\_2 Register

			_	·	•		
7	6	5	4	3	2	1	0
RESERVED	DPDM_DONE_ MASK	ADC_DONE_M ASK	VSYS_MASK	CHG_TMR_MA SK	TRICHG_TMR_ MASK	PRECHG_TMR _MASK	TOPOFF_TMR _MASK
R-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h

#### 表 9-51. REG2A\_Charger\_Mask\_2 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	RESERVED	R	0h		RESERVED
6	DPDM_DONE_MAS	R/W	Oh	Reset by: REG_RST	D+/D- detection is done mask flag Type: RW POR: 0b 0h = D+/D- detection done does produce INT pulse 1h = D+/D- detection done does NOT produce INT pulse
5	ADC_DONE_MASK	R/W	0h	Reset by: REG_RST	ADC conversion mask flag (only in one-shot mode) Type: RW POR: 0b 0h = ADC conversion done does produce INT pulse 1h = ADC conversion done does NOT produce INT pulse
4	VSYS_MASK	R/W	Oh	Reset by: REG_RST	VSYS min regulation mask flag Type: RW POR: 0b 0h = enter or exit VSYSMIN regulation does produce INT pulse 1h = enter or exit VSYSMIN regulation does NOT produce INT pulse
3	CHG_TMR_MASK	R/W	0h	Reset by: REG_RST	Fast charge timer mask flag Type: RW POR: 0b 0h = Fast charge timer expire does produce INT 1h = Fast charge timer expire does NOT produce INT
2	TRICHG_TMR_MAS	R/W	0h	Reset by: REG_RST	Trickle charge timer mask flag Type: RW POR: 0b 0h = Trickle charge timer expire does produce INT 1h = Trickle charge timer expire does NOT produce INT
1	PRECHG_TMR_MA SK	R/W	0h	Reset by: REG_RST	Pre-charge timer mask flag Type: RW POR: 0b 0h = Pre-charge timer expire does produce INT 1h = Pre-charge timer expire does NOT produce INT
0	TOPOFF_TMR_MA SK	R/W	0h	Reset by: REG_RST	Top off timer mask flag Type: RW POR: 0b 0h = Top off timer expire does produce INT 1h = Top off timer expire does NOT produce INT

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# 9.5.1.39 REG2B\_Charger\_Mask\_3 Register (Offset = 2Bh) [reset = 0h]

REG2B\_Charger\_Mask\_3 is shown in 图 9-64 and described in 表 9-52.

Return to the 表 9-12.

Charger Mask 3

# 图 9-64. REG2B\_Charger\_Mask\_3 Register

7	6	5	4	3	2	1	0
	RESERVED		VBATOTG_LO W_MASK	TS_COLD_MA SK	TS_COOL_MA SK	TS_WARM_MA SK	TS_HOT_MAS K
	R-0h		R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h

# 表 9-52. REG2B\_Charger\_Mask\_3 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7-5	RESERVED	R	0h		RESERVED
4	VBATOTG_LOW_M ASK	R/W	Oh	Reset by: WATCHDOG REG_RST	VBAT too low to enable OTG mask Type: RW POR: 0b 0h = VBAT falling below the threshold to enable the OTG mode, does produce INT 1h = VBAT falling below the threshold to enable the OTG mode, does NOT produce INT
3	TS_COLD_MASK	R/W	Oh	Reset by: WATCHDOG REG_RST	TS cold temperature interrupt mask Type: RW POR: 0b 0h = TS across cold temperature (T1) does produce INT 1h = TS across cold temperature (T1) does NOT produce INT
2	TS_COOL_MASK	R/W	Oh	Reset by: WATCHDOG REG_RST	TS cool temperature interrupt mask Type: RW POR: 0b 0h = TS across cool temperature (T2) does produce INT 1h = TS across cool temperature (T2) does NOT produce INT
1	TS_WARM_MASK	R/W	Oh	Reset by: WATCHDOG REG_RST	TS warm temperature interrupt mask Type: RW POR: 0b 0h = TS across warm temperature (T3) does produce INT 1h = TS across warm temperature (T3) does NOT produce INT
0	TS_HOT_MASK	R/W	Oh	Reset by: WATCHDOG REG_RST	TS hot temperature interrupt mask Type: RW POR: 0b 0h = TS across hot temperature (T5) does produce INT 1h = TS across hot temperature (T5) does NOT produce INT

# 9.5.1.40 REG2C\_FAULT\_Mask\_0 Register (Offset = 2Ch) [reset = 0h]

REG2C\_FAULT\_Mask\_0 is shown in 图 9-65 and described in 表 9-53.

Return to the 表 9-12.

FAULT Mask 0

#### 图 9-65. REG2C\_FAULT\_Mask\_0 Register

			_		•		
7	6	5	4	3	2	1	0
IBAT_REG_MA SK	VBUS_OVP_M ASK	VBAT_OVP_M ASK	IBUS_OCP_MA SK	IBAT_OCP_MA SK	CONV_OCP_M ASK	VAC2_OVP_M ASK	VAC1_OVP_M ASK
R/W-0h							

#### 表 9-53. REG2C\_FAULT\_Mask\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	IBAT_REG_MASK	R/W	Oh	Reset by: REG_RST	IBAT regulation mask flag Type: RW POR: 0b 0h = enter or exit IBAT regulation does produce INT 1h = enter or exit IBAT regulation does NOT produce INT
6	VBUS_OVP_MASK	R/W	Oh	Reset by: REG_RST	VBUS over-voltage mask flag Type: RW POR: 0b 0h = entering VBUS OVP does produce INT 1h = entering VBUS OVP does NOT produce INT
5	VBAT_OVP_MASK	R/W	0h	Reset by: REG_RST	VBAT over-voltage mask flag Type : RW POR: 0b 0h = entering VBAT OVP does produce INT 1h = entering VBAT OVP does NOT produce INT
4	IBUS_OCP_MASK	R/W	Oh	Reset by: REG_RST	IBUS over-current mask flag Type: RW POR: 0b 0h = IBUS OCP fault does produce INT 1h = IBUS OCP fault does NOT produce INT
3	IBAT_OCP_MASK	R/W	Oh	Reset by: REG_RST	IBAT over-current mask flag Type: RW POR: 0b 0h = IBAT OCP fault does produce INT 1h = IBAT OCP fault does NOT produce INT
2	CONV_OCP_MASK	R/W	Oh	Reset by: REG_RST	Converter over-current mask flag Type: RW POR: 0b 0h = Converter OCP fault does produce INT 1h = Converter OCP fault does NOT produce INT
1	VAC2_OVP_MASK	R/W	0h	Reset by: REG_RST	VAC2 over-voltage mask flag Type : RW POR: 0b 0h = entering VAC2 OVP does produce INT 1h = entering VAC2 OVP does NOT produce INT
0	VAC1_OVP_MASK	R/W	0h	Reset by: REG_RST	VAC1 over-voltage mask flag Type : RW POR: 0b 0h = entering VAC1 OVP does produce INT 1h = entering VAC1 OVP does NOT produce INT

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# 9.5.1.41 REG2D\_FAULT\_Mask\_1 Register (Offset = 2Dh) [reset = 0h]

REG2D\_FAULT\_Mask\_1 is shown in 图 9-66 and described in 表 9-54.

Return to the 表 9-12.

FAULT Mask 1

# 图 9-66. REG2D\_FAULT\_Mask\_1 Register

7	6	5	4	3	2	1 0	
VSYS_SHORT _MASK	VSYS_OVP_M ASK	OTG_OVP_MA SK	OTG_UVP_MA SK	RESERVED	TSHUT_MASK	RESERVED	
R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R-0h	

#### 表 9-54. REG2D\_FAULT\_Mask\_1 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	VSYS_SHORT_MA SK	R/W	Oh	Reset by: REG_RST	VSYS short circuit mask flag Type: RW POR: 0b 0h = System short fault does produce INT 1h = System short fault does NOT produce INT
6	VSYS_OVP_MASK	R/W	Oh	Reset by: REG_RST	VSYS over-voltage mask flag Type: RW POR: 0b 0h = System over-voltage fault does produce INT 1h = System over-voltage fault does NOT produce INT
5	OTG_OVP_MASK	R/W	0h	Reset by: REG_RST	OTG over-voltage mask flag Type: RW POR: 0b 0h = OTG VBUS over-voltage fault does produce INT 1h = OTG VBUS over-voltage fault does NOT produce INT
4	OTG_UVP_MASK	R/W	Oh	Reset by: REG_RST	OTG under-voltage mask flag Type: RW POR: 0b 0h = OTG VBUS under voltage fault does produce INT 1h = OTG VBUS under voltage fault does NOT produce INT
3	RESERVED	R/W	0h		RESERVED
2	TSHUT_MASK	R/W	Oh	Reset by: REG_RST	IC thermal shutdown mask flag Type: RW POR: 0b 0h = TSHUT does produce INT 1h = TSHUT does NOT produce INT
1-0	RESERVED	R	0h		RESERVED

# 9.5.1.42 REG2E\_ADC\_Control Register (Offset = 2Eh) [reset = 30h]

REG2E\_ADC\_Control is shown in 图 9-67 and described in 表 9-55.

Return to the 表 9-12.

ADC Control

# 图 9-67. REG2E\_ADC\_Control Register

7	6	5	4	3	2	1	0
ADC_EN	ADC_RATE	ADC_SAM	IPLE_1:0	ADC_AVG	ADC_AVG_INIT	RESE	RVED
R/W-0h	R/W-0h	R/W-	-3h	R/W-0h	R/W-0h	R/W	/-0h

# 表 9-55. REG2E\_ADC\_Control Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	ADC_EN	R/W	0h	Reset by: WATCHDOG REG_RST	ADC Control Type: RW POR: 0b 0h = Disable 1h = Enable
6	ADC_RATE	R/W	0h	Reset by: REG_RST	ADC conversion rate control Type: RW POR: 0b 0h = Continuous conversion 1h = One shot conversion
5-4	ADC_SAMPLE_1:0	R/W	3h	Reset by: REG_RST	ADC sample speed Type: RW POR: 11b 0h = 15 bit effective resolution 1h = 14 bit effective resolution 2h = 13 bit effective resolution 3h = 12 bit effective resolution (not recommended)
3	ADC_AVG	R/W	Oh	Reset by: REG_RST	ADC average control Type: RW POR: 0b 0h = Single value 1h = Running average (not available for IBAT discharge)
2	ADC_AVG_INIT	R/W	0h	Reset by: REG_RST	ADC average initial value control Type: RW POR: 0b 0h = Start average using the existing register value 1h = Start average using a new ADC conversion
1-0	RESERVED	R/W	0h		RESERVED

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# 9.5.1.43 REG2F\_ADC\_Function\_Disable\_0 Register (Offset = 2Fh) [reset = 0h]

REG2F\_ADC\_Function\_Disable\_0 is shown in 图 9-68 and described in 表 9-56.

Return to the 表 9-12.

ADC Function Disable 0

# 图 9-68. REG2F\_ADC\_Function\_Disable\_0 Register

7	6	5	4	3	2	1	0
IBUS_ADC_DIS	IBAT_ADC_DIS	VBUS_ADC_DI S	VBAT_ADC_DI S	VSYS_ADC_DI S	TS_ADC_DIS	TDIE_ADC_DIS	RESERVED
R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R-0h

# 表 9-56. REG2F\_ADC\_Function\_Disable\_0 Register Field Descriptions

Bit	Field	Туре	Reset	Notes	Description
7	IBUS_ADC_DIS	R/W	0h	Reset by: REG_RST	IBUS ADC control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
6	IBAT_ADC_DIS	R/W	0h	Reset by: REG_RST	IBAT ADC control Type : RW POR: 0b 0h = Enable (Default) 1h = Disable
5	VBUS_ADC_DIS	R/W	0h	Reset by: REG_RST	VBUS ADC control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
4	VBAT_ADC_DIS	R/W	0h	Reset by: REG_RST	VBAT ADC control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
3	VSYS_ADC_DIS	R/W	0h	Reset by: REG_RST	VSYS ADC control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
2	TS_ADC_DIS	R/W	0h	Reset by: REG_RST	TS ADC control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
1	TDIE_ADC_DIS	R/W	0h	Reset by: REG_RST	TDIE ADC control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
0	RESERVED	R	0h		RESERVED

# 9.5.1.44 REG30\_ADC\_Function\_Disable\_1 Register (Offset = 30h) [reset = 0h]

REG30\_ADC\_Function\_Disable\_1 is shown in 图 9-69 and described in 表 9-57.

Return to the 表 9-12.

ADC Function Disable 1

#### 图 9-69. REG30\_ADC\_Function\_Disable\_1 Register

				_	_ 0		
7	6	5	4	3	2	1	0
DP_ADC_DIS	DM_ADC_DIS	VAC2_ADC_DI S	VAC1_ADC_DI S		RESEF	RVED	
R/W-0h	R/W-0h	R/W-0h	R/W-0h		R-0	h	

#### 表 9-57. REG30\_ADC\_Function\_Disable\_1 Register Field Descriptions

Bit	Field	Type	Reset	Notes	Description
7	DP_ADC_DIS	R/W	Oh	Reset by: REG_RST	D+ ADC Control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
6	DM_ADC_DIS	R/W	Oh	Reset by: REG_RST	D- ADC Control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
5	VAC2_ADC_DIS	R/W	Oh	Reset by: REG_RST	VAC2 ADC Control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
4	VAC1_ADC_DIS	R/W	Oh	Reset by: REG_RST	VAC1 ADC Control Type: RW POR: 0b 0h = Enable (Default) 1h = Disable
3-0	RESERVED	R	0h		RESERVED

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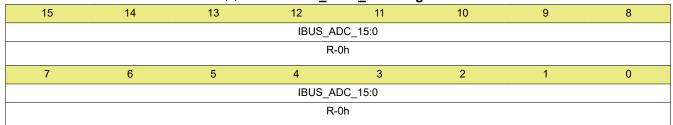
# 9.5.1.45 REG31\_IBUS\_ADC Register (Offset = 31h) [reset = 0h]

REG31\_IBUS\_ADC is shown in 图 9-70 and described in 表 9-58.

Return to the 表 9-12.

**IBUS ADC** 

# 图 9-70. REG31\_IBUS\_ADC Register



### 表 9-58. REG31 IBUS ADC Register Field Descriptions

Bit	Field	Туре	Reset	Description
15-0	IBUS_ADC_15:0	R	0h	IBUS ADC reading
				Reported in 2 's Complement.
				When the current is flowing from VBUS to PMID, IBUS ADC reports
				positive value, and when the current is flowing from PMID to VBUS,
				IBUS ADC reports negative value.
				Type: R
				POR: 0mA (0h)
				Range : 0mA-5000mA
				Fixed Offset : 0mA
				Bit Step Size : 1mA

# 9.5.1.46 REG33\_IBAT\_ADC Register (Offset = 33h) [reset = 0h]

REG33\_IBAT\_ADC is shown in 图 9-71 and described in 表 9-59.

Return to the 表 9-12.

**IBAT ADC** 

# 图 9-71. REG33\_IBAT\_ADC Register

			_		4		
15	14	13	12	11	10	9	8
			IBAT_AI	DC_15:0			
			R-	-0h			
7	6	5	4	3	2	1	0
			IBAT_AI	DC_15:0			
			R-	-0h			

# 表 9-59. REG33\_IBAT\_ADC Register Field Descriptions

	12.0-0.	). INE 033_I	שא_ואם	Register Field Descriptions
Bit	Field	Туре	Reset	Description
15-0	IBAT_ADC_15:0	R	0h	IBAT ADC reading
				Reported in 2 's Complement.
				Type: R
				POR: 0mA (0h)
				Range : 0mA-8000mA
				Fixed Offset : 0mA
				Bit Step Size : 1mA
				The IBAT ADC reports the battery charging current in forward mode
				and the battery discharging current in OTG and battery only (HiZ)
				mode if EN_BAT bit in REG14[5]=1. The sign bit is 0b for charging
				current and 1b for discharging current.

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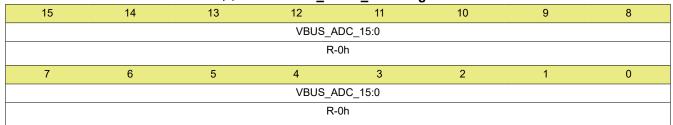
# 9.5.1.47 REG35\_VBUS\_ADC Register (Offset = 35h) [reset = 0h]

REG35\_VBUS\_ADC is shown in 图 9-72 and described in 表 9-60.

Return to the 表 9-12.

**VBUS ADC** 

# 图 9-72. REG35\_VBUS\_ADC Register



### 表 9-60. REG35 VBUS ADC Register Field Descriptions

Bit	Field	Туре	Reset	Description
15-0	VBUS_ADC_15:0	R	0h	VBUS ADC reading.
				Type : R
				POR: 0mV (0h)
				Range : 0mV-30000mV
				Fixed Offset : 0mV
				Bit Step Size : 1mV

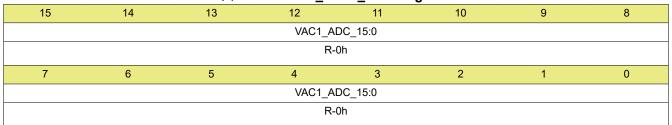
# 9.5.1.48 REG37\_VAC1\_ADC Register (Offset = 37h) [reset = 0h]

REG37\_VAC1\_ADC is shown in 图 9-73 and described in 表 9-61.

Return to the 表 9-12.

VAC1 ADC

# 图 9-73. REG37\_VAC1\_ADC Register



### 表 9-61. REG37\_VAC1\_ADC Register Field Descriptions

Bit	Field	Туре	Reset	Description
15-0	VAC1_ADC_15:0	R	0h	VAC1 ADC reading
				Type : R
				POR: 0mV (0h)
				Range : 0mV-30000mV
				Fixed Offset : 0mV
				Bit Step Size : 1mV



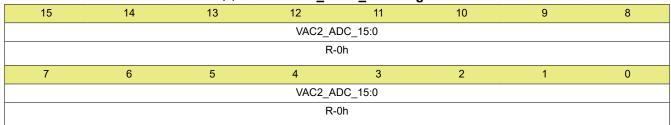
# 9.5.1.49 REG39\_VAC2\_ADC Register (Offset = 39h) [reset = 0h]

REG39\_VAC2\_ADC is shown in 图 9-74 and described in 表 9-62.

Return to the 表 9-12.

VAC2 ADC

# 图 9-74. REG39\_VAC2\_ADC Register



# 表 9-62. REG39 VAC2 ADC Register Field Descriptions

	Bit	Field	Туре	Reset	Description		
	15-0	VAC2_ADC_15:0	R	0h	VAC2 ADC reading		
					Type : R		
					POR: 0mV (0h)		
					Range : 0mV-30000mV		
					Fixed Offset : 0mV		
					Bit Step Size : 1mV		

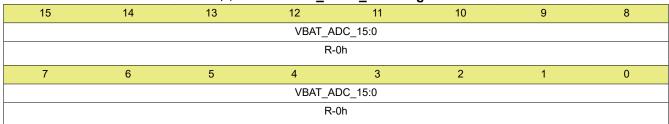
# 9.5.1.50 REG3B\_VBAT\_ADC Register (Offset = 3Bh) [reset = 0h]

REG3B\_VBAT\_ADC is shown in 图 9-75 and described in 表 9-63.

Return to the 表 9-12.

**VBAT ADC** 

# 图 9-75. REG3B\_VBAT\_ADC Register



# 表 9-63. REG3B\_VBAT\_ADC Register Field Descriptions

Bit	Field	Туре	Reset	Description
15-0	VBAT_ADC_15:0	R	0h	The battery remote sensing voltage (VBATP) ADC reading
				Type : R
				POR: 0mV (0h)
				Range : 0mV-20000mV
				Fixed Offset : 0mV
				Bit Step Size : 1mV

# 9.5.1.51 REG3D\_VSYS\_ADC Register (Offset = 3Dh) [reset = 0h]

REG3D\_VSYS\_ADC is shown in 图 9-76 and described in 表 9-64.

Return to the 表 9-12.

**VSYS ADC** 

# 图 9-76. REG3D\_VSYS\_ADC Register

			_	_	•		
15	14	13	12	11	10	9	8
			VSYS_A	DC_15:0			
			R-	-0h			
7	6	5	4	3	2	1	0
			VSYS_A	DC_15:0			
			R-	-0h			

### 表 9-64. REG3D VSYS ADC Register Field Descriptions

Bit	Field	Туре	Reset	Description
15-0	VSYS_ADC_15:0	R	0h	VSYS ADC reading
				Type : R
				POR: 0mV (0h)
				Range : 0mV-24000mV
				Fixed Offset : 0mV
				Bit Step Size : 1mV

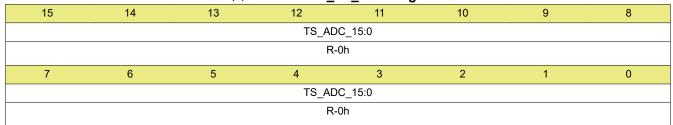
# 9.5.1.52 REG3F\_TS\_ADC Register (Offset = 3Fh) [reset = 0h]

REG3F\_TS\_ADC is shown in 图 9-77 and described in 表 9-65.

Return to the 表 9-12.

TS ADC

# 图 9-77. REG3F\_TS\_ADC Register



### 表 9-65. REG3F\_TS\_ADC Register Field Descriptions

Bit	Field	Туре	Reset	Description
15-0	TS_ADC_15:0	R	0h	TS ADC reading
				Type : R
				POR: 0% (0h)
				Range : 0%-99.9023%
				Fixed Offset: 0%
				Bit Step Size : 0.0976563%



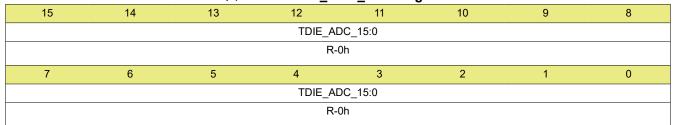
# 9.5.1.53 REG41\_TDIE\_ADC Register (Offset = 41h) [reset = 0h]

REG41\_TDIE\_ADC is shown in 图 9-78 and described in 表 9-66.

Return to the 表 9-12.

TDIE\_ADC

# 图 9-78. REG41\_TDIE\_ADC Register



### 表 9-66. REG41\_TDIE\_ADC Register Field Descriptions

Field	Туре	Reset	Description				
TDIE_ADC_15:0	R	0h	TDIE ADC reading Reported in 2 's Complement.				
			Type : R				
			POR: 0°C (0h) Range : -40°C-150°C				
			Fixed Offset : 0°C Bit Step Size : 0.5°C				
		7,1	TDIE_ADC_15:0 R 0h				

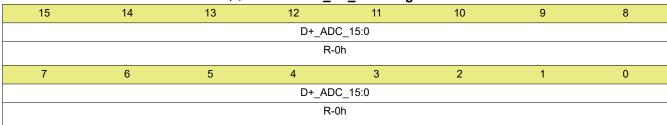
# 9.5.1.54 REG43\_D+\_ADC Register (Offset = 43h) [reset = 0h]

REG43\_D+\_ADC is shown in 图 9-79 and described in 表 9-67.

Return to the 表 9-12.

D+ ADC

# 图 9-79. REG43\_D+\_ADC Register



# 表 9-67. REG43\_D+\_ADC Register Field Descriptions

Bit	Field	Туре	Reset	Description
15-0	D+_ADC_15:0	R 0h		D+ ADC reading
				Type : R
				POR: 0mV (0h)
				Range : 0mV-3600mV
				Fixed Offset : 0mV
				Bit Step Size : 1mV



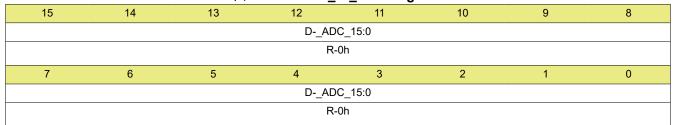
# 9.5.1.55 REG45\_D-\_ADC Register (Offset = 45h) [reset = 0h]

REG45\_D-\_ADC is shown in 图 9-80 and described in 表 9-68.

Return to the 表 9-12.

D- ADC

# 图 9-80. REG45\_D-\_ADC Register



### 表 9-68. REG45 D- ADC Register Field Descriptions

Bit	Field	Туре	Reset	Description
15-0	DADC_15:0	R	0h	D- ADC reading
				Type : R
				POR: 0mV (0h)
				Range : 0mV-3600mV
				Fixed Offset : 0mV
				Bit Step Size : 1mV

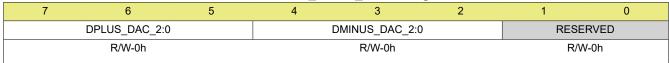
# 9.5.1.56 REG47\_DPDM\_Driver Register (Offset = 47h) [reset = 0h]

REG47\_DPDM\_Driver is shown in 图 9-81 and described in 表 9-69.

Return to the 表 9-12.

**DPDM** Driver

#### 图 9-81. REG47\_DPDM\_Driver Register



#### 表 9-69. REG47\_DPDM\_Driver Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-5	DPLUS_DAC_2:0	R/W	Oh	D+ Output Driver Type: RW POR: 000b 0h = HIZ 1h = 0 2h = 0.6V 3h = 1.2V 4h = 2.0V 5h = 2.7V 6h = 3.3V 7h = D+/D- Short
4-2	DMINUS_DAC_2:0	R/W	Oh	D- Output Driver Type: RW POR: 000b 0h = HIZ 1h = 0 2h = 0.6V 3h = 1.2V 4h = 2.0V 5h = 2.7V 6h = 3.3V 7h = reserved
1-0	RESERVED	R/W	0h	RESERVED

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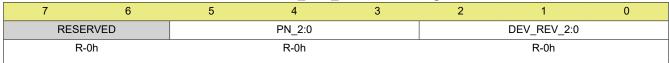
# 9.5.1.57 REG48\_Part\_Information Register (Offset = 48h) [reset = 0h]

REG48\_Part\_Information is shown in 图 9-82 and described in 表 9-70.

Return to the 表 9-12.

Part Information

#### 图 9-82. REG48\_Part\_Information Register



#### 表 9-70. REG48\_Part\_Information Register Field Descriptions

Bit	Field	Туре	Reset	Description				
7-6	RESERVED	R 0h		RESERVED				
5-3	PN_2:0	R	3h	Device Part Number 011b = BQ25798				
2-0	DEV_REV_2:0	R 1h		Device Revision 001b = BQ25798				

# 10 Application and Implementation

#### 备注

以下应用部分中的信息不属于 TI 器件规格的范围, TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

#### 10.1 Application Information

A typical application consists of the device configured as an  $I^2C$  controlled power path management battery backup device and a multi-cell battery charger for Li-lon and Li-polymer batteries. It integrates the four switching MOSFETs ( $Q_1$  to  $Q_4$ ) for the buck-boost converter, and the battery FET (BATFET) between system and battery. The device also integrates the input current sensing and charging current sensing circuitries, the bootstrap diode for the high-side gate driving and the dual-input power mux for the power sources selection.

The charger's MPPT algorithm allows a simple but efficient interface between the charger and a small photovoltaic panel. The power mux may optionally be used to add a secondary charging port such as a barrel jack or USB input.

For applications that will enable backup mode, it is required that RBFET and ACFET are populated in the input power multiplexer. When backup mode is entered, the ACDRV turns off the RBFET and ACFET to block the converter output from propagating out to the adapter connector. EN\_BACKUP cannot be set to 1 to enable backup mode if RBFET and ACFET are not detected at POR.

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# **10.2 Typical Application**

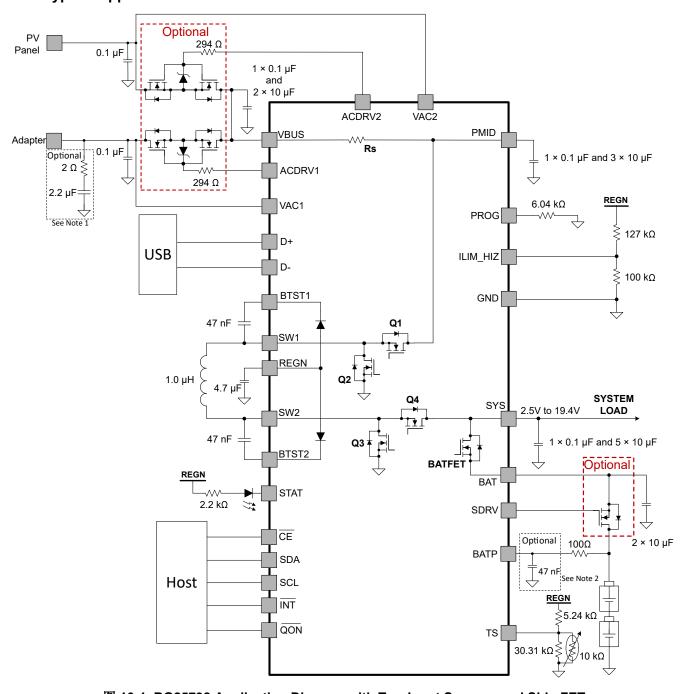


图 10-1. BQ25798 Application Diagram with Two Input Sources and Ship FET

- 1. Recommended if hot plugging adapters > 15 V.
- 2. Recommended if hot plugging 4S battery packs with long leads or PCB traces.

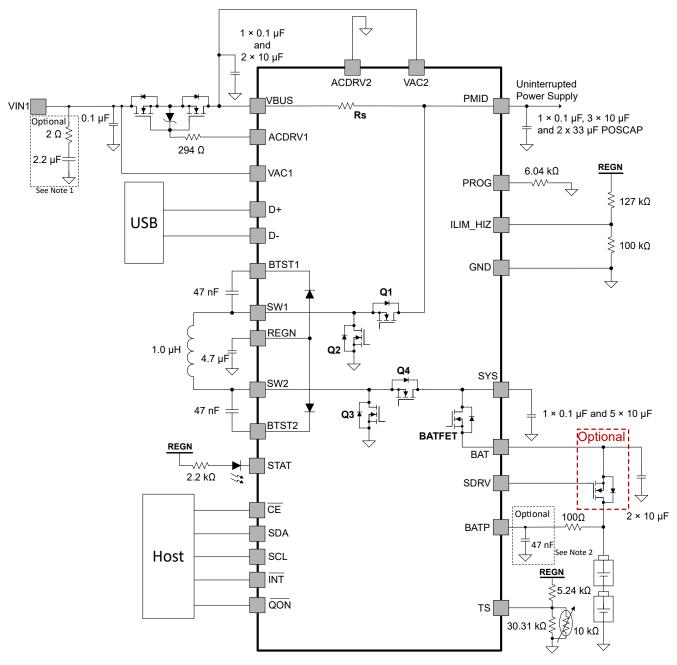


图 10-2. BQ25798 Application Diagram with Single Input Source, Back Up Mode and Ship FET



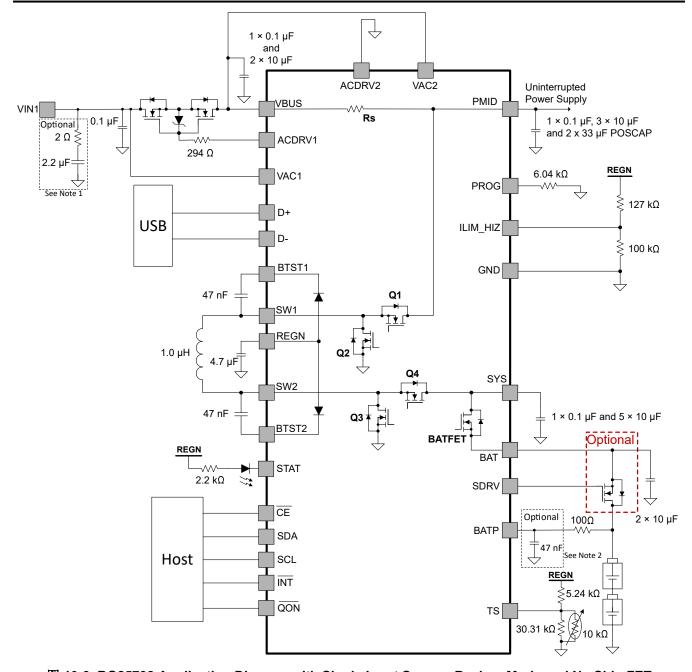


图 10-3. BQ25798 Application Diagram with Single Input Source, Backup Mode and No Ship FET

- 1. Recommended if hot plugging adapters > 15 V.
- 2. Recommended if hot plugging 4S battery packs with long leads or PCB traces.

#### 10.2.1 Design Requirements

For this design example, use the parameters shown in the table below.

表 10-1. Design Parameters

PARAMETER	VALUE
VBUS voltage range	5 V to 20 V
PV panel voltage	V <sub>OC</sub> = 10 V <sub>MPP</sub> = 8 V
Secondary adapter voltage range	5 V to 20 V
Input current limit (IINDPM[8:0])	3.0 A
Fast charge current limit (ICHG[8:0])	3.0 A
Backup mode voltage (VOTG[10:0])	12.0 V
Battery regulation voltage (VREG[10:0])	8.4 V
Enable MPPT (EN_MPPT[0])	1
VOC measure internval (VOC_RATE[1:0])	2 min
VOC measure delay (VOC_DLY[1:0])	300 ms
VOC percent for MPP (VOC_PCT[2:0])	0.8125

#### 10.2.2 Detailed Design Procedure

#### 10.2.2.1 PV Panel Selection

BQ25798 has a 3.6 to 24V wide input voltage range, allowing it to interface with 6V, 9V and 12V photovoltaic panels. Two critical parameters of the PV panel are the open circuit voltage,  $V_{OC}$ , and the maximum power point voltage,  $V_{MPP}$ . The open-circuit voltage should not exceed the 24V recommended operating condition of VIN1 or VIN2. BQ25798 has a small-PV maximum power point tracking algorithm (see  $\ddagger$  9.3.6.3) to simplify the interface to the solar panel while maintaining high effiiency.

The ratio of maximum power point voltage to open circuit voltage can change over differing conditions such as temperature and irradiance, but the ratio of  $V_{MPP}$  /  $V_{OC}$  as provided in the PV panel manufacturer's datasheet provides a good estimate to use when configuraing VOC\_PCT. For a panel with  $V_{OC}$  = 10.0 Vand  $V_{MPP}$  = 8.0 V, the calculated maximum power point ratio is 8.0 V / 10.0 V = 80.0%. A setting of VOC\_PCT = 4 (81.25%) is a good starting configuration for this panel. Users may wish to characterize their PV panel's operation over their specific application conditions of temperature, irradiance, humidity and other parameters in order to adjust this setting if necessary.

#### 10.2.2.2 Inductor Selection

The device has 1.5 MHz switching frequency to allow the use of small inductor ( $1\mu$ H) and capacitor values. It also provide the 750kHz switching frequency to achieve higher efficiency for the applications which have enough design space to accommodate the larger inductor ( $2.2~\mu$ H) and capacitors. Please note that the 1.5 MHz switching frequency only works with the  $1\mu$ H inductor and the 750 kHz switching frequency only works with the  $2.2\mu$ H inductor.

Because the converter might be either operated in the buck mode or the boost mode, so the inductor current is equal to either the charging current or the input current. The inductor saturation current should be higher than the larger value of the input current ( $I_{IN}$ ) or the charging current ( $I_{CHG}$ ) plus half the ripple current ( $I_{RIPPLE}$ ):

$$I_{SAT} \ge MAX \left[ \left( I_{IN} + \frac{I_{RIPPLE}}{2} \right), \left( I_{CHG} + \frac{I_{RIPPLE}}{2} \right) \right] \tag{4}$$

The inductor ripple current ( $I_{RIPPLE}$ ) depends on the input voltage ( $V_{BUS}$ ), the output voltage ( $V_{SYS}$ ), the switching frequency ( $F_{SW}$ ) and the inductance (L). The inductor current ripples for buck mode and boost mode are calculated with equations (4) and (5), respectively:

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$$I_{RIPPLE\_BUCK} = \frac{V_{SYS} \times (V_{BUS} - V_{SYS})}{V_{BUS} \times F_{SW} \times L}$$
(5)

$$I_{RIPPLE\_BOOST} = \frac{V_{BUS} \times (V_{SYS} - V_{BUS})}{V_{SYS} \times F_{SW} \times L}$$
(6)

The inductor current ripple in the buck mode is usually larger than that in the boost mode, since the voltage-second applied on the inductor is larger. The maximum inductor current ripple in the buck mode happens in the vicinity of D =  $V_{SYS}$  /  $V_{BUS}$  = 0.5. The SYS voltage is approximately 8V for the 2s battery configuration, so the worst case for the inductor ripples is with the 15V or 20V input voltage.

#### 10.2.2.3 Input (VBUS / PMID) Capacitor

In the buck mode operation, the input current is discontinuous, which dominates the input RMS ripple current and input voltage ripple. The input capacitors should have enough ripple current rating to absorb the input AC current and have large enough capacitance to maintain the small input voltage ripple. For the buck mode operation, the input RMS ripple current is calculated by the equation (6) and the input voltage ripple is calculated by the equation (7), where  $D = V_{SYS} / V_{BUS}$ .

$$I_{CIN\_BUCK} = I_{CHG} \times \sqrt{D \times (1 - D)}$$
(7)

$$\Delta V_{IN\_BUCK} = \frac{D \times (1 - D) \times I_{CHG}}{C_{IN} \times F_{SW}}$$
(8)

The worst case input RMS ripple current and input voltage ripple both occur at 0.5 duty cycle condition. The SYS voltage is approximately 8V for the 2s battery configuration, so the worst case is when 15V to 20V VBUS condition. Low ESR ceramic capacitor such as X7R or X5R is preferred for the input decoupling capacitor and should be placed close to the PMID and GND pins of the IC. The voltage rating of the capacitor must be higher than the normal input voltage level. The capacitor with 25V or higher voltage rating is preferred for up to 20V input voltage. 1\*0.1  $\mu$ F + 3\*10  $\mu$ F ceramic capacitors are suggested for up to 3.3-A input current limit to support the converter in forward mode.

The PMID capacitance also holds up the PMID rail during the transition into backup mode when the adapter is removed. For applications that utilize the backup mode an additional 2\*33 uF POSCAP is recommended at PMID.

#### 10.2.2.4 Output (VSYS) Capacitor

In the boost mode operation, the output current is discontinuous, which dominates the output RMS ripple current and output voltage ripple. The output capacitors should have enough ripple current rating to absorb the output AC current and have large enough capacitance to maintain the small output voltage ripple. For the boost mode operation, the output RMS ripple current is calculated by the equation (8) and the output voltage ripple is calculated by the equation (9), where  $D = (1 - V_{BUS} / V_{SYS})$ .

$$I_{COUT\_BOOST} = I_{CHG} \times \sqrt{\frac{D}{(1-D)}}$$
(9)

$$\Delta V_{OUT\_BOOST} = \frac{I_{CHG} \times D}{C_{OUT} \times F_{SW}} \tag{10}$$

The worst case output RMS ripple current and output voltage ripple both occur at the lowest VBUS input voltage. The SYS voltage is approximately 8V for the 2s battery configuration, so the worst case is 5V VBUS condition. Low ESR ceramic capacitor such as X7R or X5R is preferred for the output decoupling capacitor and should be placed close to the SYS and GND pins of the IC. The voltage rating of the capacitor must be higher than the

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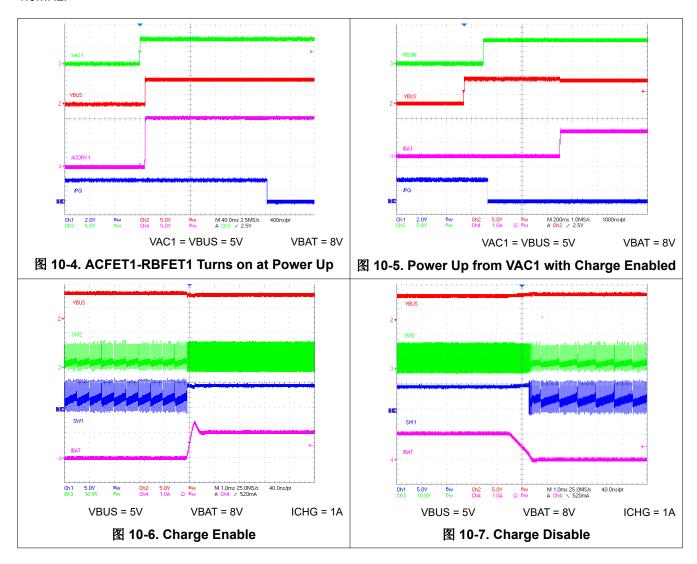


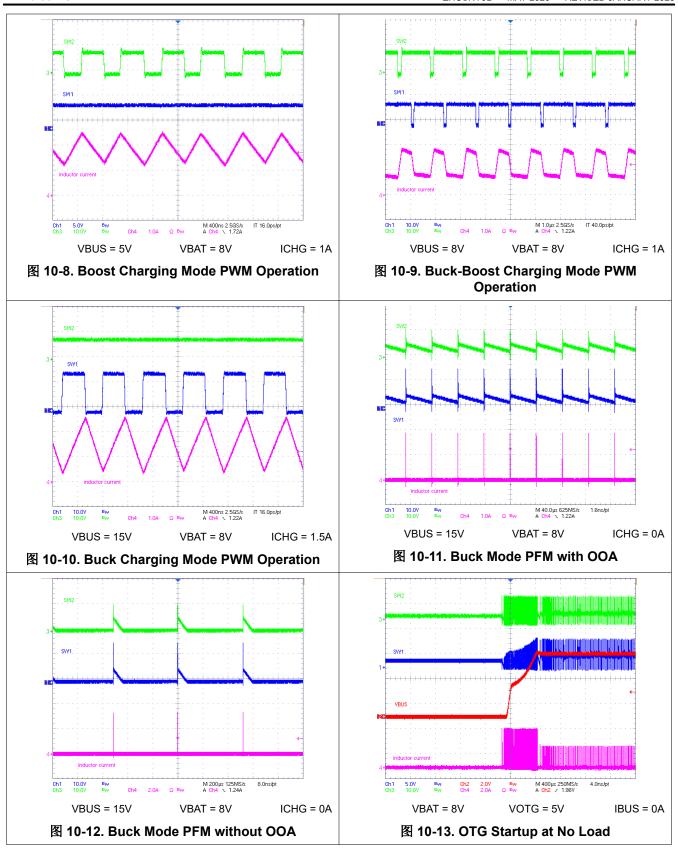
normal input voltage level. The capacitor with 16V or higher voltage rating is preferred for the 2s battery configuration. 1\*0.1  $\mu$  F + 5\*10  $\mu$  F capacitors are suggested for up to 5A charging current.



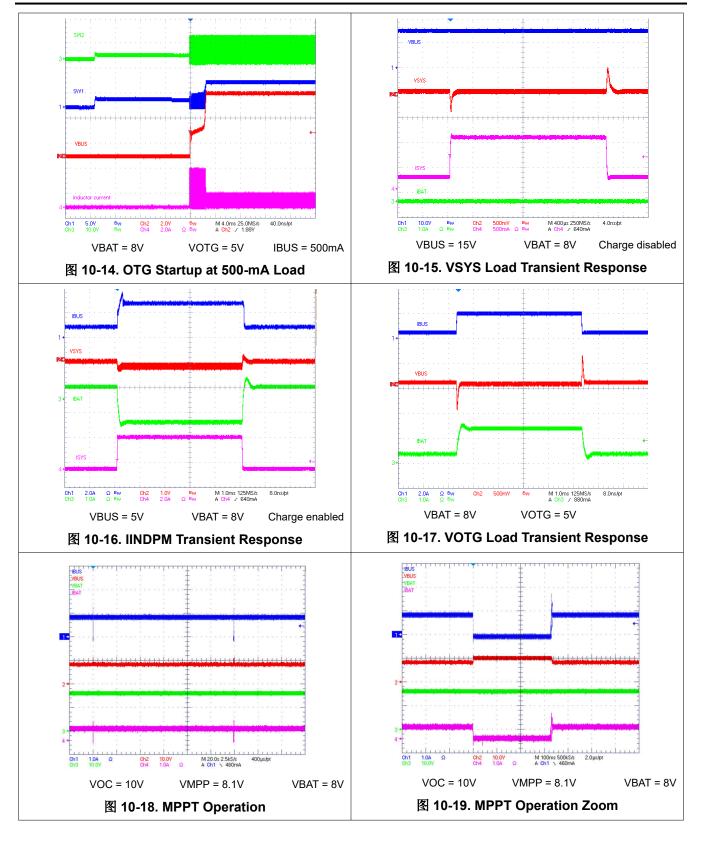
#### 10.2.3 Application Curves

 $C_{VBUS}$  = 2\*10 $\mu$ F,  $C_{PMID}$ = 3\*10 $\mu$ F,  $C_{SYS}$  = 5\*10 $\mu$ F,  $C_{BAT}$  = 2\*10 $\mu$ F, L1 = 1 $\mu$ H (SPM6530T-1R0M120), Fsw = 1.5MHz.











# 11 Power Supply Recommendations

In order to provide an output voltage on SYS, the device requires a power supply between 3.6 V and 24 V input with recommended >500mA current rating connected to VBUS or a 1s to 4s Li-lon battery with voltage higher than  $V_{BAT\_UVLO}$  connected to BAT. The source current rating needs to be at least 3A for the buck-boost converter of the charger to provide maximum output power to SYS.

# 12 Layout

# 12.1 Layout Guidelines

The switching nodes rising and falling times should be minimized for minimum switching loss. Proper layout of the components to minimize the high frequency current path loops (shown in the figure below) is important to prevent the electrical and magnetic field radiation and the high frequency resonant problems. Here is a PCB layout priority list for proper layout. Layout PCB according to this specific order is essential.

- 1. Place the SYS output capacitors as close to SYS and GND as possible. Place a 0.1  $\mu$ F small size (such as 0402 or 0201) capacitor closer than the other 10  $\mu$ F capacitors. Ground connections need to be tied to the IC ground with a short copper trace connection or GND plane.
- 2. Place the PMID input capacitors as close to PMID and GND as possible. Place a 0.1  $\mu$ F small size (such as 0402 or 0201) capacitor closer than the other 10  $\mu$ F capacitors. Ground connections need to be tied to the IC ground with a short copper trace connection or GND plane.
- 3. Place the VBUS input capacitors as close to VBUS and GND as possible. Place a 0.1  $\mu$ F small size (such as 0402 or 0201) capacitor closer than the other 10  $\mu$ F capacitors. Ground connections need to be tied to the IC ground with a short copper trace connection or GND plane.
- 4. The connection from SYS/PMID/VBUS to the 0.1 μF has to be routed on the top layer of the PCB, the returning back to GND also has to be in the top layer. Keep the whole routing loop as small as possible.
- 5. Place the inductor input terminal to SW1 and the inductor output terminal to SW2 as close as possible. Minimize the copper area of this trace to lower electrical and magnetic field radiation but make the trace wide enough to carry the inductor current. Minimize parasitic capacitance from this area to any other trace or plane.
- 6. Place the BAT capacitors close to BAT and GND, place the VBUS capacitors close to VBUS and GND.
- 7. The REGN decoupling capacitor and the bootstrap capacitors should be placed next to the IC and make trace connection as short as possible.
- 8. Ensure that there are sufficient thermal vias directly under the power MOSFETs, connecting to copper on other layers.
- 9. Via size and number should be enough for a given current path.
- 10. Route BATP away from switching nodes such as SW1 and SW2.

Refer to the EVM design and more information in the *BQ25792EVM*, *BQ25798EVM*, and *BQ25798BKUPEVM* (*BMS034*) Evaluation Module for the recommended component placement with trace and via locations.

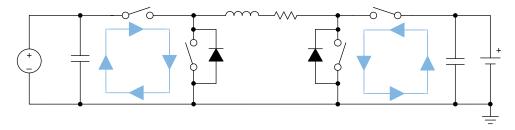


图 12-1. Buck-Boost Converter High Frequency Current Path

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#### 12.2 Layout Example

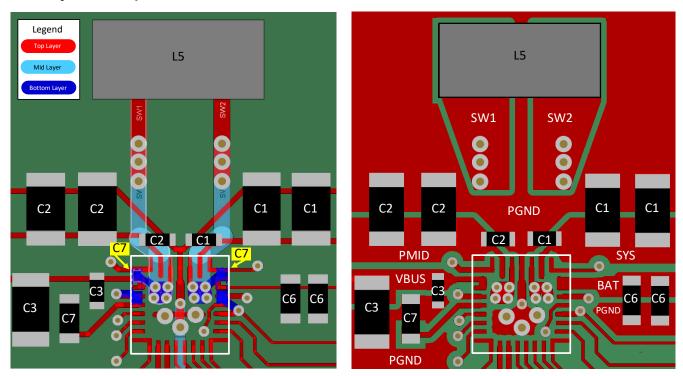


图 12-2. PCB Layout Example (Top Layer Copper Pours Removed on Left, Shown on Right)

图 12-2 shows the recommended placement and routing of external components. The components are labelled with "R," "C" or "L" to indicate resistor, capacitor or inductor and a number that corresponds to the numbered list in 节 12.1. Since the layout guidelines are listed in priority order, this number also provides a priority for component placement.

The placement of C1 and C2 0.1  $\mu$ F PMID and SYS capacitors is critical for noise filtering. They should be placed on the same layer as the BQ25798, as close to the IC as possible. This will generally require that the traces to connect SW1 and SW2 to the inductor are routed on a different layer.

The SW1 and SW2 pins are routed to vias placed under the IC and then back out on an inner PCB layer. This supports the tightest placement of C1 and C2 capctiors as described above. These vias are also used to route to the C7 BTST1 and BTST2 capactiors on the bottom layer as shown.



# 13 Device and Documentation Support

# 13.1 Device Support

#### 13.1.1 第三方产品免责声明

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#### 13.2 Documentation Support

#### 13.2.1 Related Documentation

For related documentation see the following:

BQ25792EVM, BQ25798EVM, and BQ25798BKUPEVM (BMS034) Evaluation Module

#### 13.3 接收文档更新通知

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#### 13.7 术语表

TI术语表本术语表列出并解释了术语、首字母缩略词和定义。

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# 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
BQ25798RQMR	ACTIVE	VQFN-HR	RQM	29	3000	RoHS & Green	(6) SN	Level-2-260C-1 YEAR	-40 to 85	BQ25798	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE MATERIALS INFORMATION**

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#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ25798RQMR	VQFN- HR	RQM	29	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

# **PACKAGE MATERIALS INFORMATION**

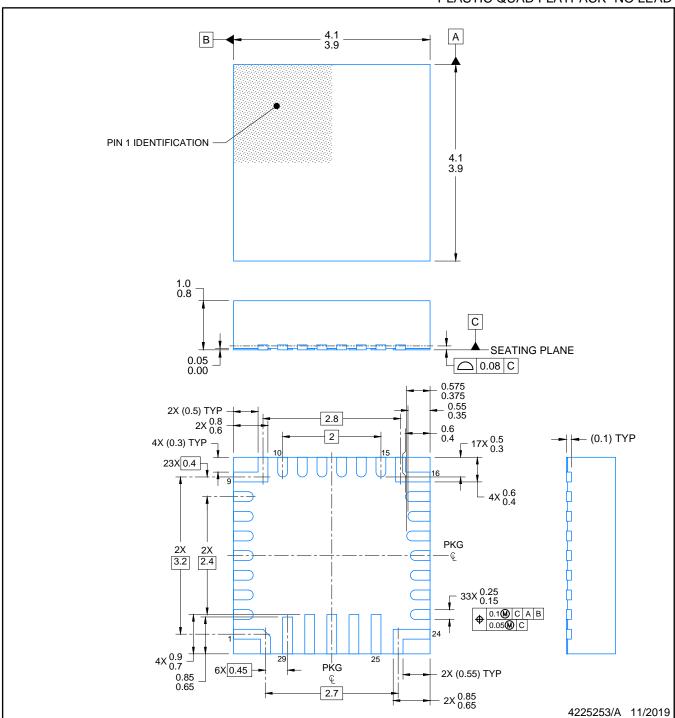
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#### \*All dimensions are nominal

	Device Package Type		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	BQ25798RQMR	VQFN-HR	RQM	29	3000	367.0	367.0	35.0	

PLASTIC QUAD FLATPACK- NO LEAD

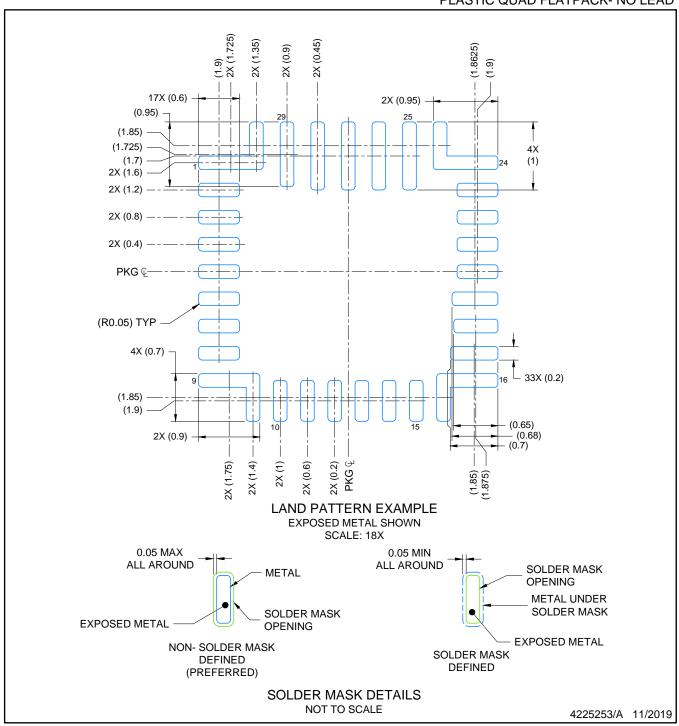


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



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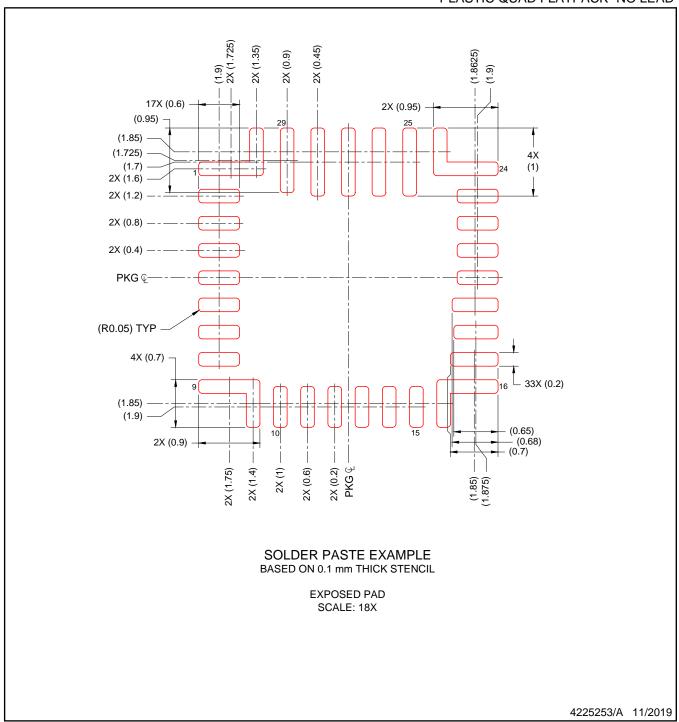


NOTES: (continued)

- 3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 4. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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